documentation

Texas
INSTRUMENTS
TPS65220

## TPS65220 Integrated Power Management IC for ARM Cortex ${ }^{\circledR}$ —A53 ProcessorsA53 Processors and FPGAs

## 1 Features

- 3 Buck converters at up to $2.3-\mathrm{MHz}$ non-fixed switching frequency or fixed frequency mode:
- $1 x$ VIN: $2.5 \mathrm{~V}-5.5 \mathrm{~V}$; $\mathrm{I}_{\text {OUT: }}: 3.5 \mathrm{~A}$; $\mathrm{V}_{\text {OUT }} 0.6 \mathrm{~V}$ 3.4 V
- $2 x$ VIN: $2.5 \mathrm{~V}-5.5 \mathrm{~V}$; I IOUT: 2 A ; $\mathrm{V}_{\text {OUT }} 0.6 \mathrm{~V}$ 3.4 V
- 4 linear regulators:
- $2 x$ VIN: $1.5 \mathrm{~V}-5.5 \mathrm{~V}$; Iоит: 400 mA ; $\mathrm{V}_{\text {OUT: }}$ : $0.6 \mathrm{~V}-3.4 \mathrm{~V}$ (configurable as load switch and bypass-mode, supporting SD-Card)
- $2 x$ VIN: 2.2 V - 5.5 V ; lout: 300 mA ; V $\mathrm{V}-3.3 \mathrm{~V}$ (configurable as load switch)
- Dynamic voltage scaling on all three buck converters
- Low IQ/PFM, PWM-mode (quasi-fixed frequency) or fixed frequency mode
- Programmable power sequencing and default voltages
- $I^{2} \mathrm{C}$ interface, supporting standard, fast-mode and fast-mode+
- Designed to support systems with up to $14+$ rails ( $2 x$ TPS65220 7 rails each + GPO-controlled external rails)
- 2 GPOs, 1 GPIO, and 3 multi-function-pins
- EEPROM programmability
- Functional safety capable


## 2 Applications

- Low power industrial MPUs such as AM62x and AM64x
- Low power automotive MPUs such as AM62x-Q1 and AM64x-Q1
- HMI
- PLC
- Industrial PC
- Building security
- HVAC
- Video surveillance
- Data concentrators
- Smart meter
- Protection relays
- Patient monitoring and diagnostics
- Imaging
- Head units, digital cluster, telematic control units, lidar proc.
- DMS/OMS, eMirror and CMS
- ISP and deep learning


## 3 Description

The TPS65220 is a Power Management IC (PMIC) designed to supply a wide range of SoCs in both portable and stationary automotive applications. The device is characterized across an ambient temperature range of $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$, making the PMIC an excellent choice for various industrial automotive applications. The device includes three synchronous stepdown DC-DC converters and four linear regulators.
The DC-DC converters are capable of $1 \times 3.5 \mathrm{~A}$ and 2 x 2 A. The converters require a small 470 nH inductor, $4.7 \mu \mathrm{~F}$ input capacitance, and a minimum $10 \mu \mathrm{~F}$ output capacitance per rail.

Two of the LDOs support output currents of 400 mA at an output voltage range of 0.6 V to 3.4 V . These LDOs support bypass mode, acting as a loadswitch, and allow voltage-changes during operation. The other two LDOs support output currents of 300 mA at an output voltage range of 1.2 V to 3.3 V . The LDOs also support load-switch mode.
The I2C-interface, IOs, GPIOs and multi-function-pins (MFP) allow a seamless interface to a wide range of SoCs.

## Package Information

| PART NUMBER $^{(1)}$ | PACKAGE | PACKAGE SIZE (NOM) |
| :---: | :---: | :---: |
| TPS65220 | $32-$ pin QFN | $5.00 \mathrm{~mm} \times 5.00 \mathrm{~mm}$ |

(1) For all available packages, see the orderable addendum at the end of the data sheet.


## Table of Contents

1 Features ..... 1
7 Detailed Description ..... 28
2 Applications ..... 1
3 Description ..... 1
4 Revision History ..... 2
5 Pin Configuration and Functions. ..... 3
6 Specifications ..... 7
6.1 Absolute Maximum Ratings ..... 7
6.2 ESD Ratings ..... 7
6.3 Recommended Operating Conditions ..... 7
6.4 Thermal Information ..... 9
6.5 System Control Thresholds ..... 9
6.6 BUCK1 Converter. ..... 10
6.7 BUCK2, BUCK3 Converter ..... 14
6.8 General Purpose LDOs (LDO1, LDO2) ..... 17
6.9 General Purpose LDOs (LDO3, LDO4) ..... 19
6.10 GPIOs and multi-function pins (EN/PB/ VSENSE, nRSTOUT, nINT, GPO1, GPO2, GPIO, MODE/RESET, MODE/STBY, VSEL_SD/ VSEL_DDR) ..... 21
6.11 Voltage and Temperature Monitors ..... 23
$6.12 \mathrm{I}^{2} \mathrm{C}$ Interface ..... 24
6.13 Typical Characteristics ..... 26
7.1 Overview. ..... 28
7.2 Functional Block Diagram ..... 29
7.3 Feature Description ..... 29
7.4 Device Functional Modes ..... 53
7.5 User Registers ..... 59
7.6 Device Registers ..... 60
8 Application and Implementation. ..... 135
8.1 Application Information ..... 135
8.2 Typical Application ..... 135
8.3 Power Supply Recommendations ..... 142
8.4 Layout ..... 142
9 Device and Documentation Support ..... 144
9.1 Documentation Support. ..... 144
9.2 Receiving Notification of Documentation Updates ..... 144
9.3 Support Resources ..... 144
9.4 Trademarks ..... 144
9.5 Electrostatic Discharge Caution ..... 144
9.6 Glossary ..... 144
10 Mechanical, Packaging, and Orderable Information ..... 145
4 Revision History
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.
Changes from Revision * (December 2022) to Revision A (July 2023) ..... Page

- Changed the device status from Advance Information to Production Data ..... 1


## 5 Pin Configuration and Functions



Figure 5-1. RHB Package, 32-pin QFN (Top View)
Table 5-1. Pin Functions

| PIN NAME | PIN NO. | TYPE | DESCRIPTION | CONNECTION if not used (output rails must be permanently disabled) |
| :---: | :---: | :---: | :---: | :---: |
| FB_B1 | 1 | 1 | Feedback Input for Buck1. Connect to Buck1 output filter. Nominal output voltage is configured in EEPROM. | Connect to GND |
| LX_B1_1 | 2 | PWR | Switch Pin for Buck1. Connect one side of the Buck1-inductor to this pin. | Leave floating |
| LX_B1_2 | 3 | PWR | 2nd Switch Pin for Buck1. Connect one side of the Buck1-inductor to this pin. Connect to LX_B1_1. | Leave floating |
| PVIN_B1_1 | 4 | PWR | Power Input for BUCK1. Bypass this pin to ground with a $4.7 \mu \mathrm{~F}$ or greater ceramic capacitor. Voltage on PVIN_B1_1 pin must not exceed voltage on VSYS pin. | Connect to VSYS |
| PVIN_B1_2 | 5 | PWR | 2nd Power Input for BUCK1. This pin shares the bypass capacitor from pin 4. Voltage on PVIN_B1_2 pin must not exceed voltage on VSYS pin. | Connect to VSYS |
| PVIN_LDO1 | 6 | PWR | Power Input for LDO1. Voltage on PVIN_LDO1 pin must not exceed voltage on VSYS pin. | Connect to VSYS |
| VLDO1 | 7 | PWR | Output Voltage of LDO1. Nominal output voltage is configured in EEPROM. Bypass this pin to ground with a $2.2 \mu \mathrm{~F}$ or greater ceramic capacitor. | Leave floating |
| GPO1 | 8 | 0 | General Purpose Open-Drain Output. Configurable in the power-up and power-down-sequence to enable an external rail. | Leave floating |
| SDA | 9 | I/O | Data Pin for the I2C Serial Port. The I2C logic levels depend on the external pull-up voltage. | Connect to VIO |

Table 5-1. Pin Functions (continued)

| PIN NAME | PIN NO. | TYPE | DESCRIPTION | CONNECTION if not used (output rails must be permanently disabled) |
| :---: | :---: | :---: | :---: | :---: |
| SCL | 10 | 1 | Clock Pin for the I2C Serial Port. The I2C logic levels depend on the external pull-up voltage. | Connect to VIO |
| nINT | 11 | 0 | Interrupt Request Output. Open-drain driver is pulled low for fault conditions. Released if bit is cleared | Leave floating |
| VSEL_SD/ VSEL_DDR | 12 | 1 | Multi-Function-Pin: Configured as VSEL_SD: SD-card-IO-voltage select. Connected to SoC. Trigger a voltage change between 1.8 V and register-based VOUT on LDO1 or LDO2. Polarity is configurable. Configured as VSEL_DDR: DDR-voltage selection. Hard-wired pull-up ( 1.35 V ), pull-down (register based VOUT) or floating (1.2 V) | $\mathrm{n} / \mathrm{a}$ (connect to GND) |
| VSYS | 13 | PWR | Input supply pin for reference system. Bypass this pin to ground with a $2.2 \mu \mathrm{~F}$ or greater ceramic capacitor (can be shared with PVIN-capacitors). | n/a |
| VDD1P8 | 14 | PWR | Internal Reference Voltage: For Internal Use Only. Bypass this pin to ground with a $2.2 \mu \mathrm{~F}$ or greater ceramic capacitor. | n/a |
| AGND | 15 | GND | Ground pin for Analog GND | n/a |
| GPIO | 16 | I/O | GPO-configuration: General Purpose Open-Drain Output. Configurable in the power-up and power-down-sequence to enable an external rail. GPIO-configuration: <br> Synchronizing I/O. Used to synchronize two or more TPS65220. The pin is level-sensitive. | Leave floating |
| GPO2 | 17 | 0 | General Purpose Open-Drain Output. Configurable in the power-up and power-down-sequence to enable an external rail. | Leave floating |
| nRSTOUT | 18 | 0 | Reset-output to SoC. Controlled by sequencer. High in ACTIVE and STBY state. | Leave floating |
| VLDO2 | 19 | PWR | Output Voltage of LDO2. Nominal output voltage is configured in EEPROM. Bypass this pin to ground with a $2.2 \mu \mathrm{~F}$ or greater ceramic capacitor. | Leave floating |
| PVIN_LDO2 | 20 | PWR | Power Input for LDO2. Bypass this pin to ground with a $2.2 \mu \mathrm{~F}$ or greater ceramic capacitor. Voltage on PVIN_LDO2 pin must not exceed voltage on VSYS pin. | Connect to VSYS |
| VLDO3 | 21 | PWR | Output Voltage of LDO3. Nominal output voltage is configured in EEPROM. Bypass this pin to ground with a $2.2 \mu \mathrm{~F}$ or greater ceramic capacitor. | Leave floating |
| PVIN_LDO34 | 22 | PWR | Power Input for LDO3 and LDO4. Bypass this pin to ground with a $4.7 \mu \mathrm{~F}$ or greater ceramic capacitor. Voltage on PVIN_LDO34 pin must not exceed voltage on VSYS pin. | Connect to VSYS |
| VLDO4 | 23 | PWR | Output Voltage of LDO4. Nominal output voltage is configured in EEPROM. Bypass this pin to ground with a $2.2 \mu \mathrm{~F}$ or greater ceramic capacitor. | Leave floating |
| FB_B3 | 24 | 1 | Feedback Input for Buck3. Connect to Buck3 output filter. Nominal output voltage is configured in EEPROM. | Connect to GND |

Table 5-1. Pin Functions (continued)

| PIN NAME | PIN NO. | TYPE | DESCRIPTION | CONNECTION if not used (output rails must be permanently disabled) |
| :---: | :---: | :---: | :---: | :---: |
| EN/PB/ VSENSE | 25 | 1 | ON-request input. <br> Configured as EN: Device enable pin, high level is ON-request, low-level is OFF-request. <br> Configured as PB: Push-button monitor input. 600 ms low-level is an ON -request, 8 s low-level is an OFF-request. <br> Configured as VSENSE: Power-fail comparator input. Set sense voltage using a resistor divider connected from the input to the pre-regulator to this pin to ground. Detects rising/falling voltage on pre-regulator and triggers ON- / OFF-request. <br> The pin is edge-sensitive with a wait-time in PB-configuration and deglitch time for EN- and VSENSE-configuration. | $\mathrm{n} / \mathrm{a}$ (configure as EN and connect to VSYS) |
| PVIN_B3 | 26 | PWR | Power Input for BUCK3. Bypass this pin to ground with a $4.7 \mu \mathrm{~F}$ or greater ceramic capacitor. Voltage on PVIN_B3 pin must not exceed voltage on VSYS pin. | Connect to VSYS |
| LX_B3 | 27 | PWR | Switch Pin for Buck3. Connect one side of the Buck3-inductor to this pin. | Leave floating |
| MODE/RESET | 28 | 1 | Multi-Function-Pin: <br> Configured as MODE: Connected to SoC or hardwired pull-up/-down. Forces the Buck-converters into PWM or permits auto-entry in PFM-mode. Configured as RESET: Connected to SoC. Forces a WARM or COLD reset (configurable), WARM reset resetting output voltages to defaults, COLD reset sequencing down all enabled rails and power up again. <br> Polarity is configurable. <br> The pin is level-sensitive for MODE-configuration, edge-sensitive for RESET-configuration. | $\mathrm{n} / \mathrm{a}$ (tie high or low, dependent on configuration, see 'PWM/PFM and Reset (MODE/RESET)' |
| LX_B2 | 29 | PWR | Switch Pin for Buck2. Connect one side of the Buck2-inductor to this pin. | Leave floating |
| PVIN_B2 | 30 | PWR | Power Input for BUCK2. Bypass this pin to ground with a $4.7 \mu \mathrm{~F}$ or greater ceramic capacitor. Voltage on PVIN_B2 pin must not exceed voltage on VSYS pin. | Connect to VSYS |
| MODE/STBY | 31 | 1 | Multi-Function-Pin: <br> Configured as MODE: <br> Connected to SoC or hard-wired pull-up/-down. <br> Forces the Buck-converters into PWM or permits <br> auto-entry in PFM-mode. <br> Configured as STBY: Low-power-mode command, disables selected rails. <br> Both functions, MODE and STBY, can be combined. <br> The pin is level-sensitive. | $\mathrm{n} / \mathrm{a}$ (tie high or low, dependent on configuration, see 'PWM/PFM and Low Power Modes (MODE/ STBY)' |
| FB_B2 | 32 | 1 | Feedback Input for Buck2. Connect to Buck2 output filter. Nominal output voltage is configured in EEPROM. | Connect to GND |

Table 5-1. Pin Functions (continued)

| PIN NAME | PIN NO. | TYPE | DESCRIPTION <br> PGNECTION if not used <br> (output rails must be <br> permanently disabled) |  |
| :---: | :---: | :---: | :--- | :--- |
| PGND | PowerPad | GND | Power-Ground. The exposed pad must be <br> connected to a continuous ground plane of the <br> printed circuit board by multiple interconnect vias <br> directly under the TPS65220 to maximize electrical <br> and thermal conduction. | $\mathrm{n} / \mathrm{a}$ |

TPS65220
SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ${ }^{(1)}$

| POS |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 1.1.1 | Input voltage | VSYS | -0.3 | 6 | V |
| 1.1.2 | Input voltage | PVIN_B1, PVIN_B2, PVIN_B3, PVIN_LDO1, PVIN_LDO2, PVIN_LDO34 | -0.3 | 6 | V |
| 1.1.3 | Input voltage vs. VSYS for Bucks | PVIN_B1, PVIN_B2, PVIN_B3 maximum voltage exceeding VSYS |  | 200 | mV |
| 1.1.4 | Input voltage vs. VSYS for LDOs | PVIN_LDO1, PVIN_LDO2, PVIN_LDO34 maximum voltage exceeding VSYS |  | 20 | mV |
| 1.1.5 | Input voltage | FB_B1, FB_B2, FB_B3 | -0.3 | 6 | V |
| 1.1.6 | Input voltage | EN/PB/VSENSE, MODE/STBY, MODE/RESET, VSEL_SD/VSEL_DDR | -0.3 | 6 | V |
| 1.2.1 | Output voltage | LX_B1, LX_B2, LX_B3 | $-0.3$ | $\begin{array}{r} \mathrm{N} \text { Bx }+ \\ , \text { up to } \\ 6 \mathrm{~V} \end{array}$ | V |
| 1.2.2 | Output voltage | LX_B1, LX_B2, LX_B3 spikes for maximum 10ns | -2 | 10 | V |
| 1.2.3 | Output voltage | GPO1, GPO2, GPIO | -0.3 | 6 | V |
| 1.2.4 | Output voltage | VLDO1, VLDO2, VLDO4, VLDO4 | $-0.3$ | $\begin{aligned} & \text { LDOx } \\ & 3 \mathrm{~V}, \mathrm{up} \\ & \text { to } 6 \mathrm{~V} \end{aligned}$ | V |
| 1.2.5 | Output voltage | VDD1P8 | -0.3 | 2 | V |
| 1.2.6 | Output voltage | SDA, SCL | -0.3 | 6 | V |
| 1.2.7 | Output voltage | nINT, nRSTOUT | -0.3 | 6 | V |
| 1.4.1 | Operating junction temperature, $\mathrm{T}_{J}$ |  | -40 | 150 | ${ }^{\circ} \mathrm{C}$ |
| 1.4.2 | Storage temperature, $\mathrm{T}_{\text {stg }}$ |  | -40 | 150 | ${ }^{\circ} \mathrm{C}$ |

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

### 6.2 ESD Ratings

| POS |  |  |  | VALUE | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 2.1 | $\mathrm{V}_{(\mathrm{ESD})}$ | Electrostatic discharge, Human Body Model | Human body model (HBM), per ANSI/ ESDA/JEDEC JS-001, all pins ${ }^{(1)}$ | $\pm 2000$ | V |
| 2.2 | $\mathrm{V}_{(\mathrm{ESD})}$ | Electrostatic discharge, Charged Device Model | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ${ }^{(2)}$ | $\pm 500$ | V |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| POS |  |  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 3.1.1 | $\mathrm{V}_{\text {VSYS }}$ | Input voltage | $2.5{ }^{(1)}$ |  | 5.5 | V |
| 3.1.2 | $\mathrm{V}_{\text {PVIN_B1 }}, \mathrm{V}_{\text {PVIN_B2 }}$, <br> $V_{\text {PVIN_B3 }}$ <br> $V_{L X \_B}, V_{L X \_B 2}$, <br> VLX_B3 | BUCKx Pins | 2.5 |  | $5.5{ }^{(2)}$ | V |
| 3.1.3 | $\Delta \mathrm{V}_{\text {VSYS_PVIN_Bx }}$ | Voltage by which $\mathrm{V}_{\text {PVIN_Bx }}$ may exceed $\mathrm{V}_{\text {VSYS }}$ |  |  | 0 | mV |
| 3.1 .4 | $\Delta \mathrm{V}_{\text {VSYS_PVIN_LDO1,LDO2 }}$ | Voltage by which $\mathrm{V}_{\text {PVIN_LDO1 }}$ or $\mathrm{V}_{\text {PVIN_LDO2 }}$ may exceed $\mathrm{V}_{\mathrm{Vsys}}$ |  |  | 0 | mV |

TPS65220
SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 6.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  |  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 3.1.5 | $\Delta \mathrm{V}_{\text {VSYS_VLDO34 }}$ | Voltage by which $\mathrm{V}_{\text {Vsys }}$ must exceed LDO output voltage (VLDO3, VLDO4); $\mathrm{V}_{\mathrm{VSYS}}=2.5 \mathrm{~V}$ to 3.45 V ; LDO mode | 150 |  |  | mV |
| 3.1.6 | $\Delta \mathrm{V}_{\text {VSYS_VLDO34 }}$ | Voltage by which $V_{\text {VSYs }}$ must exceed LDO output voltage (VLDO3, VLDO4); $\mathrm{V}_{\text {VSYS }}=3.45 \mathrm{~V}$ to 5.5 V in LDO-mode or $\mathrm{V}_{\mathrm{VSYS}}=2.5 \mathrm{~V}$ to 5.5 V in LSW-mode | n/a |  |  | mV |
| 3.1.7 | CPVIn_B1, CPVIn_b2, CPVIN_B3 | BUCKx Input Capacitance | 3.9 | 4.7 |  | $\mu \mathrm{F}$ |
| 3.1.8 | $\mathrm{L}_{\mathrm{B} 1}, \mathrm{~L}_{\mathrm{B} 2}, \mathrm{~L}_{\mathrm{B} 3}$ | BUCKx Output Inductance | 330 | 470 | 611 | nH |
| 3.1.9a | Cout_b1, Cout_в2, Cout_b3 | BUCKx Output Capacitance, forced PWM or auto-PFM, low bandwidth case | 10 |  | 75 | $\mu \mathrm{F}$ |
| 3.1.9b | Cout_B1, Cout_в2, Cout_b3 | BUCKx Output Capacitance, fixed frequency, low BW case | 12 |  | 36 | $\mu \mathrm{F}$ |
| 3.1.10a | Cout_b1, Cout_b2, Cout_b3 | BUCKx Output Capacitance, forced PWM or auto-PFM, high bandwidth case | 30 |  | 220 | $\mu \mathrm{F}$ |
| 3.1.10b | Cout_b1, Cout_b2, Cout_b3 | BUCKx Output Capacitance, fixed frequency, high BW case | 48 |  | 144 | $\mu \mathrm{F}$ |
| 3.1.11 | $\begin{aligned} & \mathrm{V}_{\text {FB_B1 }}, \mathrm{V}_{\text {FB_B2 }}, \\ & \mathrm{V}_{\text {FB_B3 }} \end{aligned}$ | BUCKx FB Pins | 0 |  | $5.5{ }^{(2)}$ | V |
| 3.1.12 | $\mathrm{V}_{\text {PVIN_LDO1, }} \mathrm{V}_{\text {PVIN_LDO2 }}$ | LDO Input Voltage | 1.5 |  | $5.5{ }^{(2)}$ | V |
| 3.1.13 | $\mathrm{V}_{\text {PVIN_LDO1 }}, \mathrm{V}_{\text {PVIN_LDO2 }}$ | LDO Input Voltage in bypass mode | 1.5 |  | 3.6 | V |
| 3.1.14 | $\mathrm{V}_{\text {PVIN_LDO1 }}, \mathrm{V}_{\text {PVIN_LDO2 }}$ | Allowable delta between $V_{\text {PVIN_LDOx }}$ and configured $\mathrm{V}_{\text {VLDOx }}$ in bypass mode | -200 |  | 200 | mV |
| 3.1.15 | $\mathrm{V}_{\mathrm{VLDO} 1}, \mathrm{~V}_{\mathrm{VLDO} 2}$ | LDO Output Voltage Range | 0.6 |  | 3.4 | V |
| 3.1.16 | $\mathrm{C}_{\text {PVIN_LDO1 }}, \mathrm{C}_{\text {PVIN_LDO2 }}$ | LDO Input Capacitance | 1.6 | 2.2 |  | $\mu \mathrm{F}$ |
| 3.1.17 | $\mathrm{C}_{\mathrm{VLDO} 1}, \mathrm{C}_{\mathrm{VLDO} 2}$ | LDO Output Capacitance | 1.6 | 2.2 | 20 | $\mu \mathrm{F}$ |
| 3.1.18 | $\mathrm{V}_{\text {PVIN_LDO3, }} \mathrm{V}_{\text {PVIN_LDO4 }}$ | LDO Input Voltage | 2.2 |  | $5.5{ }^{(2)}$ | V |
| 3.1.19 | $\mathrm{V}_{\mathrm{VLDO}}$, $\mathrm{V}_{\mathrm{VLDO}}$ | LDO Output Voltage Range | 1.2 |  | 3.3 | V |
| 3.1.20 | $\mathrm{C}_{\text {PVIN_LDO34 }}$ | LDO Input Capacitance | 2.2 | 4.7 |  | $\mu \mathrm{F}$ |
| 3.1.21 | $\mathrm{C}_{\text {VLDO3 }}, \mathrm{C}_{\text {VLDO4 }}$ | LDO Output Capacitance | 1.6 | 2.2 | $30^{(3)}$ | $\mu \mathrm{F}$ |
| 3.1.22 | $\mathrm{V}_{\text {VDD1P8 }}$ | VDD1P8 pin | 0 |  | 1.8 | V |
| 3.1.23 | $\mathrm{C}_{\text {VDD1P8 }}$ | Internal Regulator Decoupling Capacitance | 1 | 2.2 | 4 | $\mu \mathrm{F}$ |
| 3.1.24 | $\mathrm{C}_{\text {VSYS }}$ | VSYS Input Decoupling Capacitance | 1 | 2.2 |  | $\mu \mathrm{F}$ |
| 3.1.25 | $\mathrm{V}_{\text {nint }}, \mathrm{V}_{\text {nRStout }}$ | Digital Outputs | 0 |  | 3.4 | V |
| 3.1.26 | $\mathrm{V}_{\text {GPO1 }}, \mathrm{V}_{\text {GPO2 }}, \mathrm{V}_{\text {GPIO }}$ | Digital Outputs | 0 |  | $5.5{ }^{(2)}$ | V |
| 3.1.27 | $\mathrm{V}_{\text {SCL }}, \mathrm{V}_{\text {SDA }}$ | I2C Interface | 0 |  | 3.4 | V |
| 3.1.28 | $\mathrm{V}_{\text {EN/PBNSEASE }}, \mathrm{V}_{\text {MODE/StBY }}$, <br> $\mathrm{V}_{\text {MODE/RESET }}$, <br> VVSEL_SDNSELIDDR | Digital Inputs | 0 |  | $5.5{ }^{(2)}$ | V |
| 3.2.1 | tVSYS_RAMP_RISE | Input voltage rising ramp Time, Input voltage controlled by a pre-regulator. $\mathrm{V}_{\mathrm{VSYS}}=$ $\mathrm{V}_{\text {PVIN_Bx }}=\mathrm{V}_{\text {PVIN_LDOX }}=0 \mathrm{~V}$ to 5 V | 0.1 |  | 600000 | ms |
| 3.2.2 | tVSYS_RAMP_FALL | Input voltage falling Ramp Time, $\mathrm{V}_{\text {vSYS }}=$ $\mathrm{V}_{\text {PVIN_Bx }}=\mathrm{V}_{\text {PVIN_LDOX }}=5 \mathrm{~V}$ to 2.5 V | 0.4 |  | 600000 | ms |
| 3.3.1 | $\mathrm{T}_{\mathrm{A}_{-}}$ | Operating free-air temperature | -40 |  | 125 | ${ }^{\circ} \mathrm{C}$ |
| 3.3.2 | $\mathrm{T}_{\mathrm{J}}$ | Operating junction temperature | -40 |  | 150 | ${ }^{\circ} \mathrm{C}$ |

(1) For EEPROM programming, $\mathrm{VSYS}(\mathrm{min})=3.3 \mathrm{~V}$
(2) Must not exceed VSYS

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(3) In slow-ramp-mode. Fast-ramp supports $15 \mu \mathrm{~F}$ maximum

### 6.4 Thermal Information

| THERMAL METRIC ${ }^{(1)}$ |  | TPS65220 | UNIT |
| :---: | :---: | :---: | :---: |
|  |  | RHB (QFN) |  |
|  |  | 32 PINS |  |
| $\mathrm{R}_{\text {©JA }}$ | Junction-to-ambient thermal resistance | 31.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {©JC(top) }}$ | Junction-to-case (top) thermal resistance | 20.4 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {©JB }}$ | Junction-to-board thermal resistance | 10.9 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\Psi_{\text {JT }}$ | Junction-to-top characterization parameter | 0.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\Psi_{\text {JB }}$ | Junction-to-board characterization parameter | 10.8 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {©JC(bot) }}$ | Junction-to-case (bottom) thermal resistance | 2.8 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

### 6.5 System Control Thresholds

Over operating free-air temperature range (unless otherwise noted). Voltage level refers to the AGND ground of the device.

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Electrical Characteristics |  |  |  |  |  |  |  |
| 4.1.1 | VSYS | Operating Input Voltage |  | 2.5 |  | 5.5 | V |
| 4.1.2 | VSYSPOR_Rising | VSYS POR rising threshold | Measured on VSYS pin, untrimmed | 2.2 |  | 2.5 | V |
| 4.1.3 | VSYS ${ }_{\text {UVLO_Falling }}$ | VSYS UVLO falling threshold | Measured on VSYS pin, trimmed | 2.175 |  | 2.25 | V |
| 4.1.4 | VSYS POR_Hyst | VSYS UVLO/POR hysteresis | VSYS ${ }_{\text {POR_Rising_untrimmed }}{ }^{-}$ VSYSUVLO_Falling_trimmed |  | 130 |  | mV |
| 4.1.5 | VVSYS_OVP_Rise | VSYS OVP rising threshold, trimmed | Measured on VSYS pin, trimmed | 5.9 |  | 6.1 | V |
| 4.1.6 | VVsYs_OVP_Fall | VSYS OVP falling threshold, trimmed | Measured on VSYS pin, trimmed | 5.7 |  | 5.95 | V |
| 4.1.7 | Vvsys_ovp_Hyst | VSYS OVP hysteresis | VSYS ${ }_{\text {OVP_Rising_trimmed }}{ }^{-}$ VSYS ${ }_{\text {OVP_falling_trimmed }}$ | 100 | 140 | 180 | mV |
| 4.1.8 | $\mathrm{V}_{\text {VID1P8 }}$ | VDD1P8 voltage |  | 1.7 | 1.8 | 1.9 | V |
| 4.2.1a | IInitialize | Current Consumption in INITIALIZE state, <br> at $25^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS = PVIN_Bx = PVIN_LDOx $=5 \mathrm{~V}$. All Monitors are off. $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ |  | 15 | 22 | $\mu \mathrm{A}$ |
| 4.2.1b | IInitialize | Current Consumption in INITIALIZE state, <br> $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS $=$ PVIN_Bx $=$ PVIN_LDOx $=5 \mathrm{~V}$. All Monitors are off. $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C}$ |  | 15 | 37 | $\mu \mathrm{A}$ |
| 4.2.2a | $\mathrm{I}_{\text {Active }}$ | ACTIVE State Current Consumption, all rails on, at $25^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS = PVIN_Bx = PVIN_LDOx $=5 \mathrm{~V}$. All Outputs are on, all LDOs in LDO-mode, Bucks in PFM mode. No Load. $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 250 | 290 | $\mu \mathrm{A}$ |
| 4.2.2b | $\mathrm{I}_{\text {Active }}$ | ACTIVE State Current Consumption, all rails on, $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS $=$ PVIN_Bx $=$ PVIN_LDOx $=5 \mathrm{~V}$. All Outputs are on, all LDOs in LDO-mode, Bucks in PFM mode. No Load. $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |  | 250 | 500 | $\mu \mathrm{A}$ |

TPS65220

### 6.5 System Control Thresholds (continued)

Over operating free-air temperature range (unless otherwise noted). Voltage level refers to the AGND ground of the device.

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 4.2.3a | Istby | STBY State Current Consumption, only LDO1 on, at $25^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS $=$ PVIN_Bx $=$ PVIN_LDOx $=5 \mathrm{~V}$. Only LDO1 on in LDO-mode. No Load. $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ |  | 105 | 125 | $\mu \mathrm{A}$ |
| 4.2.3b | Ister | STBY State Current Consumption, only LDO1 on, $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS $=$ PVIN_Bx $=$ PVIN_LDOx $=5 \mathrm{~V}$. Only LDO1 on in LDO-mode. No Load. $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |  | 105 | 150 | $\mu \mathrm{A}$ |
| 4.2.4a | Istby | STBY State Current Consumption, all rails on, VMON on at $25^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS $=$ PVIN_Bx $=$ PVIN_LDOx $=5$ V. All Outputs are on, all LDOs in LDO-mode, Bucks in PFM mode. No Load. Outputvoltage Monitors are on, VSYSmonitor (UV/OVP) are on. $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 250 | 290 | $\mu \mathrm{A}$ |
| 4.2.4b | Istay | STBY State Current Consumption, all rails on, VMON on, $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | Combined Current from VSYS and PVIN_x pins. VSYS $=$ PVIN_Bx $=$ PVIN_LDOx $=5 \mathrm{~V}$. All Outputs are on, all LDOs in LDO-mode,, Bucks in PFM mode. No Load. Outputvoltage Monitors are on, VSYSmonitor (UV/OVP) are on. $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |  | 250 | 500 | $\mu \mathrm{A}$ |
| Timing Requirements |  |  |  |  |  |  |  |
| 4.3.1 | toff_TO_INT | Time from VSYS passing VSYS_POR until entering INITIALIZE state, including EEPROM-read, ready for ONrequest | Time from VSYS passing VSYS_POR until entering INITIALIZE state. On request execution gated by HOT and RV |  |  | 3.2 | ms |
| 4.3.2a | $\mathrm{t}_{\text {TIMEOUT_UV }}$ | UV-detection in case a rail does not reach UV-threshold during ramp-up |  |  |  | end of <br> tramp + sampleand deglitch time |  |
| 4.3.2b | $\dagger_{\text {TIMEOUT_UV_SLOT }}$ | Timeout in case a rail does not reach UV-threshold during ramp-up, applicable in Multi-PMICconfiguration only |  |  |  | $\begin{array}{r} \hline \text { end of } \\ \text { slot- } \\ \text { extensi } \\ \text { on time } \\ (3 \mathrm{~ms}, \\ 4 \mathrm{~ms} \mathrm{or} \\ 13 \mathrm{~ms}) \end{array}$ |  |
| 4.3.3 | ${ }^{\text {t }}$ IMEOUT_Discharge | Timeout in case a rail cannot be discharged when transitioning from STBY to ACTIVE state |  | 72 | 80 | 88 | ms |

### 6.6 BUCK1 Converter

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Electrical Characteristics |  |  |  |  |  |  |  |
| 5.1.1a | $\mathrm{V}_{\text {IN_BUCK1 }}$ | Input voltage ${ }^{(1)}$ | Buck supply voltage, maximum VSYS | 2.5 |  | 5.5 | V |

TPS65220
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SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 6.6 BUCK1 Converter (continued)

over operating free-air temperature range (unless otherwise noted)

| POS | PARAMETER |  | TEST CONDITIONS | MIN | TYP | MAX |
| :--- | :--- | :--- | :--- | :--- | :---: | :---: | UNIT

TPS65220
SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 6.6 BUCK1 Converter (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 5.2.2b | VLine_reg | DC Line Regulation, fixed frequency, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \\ & \text { lout }=1 \mathrm{~mA} \text { and } \mathrm{I}_{\text {OUT MAX }} \\ & \text { fixed frequency, low } \mathrm{BW} \text { case, } \mathrm{C}_{\text {OUT }} \\ & =12 \mu \mathrm{~F} \end{aligned}$ |  | 0.1 | 0.16 | \%/V |
| 5.2.3a | VLoad_transient | Load Transient, $\mathrm{V}_{\text {OUT }}=0.75 \mathrm{~V}$, autoPFM, high BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.75 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=100 \mathrm{~mA} \text { to } 1100 \mathrm{~mA} \text { to } 100 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=500 \mathrm{~ns}, \\ & \text { auto-PFM, high BW case, Cout }= \\ & 80 \mu \mathrm{~F} \end{aligned}$ | -27.5 |  | 27.5 | mV |
| 5.2.3b | Vload_transient | Load Transient, $\mathrm{V}_{\text {OUT }}=0.75 \mathrm{~V}$, forced PWM, high BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.75 \mathrm{~V}, \\ & \mathrm{l}_{\text {OuT }}=100 \mathrm{~mA} \text { to } 1100 \mathrm{~mA} \text { to } 100 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=500 \mathrm{~ns}, \\ & \text { forced PWM, high BW case, Cout }= \\ & 80 \mu \mathrm{~F} \end{aligned}$ | -27.5 |  | 27.5 | mV |
| 5.2.3c | Vload_transient | Load Transient, $\mathrm{V}_{\text {OUT }}=0.75 \mathrm{~V}$, fixed frequency, high BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.75 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=\mathrm{l}_{\text {OUT }}=100 \mathrm{~mA} \text { to } 1100 \mathrm{~mA} \text { to } \\ & 100 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=500 \mathrm{~ns}, \\ & \text { fixed frequency, high BW case, } \\ & \mathrm{C}_{\text {OUT }}=60 \mu \mathrm{~F} \end{aligned}$ | -27.5 |  | 27.5 | mV |
| 5.2.4a | VLoad_transient | Load Transient, $\mathrm{V}_{\mathrm{OUT}}=1.8 \mathrm{~V}$, autoPFM, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}, \\ & \mathrm{louT}_{\mathrm{OUT}}=1 \mathrm{~mA} \text { to } 1 \mathrm{~A} \text { to } 1 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=1 \mu \mathrm{~s}, \\ & \text { auto-PFM, } \mathrm{C}_{\text {OUT }}=40 \mu \mathrm{~F} \end{aligned}$ | -90 |  | 90 | mV |
| 5.2.4b | Vload_transient | Load Transient, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}$, forced PWM, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~mA} \text { to } 1 \mathrm{~A} \text { to } 1 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=1 \mu \mathrm{~s}, \\ & \text { forced } \mathrm{PWM}, \mathrm{C}_{\text {OUT }}=40 \mu \mathrm{~F} \end{aligned}$ | -60 |  | 60 | mV |
| 5.2.4c | VLoad_transient | Load Transient, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}$, fixed frequency, low BW case | $\begin{aligned} & V_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{OUT}}=1 \mathrm{~mA} \text { to } 1 \mathrm{~A} \text { to } 1 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=1 \mu \mathrm{~s}, \\ & \text { fixed frequency, low BW case, } \mathrm{C}_{\mathrm{OUT}} \\ & =12 \mu \mathrm{~F} \end{aligned}$ | -180 |  | 180 | mV |
| 5.2.5a | VIINE_transient | Line Transient, $\mathrm{V}_{\mathrm{OUT}}=1.2 \mathrm{~V}$, forced PWM, low BW case | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ to 5.5 V in $50 \mu \mathrm{~s}$, $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=1 \mathrm{~mA}$ and lout_max, forced PWM, low BW case, $\mathrm{C}_{\text {OUT }}=$ $40 \mu \mathrm{~F}$ | -50 |  | 50 | mV |
| 5.2.5b | VIIne_transient | Line Transient, $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}$, fixed frequency, low BW case | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ to 5.5 V in $50 \mu \mathrm{~s}$, $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=1 \mathrm{~mA}$ and lout_max, fixed frequency, low BW case, Cout $=12 \mu \mathrm{~F}$ | -50 |  | 50 | mV |
| 5.2.6a | $\mathrm{V}_{\text {RIPPLE_PP_PWM }}$ | Forced PWM Mode, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {Out }}=2.5 \mathrm{~V}, \\ & \text { forced PWM, low } B W \text { case, } \mathrm{C}_{\text {OUT }}= \\ & 40 \mathrm{uF}, \mathrm{X} 5 \mathrm{R}, \mathrm{ESR}=10 \mathrm{mOhm}, \\ & \mathrm{~L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega \\ & \text { lout }=1 \mathrm{~A} \end{aligned}$ |  | 10 | 20 | mV PP |
| 5.2.6b | VRIPPLE_PP_PFM | Auto PFM Mode, low BW case | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=2.5 \mathrm{~V}, \\ & \text { auto } \mathrm{PFM}, \text { low } \mathrm{BW} \text { case, } \mathrm{C}_{\text {OUT }}= \\ & 40 \mathrm{uF}, \mathrm{X} 5 \mathrm{R}, \mathrm{ESR}=10 \mathrm{mOhm}, \\ & \mathrm{~L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega \\ & \text { lout }=20 \mathrm{~mA} \end{aligned}$ |  | 20 | 40 | mV PP |

### 6.6 BUCK1 Converter (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 5.2.6c | $\mathrm{V}_{\text {RIPPLE_PP_FF }}$ | Fixed Frequency Mode, low BW case, spread spectrum disabled | $\begin{aligned} & V_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=2.5 \mathrm{~V}, \\ & \text { fixed frequency, low } \mathrm{BW} \text { case, } \mathrm{C}_{\text {OUT }} \\ & =12 \mathrm{uF}, \mathrm{X} 5 \mathrm{R}, \mathrm{ESR}=10 \mathrm{mOhm}, \\ & \mathrm{~L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega, \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~A}, \\ & \text { Spread-Spectrum disabled } \end{aligned}$ |  | 10 | 20 | mV PP |
| 5.2.6d | $\mathrm{V}_{\text {RIPPLE_PP_FF_SS }}$ | Fixed Frequency Mode, Iow BW case | $\begin{aligned} & V_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=2.5 \mathrm{~V}, \\ & \text { fixed frequency, low } \mathrm{BW} \text { case, } \mathrm{C}_{\text {OUT }} \\ & =12 \mathrm{uF}, \mathrm{X} 5 \mathrm{R}, \mathrm{ESR}=10 \mathrm{mOhm}, \\ & \mathrm{~L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega, \\ & \mathrm{l}_{\text {Out }}=1 \mathrm{~A}, \\ & \text { Spread-Spectrum enabled } \end{aligned}$ |  | 20 | 40 | mV PP |
| 5.3.1 | Iout_max | Maximum Operating Current |  |  |  | 3.5 | A |
| 5.3.2 | ICURRENT_LIMIT | Peak Current Limit | $\mathrm{V}_{\mathrm{IN}}=2.5 \mathrm{~V}$ to 5.5 V | 4.6 | 5.7 | 6.9 | A |
| 5.3.3 | IREV_CUR_LIMIT | Reverse Peak Current Limit | $\mathrm{V}_{\mathrm{IN}}=2.5 \mathrm{~V}$ to 5.5 V | -2.0 | -1.5 | -1.0 | A |
| 5.3.4a | $\mathrm{R}_{\text {DSON_HS }}$ | High Side MOSFET On Resistance, 5V-supply | Measured Pin to Pin, $\mathrm{V}_{\mathrm{IN}}=5 \mathrm{~V}$ |  |  | 70 | $\mathrm{m} \Omega$ |
| 5.3.4b | $\mathrm{R}_{\text {DSON_HS }}$ | High Side MOSFET On Resistance, 3.3V-supply | Measured Pin to Pin, $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$ |  |  | 80 | $\mathrm{m} \Omega$ |
| 5.3.5a | $\mathrm{R}_{\text {DSON_LS }}$ | Low Side MOSFET On Resistance, 5 V -supply | Measured Pin to Pin, $\mathrm{V}_{\mathrm{IN}}=5 \mathrm{~V}$ |  |  | 40 | $\mathrm{m} \Omega$ |
| 5.3.5b | $\mathrm{R}_{\text {DSON_LS }}$ | Low Side MOSFET On Resistance, 3.3V-supply | Measured Pin to Pin, $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$ |  |  | 50 | $\mathrm{m} \Omega$ |
| 5.3.6 | $\mathrm{R}_{\text {discharge }}$ | Output Discharge Resistance | Active only when converter is disabled | 60 | 125 | 200 | $\Omega$ |
| 5.4.1 | Lsw | Output Inductance | DCR $=50 \mathrm{~m} \Omega$ max | 330 | 470 | 611 | nH |
| 5.4.2a | $\mathrm{C}_{\text {OUT }}$ | Output Capacitance in auto-PFM or forced PWM for low BW case | $E S R=10 \mathrm{~m} \Omega$ max | 10 |  | 75 | $\mu \mathrm{F}$ |
| 5.4.2b | Cout_FF | Output Capacitance in fixed frequency for low BW case | $E S R=10 \mathrm{~m} \Omega$ max | 12 |  | 36 | $\mu \mathrm{F}$ |
| 5.4.3a | Cout_high_bw | Output Capacitance in auto-PFM or forced PWM for high BW case | $E S R=10 \mathrm{~m} \Omega \mathrm{max}$ | 30 |  | 220 | $\mu \mathrm{F}$ |
| 5.4.3b | Cout_HIGH_bW_FF | Output Capacitance in fixed frequency for high BW case | $E S R=10 \mathrm{~m} \Omega$ max | 48 |  | 144 | $\mu \mathrm{F}$ |
| Timing Requirements |  |  |  |  |  |  |  |
| 5.5.1 | $\mathrm{t}_{\text {RAMP }}$ | Ramp Time in forced PWM, low BW case | Time from enable to $98 \%$ of target value, assuming no residual voltage | 0.3 |  | 1.65 | ms |
| 5.5.2a | $\begin{aligned} & \text { DVFS_RISE_ } \\ & \text { QFF } \end{aligned}$ | DVFS timing requirements in forced PWM, rising slope | Step-duration during DVFS voltage adjustments from 0.6 V to 1.4 V | 2.9 | 3.2 | 3.5 | $\mathrm{mV} / \mathrm{\mu s}$ |
| 5.5.2b | $\begin{aligned} & \text { DVFS_RISE_ } \\ & \text { FF } \end{aligned}$ | DVFS timing requirements in fixedfrequency mode, rising slope | Step-duration during DVFS voltage adjustments from 0.6 V to 1.4 V | 1.8 | 2.1 | 2.5 | $\mathrm{mV} / \mathrm{\mu s}$ |
| 5.5.2c | DVFS_FALL | DVFS timing requirements in forced PWM or fixed-frequency mode, falling slope | Step-duration during DVFS voltage adjustments from 1.4 V to 0.6 V | 0.45 | 0.53 | 0.61 | $\mathrm{mV} / \mathrm{\mu s}$ |
| Switching Characteristics |  |  |  |  |  |  |  |
| 5.6.1a | $\mathrm{f}_{\text {Sw }}$ | Switching Frequency, forced PWM, high or low BW case | $\begin{aligned} & \text { Forced } \mathrm{PWM}, \mathrm{~V}_{\text {IN }}=3.3 \mathrm{~V} \text { to } 5 \mathrm{~V} \text {, } \\ & \mathrm{V}_{\text {OUT }}=0.8 \mathrm{~V} \text { to } 1.8 \mathrm{~V} \text {, } \\ & \text { lout }=1 \mathrm{~A} \text { to } 3 \mathrm{~A} \end{aligned}$ |  | 2.3 |  | MHz |
| 5.6.1b | fsw | Switching Frequency, fixed frequency, high or low BW case, no Spread Spectrum | $\begin{aligned} & \text { Fixed }- \text { Frequency, } \mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V} \text { to } 5 \mathrm{~V} \text {, } \\ & \mathrm{V}_{\text {OUT }}=0.8 \mathrm{~V} \text { to } 1.8 \mathrm{~V} \text {, } \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~A} \text { to } 3 \mathrm{~A} \end{aligned}$ | 2.18 | 2.3 | 2.42 | MHz |

TPS65220

## SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 6.6 BUCK1 Converter (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 5.6.2 | $\mathrm{f}_{\text {SW_SS_EN }}$ | Switching Frequency, fixed frequency, high or low BW case, with Spread Spectrum enabled | $\begin{aligned} & \text { Fixed - Frequency, } \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V} \text { to } 5 \mathrm{~V} \text {, } \\ & \mathrm{V}_{\text {OUT }}=0.8 \mathrm{~V} \text { to } 1.8 \mathrm{~V}, \\ & \text { lout }=1 \mathrm{~A} \text { to } 3 \mathrm{~A} \\ & \text { Spread spectrum enabled } \end{aligned}$ | 1.95 |  | 2.65 | MHz |

(1) PVIN_Bx must not exceed VSYS
(2) Refers to DC-regulation only. Transient response may require more headroom. With low headroom, the frequency variation increases for quasi-fixed frequency.

### 6.7 BUCK2, BUCK3 Converter

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Electrical Characteristics |  |  |  |  |  |  |  |
| 6.1.1a | VIN_BUCK23 | Input Voltage ${ }^{(1)}$ | Buck supply voltage, maximum VSYS | 2.5 |  | 5.5 | V |
| 6.1.1b | Vout_buck23 | Buck Output Voltage configurable Range | Output voltage configurable in 25 mV -steps for $0.6 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 1.4 \mathrm{~V}$, in 100 mV steps for $1.4 \mathrm{~V}<\mathrm{V}_{\text {OUT }} \leq$ 3.4 V | 0.6 |  | 3.4 | V |
| 6.1.2a | lQ_buck23 | Quiescent Current at $25^{\circ} \mathrm{C}, \mathrm{PFM}$ | PFM, BUCKx enabled, no load, $\mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 10 | 13 | $\mu \mathrm{A}$ |
| 6.1.2b | $\mathrm{l}_{\text {Q_BuCK23 }}$ | Quiescent Current $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$, PFM, low BW case | PFM, BUCKx enabled, no load, $\mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  | 15 | 43 | $\mu \mathrm{A}$ |
| 6.1.2c | $\mathrm{l}_{\text {Q_BuCK23 }}$ | Quiescent Current $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$, PFM, low BW case | PFM, BUCKx enabled, no load, $\mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |  | 20 | 63 | $\mu \mathrm{A}$ |
| 6.1.3a | V HEADROOM_PWM | Input to Output Voltage Headroom ${ }^{(2)}$ | Corner cases at maximum load I IOT $=1.7 \mathrm{~A}$ | 500 |  |  | mV |
| 6.1.3b | Vheadroom_PWm | Input to Output Voltage Headroom at $\mathrm{I}_{\text {OUT }}=\mathrm{I}_{\text {OUT_MAX }}{ }^{(2)}$ | Corner cases at lout $=$ lout_max | 700 |  |  | mV |
| 6.1.3c | $\mathrm{V}_{\text {HEADROOM_FF }}$ | Input to Output Voltage Headroom ${ }^{(2)}$ | Corner cases at maximum load lout $=0.5 \mathrm{~A}$ | 500 |  |  | mV |
| 6.1.3d | $\mathrm{V}_{\text {HEADROOM_FF }}$ | Input to Output Voltage Headroom at lout $=$ lout_MAX $^{(2)}$ | Corner cases at lout $=\mathrm{l}_{\text {OUt_MAX }}$ | 1000 |  |  | mV |
| 6.1.4 | Vout_Step_Low | Output voltage Steps Buck2 and Buck3 | $0.6 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 1.4 \mathrm{~V}$ |  | 25 |  | mV |
| 6.1.5 | V OUT_STEP_HIGH | Output voltage Steps Buck2, Buck3 | $1.5 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 3.4 \mathrm{~V}$ |  | 100 |  | mV |
| 6.1.6a | Vout_Acc_Dc_pw <br> M | DC Output Voltage Accuracy in forced PWM mode, low and high BW case | $\begin{aligned} & \mathrm{l}_{\text {OUT }}=\mathrm{I}_{\text {OUT }} \text { MAX, } \\ & \mathrm{V}_{\text {OUT }} \geq 0.7 \overline{\mathrm{~V}} \text { to } 3.4 \mathrm{~V}, \\ & \mathrm{~V}_{\text {IN }}-\mathrm{V}_{\text {OUT }}>700 \mathrm{mV} \\ & \text { forced PWM, low BW case } \end{aligned}$ | -1.5\% |  | 1.5\% |  |
| 6.1.6b | VOUT_ACC_DC_PW <br> M | DC Output Voltage Accuracy in forced PWM mode, low and high BW case | $\begin{aligned} & \text { Iout }=I_{\text {OUT }} \text { MAX, } \\ & V_{\text {OUT }}=0.6 V \text { to } 0.7 \mathrm{~V}, \\ & \mathrm{~V}_{\text {IN }}-\mathrm{V}_{\text {OUT }}>700 \mathrm{mV} \\ & \text { forced PWM, low BW case } \end{aligned}$ | -10 |  | 10 | mV |
| 6.1.6c | VOUT_ACC_DC_PFM | DC Output Voltage Accuracy in auto-PFM mode, low and high BW case | $\begin{aligned} & \mathrm{I}_{\text {OUT }}=1 \mathrm{~mA}, \\ & \mathrm{~V}_{\text {OUT }}=0.6 \mathrm{~V} \text { to } 3.4 \mathrm{~V}, \\ & \mathrm{~V}_{\text {IN }}-\mathrm{V}_{\text {OUT }}>500 \mathrm{mV} \\ & \text { auto-PFM, low BW case } \end{aligned}$ | -3.0\% |  | 3.5\% |  |
| 6.1.6d | Vout_Acc_dc_fF | DC Output Voltage Accuracy in Fixed Frequency mode, low and high BW case | $\begin{aligned} & \text { lout }=I_{\text {OUT }} \text { MAX, } \\ & V_{\text {OUT }} \geq 0.7 \mathrm{~V} \text { to } 3.4 \mathrm{~V}, \\ & \mathrm{~V}_{\text {IN }}-\mathrm{V}_{\text {OUT }}>1000 \mathrm{mV} \\ & \text { fixed frequency, low } \mathrm{BW} \text { case } \end{aligned}$ | -1.5\% |  | 1.5\% |  |

### 6.7 BUCK2, BUCK3 Converter (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 6.1.6e | VOUT_ACC_DC_FF | DC Output Voltage Accuracy in Fixed Frequency mode, low and high BW case | $\begin{aligned} & \mathrm{I}_{\text {OUT }}=\mathrm{I}_{\text {OUT }} \text { MAX, } \\ & \mathrm{V}_{\text {OUT }}=0.6 \mathrm{~V} \text { to } 0.7 \mathrm{~V}, \\ & \mathrm{~V}_{\text {IN }}-V_{\text {OUT }}>1000 \mathrm{mV} \\ & \text { fixed frequency, low BW case } \end{aligned}$ | -10 |  | 10 | mV |
| 6.1.9 | $\mathrm{R}_{\text {FB_INPUT }}$ | Feedback input impedance | Converter enabled | 2.3 | 3.75 | 5.0 | $\mathrm{M} \Omega$ |
| 6.2.1a | VLOAD_REG_PWM | DC Load Regulation, forced PWM, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=0 \text { to } \text { IOUT_MAX, } \end{aligned}$ forced PWM, low BW case |  | 0.1 | 0.16 | \%/A |
| 5.2.1b | VLOAD_REG_FF | DC Load Regulation, fixed frequency, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=0 \text { to } \text { lout, MAX } \\ & \text { fixed frequency, low BW case, } \mathrm{C}_{\text {OUT }} \\ & =40 \mu \mathrm{~F} \end{aligned}$ |  | 0.1 | 0.16 | \%/A |
| 6.2.2a | VIINe_reg | DC Line Regulation, forced PWM, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{~V}_{\text {Out }}=1.2 \mathrm{~V}, \\ & \mathrm{l}_{\text {OuT }}=1 \mathrm{~mA} \text { and } \mathrm{I}_{\text {OUT }} \mathrm{mAx} \\ & \text { forced PWM, low BW case, C COUT }= \\ & 40 \mu \mathrm{~F} \end{aligned}$ |  | 0.1 | 0.16 | \%/V |
| 6.2.2b | VLine_reg | DC Line Regulation, fixed frequency, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V} \text { to } 5.5 \mathrm{~V}, \\ & \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~mA} \text { and } \mathrm{IOUT}_{\text {MAX }} \\ & \text { fixed frequency, low } \overline{\mathrm{BW}} \text { case, } \mathrm{C}_{\text {OUT }} \\ & =12 \mu \mathrm{~F} \end{aligned}$ |  | 0.1 | 0.16 | \%/V |
| 6.2.3a | VLOAD_TRANSIENT | Load Transient, $\mathrm{V}_{\text {OUT }}=0.75 \mathrm{~V}$, autoPFM, high BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.75 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=100 \mathrm{~mA} \text { to } 1100 \mathrm{~mA} \text { to } 100 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=500 \mathrm{~ns}, \\ & \text { auto-PFM, high BW case, } \mathrm{C}_{\text {OUT }}= \\ & 80 \mu \mathrm{~F} \end{aligned}$ | -27.5 |  | 27.5 | mV |
| 6.2.3b | VLoad_transient | Load Transient, $\mathrm{V}_{\text {OUT }}=0.75 \mathrm{~V}$, forced PWM, high BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.75 \mathrm{~V}, \\ & \mathrm{l}_{\text {Out }}=100 \mathrm{~mA} \text { to } 1100 \mathrm{~mA} \text { to } 100 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=500 \mathrm{~ns}, \\ & \text { forced } \mathrm{PWM}, \text { high BW case, } \mathrm{C}_{\text {OUT }}= \\ & 80 \mu \mathrm{~F} \end{aligned}$ | -27.5 |  | 27.5 | mV |
| 6.2.3c | VLoAd_TRANSIENT | Load Transient, $\mathrm{V}_{\text {OUT }}=0.75 \mathrm{~V}$, fixed frequency, high BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0.75 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=\mathrm{l}_{\text {OUT }}=100 \mathrm{~mA} \text { to } 1100 \mathrm{~mA} \text { to } \\ & 100 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=500 \mathrm{~ns}, \\ & \text { fixed frequency, high BW case, } \\ & \mathrm{C}_{\text {OUT }}=60 \mu \mathrm{~F} \end{aligned}$ | -27.5 |  | 27.5 | mV |
| 6.2.4a | VLoAd_TRANSIENT | Load Transient, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}$, autoPFM, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~mA} \text { to } 1 \mathrm{~A} \text { to } 1 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=1 \mu \mathrm{~s}, \\ & \text { auto-PFM, } \mathrm{C}_{\text {OUT }}=40 \mu \mathrm{~F} \end{aligned}$ | -90 |  | 90 | mV |
| 6.2.4b | VLoAd_TRANSIENT | Load Transient, $\mathrm{V}_{\mathrm{OUT}}=1.8 \mathrm{~V}$, forced PWM, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{OUT}}=1 \mathrm{~mA} \text { to } 1 \mathrm{~A} \text { to } 1 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=1 \mu \mathrm{~s}, \\ & \text { forced PWM, } \mathrm{C}_{\mathrm{OUT}}=40 \mu \mathrm{~F} \end{aligned}$ | -60 |  | 60 | mV |
| 6.2.4c | VLoAd_TRANSIENT | Load Transient, $\mathrm{V}_{\text {OUT }}=1.8 \mathrm{~V}$, fixed frequency, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~mA} \text { to } 1 \mathrm{~A} \text { to } 1 \mathrm{~mA}, \\ & \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=1 \mu \mathrm{~s}, \\ & \text { fixed frequency, low BW case, } \mathrm{C}_{\text {OUT }} \\ & =12 \mu \mathrm{~F} \end{aligned}$ | -180 |  | 180 | mV |
| 6.2.5a | Vline_transient | Line Transient, $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}$, forced PWM, low BW case | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ to 5.5 V in $50 \mu \mathrm{~s}$, <br> $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}$, $\mathrm{I}_{\text {OUT }}=1 \mathrm{~mA}$ and <br> lout_max, <br> forced PWM, low BW case, $\mathrm{C}_{\text {Out }}=$ $40 \mu \mathrm{~F}$ | -50 |  | 50 | mV |

TPS65220
SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 6.7 BUCK2, BUCK3 Converter (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 6.2.5b | VLIne_TRANSIENT | Line Transient, $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}$, fixed frequency, low BW case | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ to 5.5 V in $50 \mu \mathrm{~s}$, <br> $\mathrm{V}_{\text {OUT }}=1.2 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=1 \mathrm{~mA}$ and <br> lout max, <br> fixed frequency, low BW case, Cout $=12 \mu \mathrm{~F}$ | -50 |  | 50 | mV |
| 6.2.6a | VRIPPLE_PP_PWM | Forced PWM Mode, low BW case | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=2.5 \mathrm{~V}, \\ & \text { forced PWM, low BW case, } \mathrm{C}_{\text {OUT }}= \\ & 40 \mathrm{uF}, \mathrm{X} 5 \mathrm{R}, \mathrm{ESR}=10 \mathrm{mOhm}, \\ & \mathrm{~L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega \\ & \mathrm{l}_{\text {out }}=1 \mathrm{~A} \end{aligned}$ |  | 10 | 20 | $m V_{P P}$ |
| 6.2.6b | V RIPPLE _PP_PFM | Auto PFM Mode, low BW case | $\mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=2.5 \mathrm{~V},$ auto PFM, low BW case, Cout $=$ $40 \mathrm{uF}, \mathrm{X} 5 \mathrm{R}, \mathrm{ESR}=10 \mathrm{mOhm}$, $\mathrm{L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega$ $\mathrm{l}_{\text {OUt }}=20 \mathrm{~mA}$ |  | 20 | 40 | $m V_{P P}$ |
| 6.2.6c | VRIPPLE_PP_FF | Fixed Frequency Mode, low BW case, spread spectrum disabled | $\mathrm{V}_{\mathrm{IN}}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=2.5 \mathrm{~V},$ <br> fixed frequency, low BW case, Cout $=12 u F, X 5 R, E S R=10 \mathrm{mOhm}$, $\mathrm{L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega$, $\mathrm{I}_{\text {OUt }}=1 \mathrm{~A}$, <br> Spread-Spectrum disabled |  | 10 | 20 | $m V_{P P}$ |
| 6.2.6d | VRIPPLE_PP_FF_SS | Fixed Frequency Mode, low BW case, spread spectrum enabled | $\mathrm{V}_{\text {IN }}=5.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{OUT}}=2.5 \mathrm{~V},$ <br> fixed frequency, low BW case, Cout $=12 u F, X 5 R, E S R=10 \mathrm{mOhm},$ $\mathrm{L}=470 \mathrm{nH}, \mathrm{DCR}=50 \mathrm{~m} \Omega \text {, }$ <br> lout $=1 \mathrm{~A}$, <br> Spread-Spectrum enabled |  | 20 | 40 | $m V_{P P}$ |
| 6.3.1 | Iout_max | Maximum Operating Current |  |  |  | 2.0 | A |
| 6.3 .2 | ICURRENT_LIMIT | Peak Current Limit | $\mathrm{V}_{\mathrm{IN}}=2.5 \mathrm{~V}$ to 5.5 V | 3.1 | 3.9 | 4.7 | A |
| 6.3.3 | $\mathrm{I}_{\text {REV_CUR_LIMIT }}$ | Reverse Peak Current Limit | $\mathrm{V}_{\mathrm{IN}}=2.5 \mathrm{~V}$ to 5.5 V | -2.0 | -1.5 | -1.0 | A |
| 6.3.4a | $\mathrm{R}_{\text {DSON_HS }}$ | High Side MOSFET On Resistance, 5V-supply | Measured Pin to Pin, $\mathrm{V}_{\text {IN }}=5 \mathrm{~V}$ |  |  | 110 | $\mathrm{m} \Omega$ |
| 6.3.4b | $\mathrm{R}_{\text {DSON_HS }}$ | High Side MOSFET On Resistance, 3.3V-supply | Measured Pin to Pin, $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$ |  |  | 135 | $\mathrm{m} \Omega$ |
| 6.3.5a | $\mathrm{R}_{\text {DSON_LS }}$ | Low Side MOSFET On Resistance, 5V-supply | Measured Pin to Pin, $\mathrm{V}_{\text {IN }}=5 \mathrm{~V}$ |  |  | 110 | $\mathrm{m} \Omega$ |
| 6.3.5b | $\mathrm{R}_{\text {DSON_LS }}$ | Low Side MOSFET On Resistance, 3.3V-supply | Measured Pin to Pin, $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ |  |  | 130 | $\mathrm{m} \Omega$ |
| 6.3.6 | $\mathrm{R}_{\text {Discharge }}$ | Output Discharge Resistance | Active only when converter is disabled | 60 | 125 | 200 | $\Omega$ |
| 6.4.1 | Lsw | Output Inductance | DCR $=50 \mathrm{~m} \Omega$ max | 330 | 470 | 611 | nH |
| 6.4.2a | Cout | Output Capacitance in auto-PFM or forced PWM for low BW case | $E S R=10 \mathrm{~m} \Omega$ max | 10 |  | 75 | $\mu \mathrm{F}$ |
| 6.4.2b | Cout_fF | Output Capacitance in fixed frequency for low BW case | $\mathrm{ESR}=10 \mathrm{~m} \Omega$ max | 12 |  | 36 | $\mu \mathrm{F}$ |
| 6.4.3a | CoUt_HIGH_BW | Output Capacitance in auto-PFM or forced PWM for high BW case | $E S R=10 \mathrm{~m} \Omega$ max | 30 |  | 220 | $\mu \mathrm{F}$ |
| 6.4.3b | C OUT_HIGH_BW_FF | Output Capacitance in fixed frequency for high BW case | $E S R=10 \mathrm{~m} \Omega$ max | 48 |  | 144 | $\mu \mathrm{F}$ |
| Timing Requirements |  |  |  |  |  |  |  |
| 6.5.1 | $t_{\text {RAMP }}$ | Ramp Time in quasi-fixed-frequency mode | Time from enable to $98 \%$ of target value, assuming no residual voltage | 0.3 |  | 1.65 | ms |
| 6.5.2a | DVFS_SLOPE_ QFF | DVFS timing requirements in forced PWM, low BW case | Step-duration during DVFS voltage adjustments from 0.6 V to 1.4 V | 2.9 | 3.2 | 3.5 | $\mathrm{mV} / \mu \mathrm{s}$ |

TPS65220
www.ti.com
SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 6.7 BUCK2, BUCK3 Converter (continued)

over operating free-air temperature range (unless otherwise noted)

| POS | PARAMETER |  | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 6.5.2b | $\begin{aligned} & \text { DVFS_SLOPE_ } \\ & \text { FF } \end{aligned}$ | DVFS timing requirements in fixedfrequency mode, low BW case | Step-duration during DVFS voltage adjustments from 0.6 V to 1.4 V | 1.8 | 2.1 | 2.5 | $\mathrm{mV} / \mathrm{\mu s}$ |
| Switching Characteristics |  |  |  |  |  |  |  |
| 6.5.2c | DVFS_FALL | DVFS timing requirements in forced PWM or fixed-frequency mode, falling slope | Step-duration during DVFS voltage adjustments from 1.4 V to 0.6 V | 0.45 | 0.53 | 0.61 | $\mathrm{mV} / \mathrm{\mu s}$ |
| 6.6.1a | $\mathrm{f}_{\mathrm{S}}$ w | Switching Frequency, forced PWM, high or low BW case | $\begin{aligned} & \text { Forced } \mathrm{PWM}, \mathrm{~V}_{\text {IN }}=3.3 \mathrm{~V} \text { to } 5 \mathrm{~V} \text {, } \\ & \mathrm{V}_{\text {OUT }}=0.8 \mathrm{~V} \text { to } 1.8 \mathrm{~V} \text {, } \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~A} \text { to } 1.8 \mathrm{~A} \end{aligned}$ |  | 2.3 |  | MHz |
| 6.6.1b | $\mathrm{f}_{\mathrm{S}}$ w | Switching Frequency, fixed frequency, high or low BW case, no Spread Spectrum | $\begin{aligned} & \text { Fixed - Frequency, } \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V} \text { to } 5 \mathrm{~V} \text {, } \\ & \mathrm{V}_{\text {OUT }}=0.8 \mathrm{~V} \text { to } 1.8 \mathrm{~V}, \\ & \mathrm{l}_{\text {OUT }}=1 \mathrm{~A} \text { to } 1.8 \mathrm{~A} \end{aligned}$ | 2.18 | 2.3 | 2.42 | MHz |
| 6.6.2 | $\mathrm{fsw}_{\text {_ }} \mathrm{Ss}$ _EN | Switching Frequency, fixed frequency, high or low BW case, with Spread Spectrum enabled | ```Fixed - Frequency, V\mathbb{N}=3.3V to 5V, V OUT = 0.8V to 1.8V, lout = 1A to 1.8A Spread spectrum enabled``` | 1.95 |  | 2.65 | MHz |

(1) PVIN_Bx must not exceed VSYS
(2) Refers to DC-regulation only. Transient response may require more headroom. With low headroom, the frequency variation increases for quasi-fixed frequency.

### 6.8 General Purpose LDOs (LDO1, LDO2)

over operating free-air temperature range (unless otherwise noted)

| POS | PARAMETER |  | TEST CONDITIONS | MIN | TYP | MAX |
| :--- | :--- | :--- | :--- | :--- | :--- | :---: | UNIT

TPS65220

### 6.8 General Purpose LDOs (LDO1, LDO2) (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 7.2.2 | V Line_transient | Transient Line Regulation | $\mathrm{V}_{\mathrm{IN}}$ step $=600 \mathrm{mV} \mathrm{PP}_{\mathrm{PP}}, \mathrm{t}_{\mathrm{R}}=\mathrm{t}_{\mathrm{F}}=10$ $\mu \mathrm{s}$, LDO not in dropout condition, LDO-mode | -25 |  | 25 | mV |
| 7.2.3 | NOISE ${ }_{\text {RMs }}$ | RMS Noise | $\begin{aligned} & 100 \mathrm{~Hz}<\mathrm{f} \leq 100 \mathrm{kHz}, \mathrm{~V}_{\text {IN }}=3.3 \mathrm{~V}, \\ & \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=300 \mathrm{~mA} \end{aligned}$ |  | 600 |  | $\mu \mathrm{V}_{\text {RMS }}$ |
| 7.2.4 | $\mathrm{V}_{\text {RIPPLE }}$ | Voltage Ripple |  |  |  | 5 | mV PP |
| 7.3.1 | lout_max | Output Current | $\mathrm{V}_{\text {PVIN_LDOxmin }} \leq \mathrm{V}_{\text {IN }} \leq \mathrm{V}_{\text {PVIN_LDOxmax }}$, Applies to LDO-, bypass- and LSWmode |  |  | 400 | mA |
| 7.3.2 | ICURRENT_LIMIT | Short Circuit Current Limit | $\mathrm{V}_{\text {IN }}=3.6 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}$ | 600 | 980 | 1600 | mA |
| 7.3.3 | IIN_RUSH_LDO | LDO Inrush Current | LDO-mode, with maximum $20-\mu \mathrm{F}$ load connected to VLDOx, , lout $=0$ mA or 400 mA |  |  | 1500 | mA |
| 7.3.4 | IIN_RUSH_LDO_BYP | LDO Inrush Current in bypass-mode | Bypass-mode, with maximum $50-\mu \mathrm{F}$ load connected to VLDOx |  |  | 1500 | mA |
| 7.3.5 | IIN_RUSH_LDO_LSW | LDO Inrush Current in LSW-mode | LSW-mode, with maximum $50-\mu \mathrm{F}$ load connected to VLDOx |  |  | 1500 | mA |
| 7.3.6 | $\mathrm{R}_{\text {discharge }}$ | Pulldown Discharge Resistance at LDO Output | Active only when converter is disabled. Applies to LDO-, bypassand LSW-mode | 100 | 200 | 300 | $\Omega$ |
| 7.3.7a | IQ_ACtive_LDo | Quiescent Current in ACTIVE state at $25^{\circ} \mathrm{C}$, <br> LDO-mode | $\begin{aligned} & \text { LDO-mode, } \begin{array}{l} \text { IOUT }=0 \mathrm{~mA}, \\ \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{array} . \end{aligned}$ |  | 50 | 62 | $\mu \mathrm{A}$ |
| 7.3.7b | IQ_ACtive_LDo | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$, <br> LDO-mode | $\begin{aligned} & \text { LDO-mode, } \mathrm{I}_{\text {OuT }}=0 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \end{aligned}$ |  | 50 | 65 | $\mu \mathrm{A}$ |
| 7.3.7b | IQ_ACtive_LDo | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$, <br> LDO-mode | $\begin{aligned} & \text { LDO-mode, } \mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=-40^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C} \end{aligned}$ |  | 50 | 66 | $\mu \mathrm{A}$ |
| 7.3.8a | IQ_ACTIVE_LDO_BY P | Quiescent Current in ACTIVE state at $25^{\circ} \mathrm{C}$, bypass-mode | bypass-mode, lout $=0 \mathrm{~mA}$, $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 43 | 48 | $\mu \mathrm{A}$ |
| 7.3.8b | IQ_ACTIVE_LDO_BY P | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$, bypass-mode | bypass-mode, $\mathrm{l}_{\text {Out }}=0 \mathrm{~mA}$, $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  | 43 | 50 | $\mu \mathrm{A}$ |
| 7.3.8b | IQ_ACTIVE_LDO_BY P | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$, bypass-mode | bypass-mode, lout $=0 \mathrm{~mA}$, $\mathrm{T}_{\mathrm{J}}=-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |  | 43 | 50 | $\mu \mathrm{A}$ |
| 7.3.9a | lQ_ACTIVE_LDO_LS w | Quiescent Current in ACTIVE state at $25^{\circ} \mathrm{C}$, <br> LSW-mode | $\begin{aligned} & \text { LSW-mode, Iout }=0 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | 46 | 53 | $\mu \mathrm{A}$ |
| 7.3.9b | lQ_ACtive_LDo_Ls w | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$, LSW-mode | $\begin{aligned} & \text { LSW-mode, Iout }=0 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C} \end{aligned}$ |  | 46 | 53 | $\mu \mathrm{A}$ |
| 7.3.9b | $\mathrm{I}_{\mathrm{Q} \text { _ACTIVE_LDO_LS }}$ w | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$, <br> LSW-mode | $\begin{aligned} & \text { LSW-mode, } \mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=-40^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C} \end{aligned}$ |  | 46 | 54 | $\mu \mathrm{A}$ |
| 7.4.1 | $\mathrm{C}_{\text {IN }}$ | Input Filtering Capacitance ${ }^{(2)}$ | Connected from PVIN_LDOx to GND <br> Applies to LDO-, bypass- and LSWmode | 1.6 | 2.2 |  | $\mu \mathrm{F}$ |

### 6.8 General Purpose LDOs (LDO1, LDO2) (continued)

over operating free-air temperature range (unless otherwise noted)

| POS | PARAMETER |  | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 7.4.2 | Cout | Output Filtering Capacitance ${ }^{(3)}$ | Connected from VLDOx to GND, LDO-mode | 1.6 | 2.2 | 4 | $\mu \mathrm{F}$ |
| 7.4.3 | Cout_total | Total Capacitance at Output (Local + POL), LDO-mode ${ }^{(4)}$ | 1 MHz < f $<10 \mathrm{MHz}$ |  |  | 20 | $\mu \mathrm{F}$ |
| 7.4.4 | Cout_total_byp | Total Capacitance at Output (Local + POL), bypass-mode ${ }^{(4)}$ | $1 \mathrm{MHz}<\mathrm{f}<10 \mathrm{MHz}$ |  |  | 50 | $\mu \mathrm{F}$ |
| 7.4.5 | Cout_total_Lsw | Total Capacitance at Output (Local + POL), LSW-mode ${ }^{(4)}$ | 1 MHz < f < 10 MHz |  |  | 50 | $\mu \mathrm{F}$ |
| 7.4.6 | $\mathrm{C}_{\text {ESR }}$ | Filtering capacitor ESR max | $1 \mathrm{MHz}<\mathrm{f}<10 \mathrm{MHz}$ |  | 10 | 20 | $\mathrm{m} \Omega$ |
| Timing Requirements |  |  |  |  |  |  |  |
| 7.5.1 | $t_{\text {RAMP }}$ | Ramp Time LDO in LDO- and bypass-mode | Measured from enable to $98 \%$ of target value, LDO-mode or bypassmode, measured when enabled individually, assuming no residual voltage |  |  | 950 | $\mu \mathrm{s}$ |
| 7.5.2 | tramp_SLEW | Ramp up Slew Rate in LDO- and bypass-mode | $\mathrm{V}_{\text {OUt }}$ from 0.3 V to $90 \%$ of $\mathrm{V}_{\text {OUT }}$ |  |  | 12 | $\mathrm{mV} / \mathrm{\mu s}$ |
| 7.5.3 | tramp_Lsw | Ramp Time LSW-mode | Measured from enable to target value, LSW-mode, assuming no residual voltage |  |  | 1250 | $\mu \mathrm{s}$ |
| 7.5.4 | $t_{\text {RAMP_SLEW }}$ | Ramp up Slew Rate in LSW-mode | $\mathrm{V}_{\text {OUT }}$ from 0.3 V to $90 \%$ of $\mathrm{V}_{\text {OUT }}$ |  |  | 12 | $\mathrm{mV} / \mathrm{\mu s}$ |
| 7.5.5 | t ${ }_{\text {TRANS_1P8_3P3 }}$ | Transition Time 1.8V-3.3V | $\mathrm{V}_{\text {IN }}=4.0 \mathrm{~V}, \mathrm{l}_{\text {OUT }}=300 \mathrm{~mA}$ |  | 2 |  | ms |
| 7.5.6 | t ${ }_{\text {TRANS_3P3_1P8 }}$ | Transition Time 3.3V-1.8V | $\mathrm{V}_{\text {IN }}=4.0 \mathrm{~V}, \mathrm{l}_{\text {OUT }}=300 \mathrm{~mA}$ |  | 2 |  | ms |

(1) PVIN_LDOx must not exceed VSYS
(2) Input capacitors must be placed as close as possible to the device pins.
(3) When DC voltage is applied to a ceramic capacitor, the effective capacitance is reduced due to DC bias effect. The table above therefore lists the minimum value as CAPACITANCE. In order to meet the minimum capacitance requirement, the nominal value of the capacitor may have to be scaled accordingly to take the drop of capacitance into account for a given dc voltage at the outputs of regulators.
(4) Additional capacitance, including local and POL, beyond the specified value can cause the LDO to become unstable
(5) PVIN_LDOx voltage must be within (configured VOUT) and (configured VOUT +200 mV ), maximum 3.6 V .

### 6.9 General Purpose LDOs (LDO3, LDO4)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Electrical Characteristics |  |  |  |  |  |  |  |
| 8.1.1 | $\mathrm{V}_{\text {IN }}$ | Input Voltage (LDO-mode) ${ }^{(1)}$ | LDO-mode, maximum $\mathrm{V}_{\text {VsYs }}$ | 2.2 |  | 5.5 | V |
| 8.1.2 | $\mathrm{V}_{\text {IN }}$ | Input Voltage (LSW-mode) ${ }^{(1)}$ | LSW-mode, maximum $\mathrm{V}_{\mathrm{VSYS}}$ | 2.2 |  | 5.5 | V |
| 8.1.3 | Vout | LDO Output Voltage configurable Range | $\mathrm{V}_{\text {IN }}=2.2 \mathrm{~V}$ to 5.5 V , maximum $\mathrm{V}_{\mathrm{VSYS}}$ | 1.2 |  | 3.3 | V |
| 8.1.4 | Vout_Step | Output voltage Steps | $1.2 \mathrm{~V} \leq \mathrm{V}_{\text {OUT }} \leq 3.3 \mathrm{~V}$ |  | 50 |  | mV |
| 8.1.5 | $V_{\text {DROPOUT }}$ | Dropout Voltage | $\mathrm{V}_{\text {INmin }} \leq \mathrm{V}_{\text {IN }} \leq \mathrm{V}_{\text {IN }}$, $\mathrm{I}_{\text {OUT }}=\mathrm{I}_{\text {OUTmax }}$ |  | 150 | 300 | mV |
| 8.1.6 | Vout_Dc_ACCURA CY | Total DC accuracy including DC load and line regulation for all valid output voltages | LDO-mode, $\mathrm{V}_{\text {IN }}-\mathrm{V}_{\text {OUT }}>300 \mathrm{mV}$ | -1\% |  | 1\% |  |
| 8.1.6a | Vload_regulatio <br> N | DC load regulation, $\Delta \mathrm{V}_{\text {OUT }}$ | $1 \mathrm{~mA} \leq \mathrm{l}_{\text {OUT }} \leq \mathrm{I}_{\text {OUTmax }}$ | -1\% |  | 1\% |  |
| 8.1.7 | $\mathrm{R}_{\text {BYPASS }}$ | Bypass resistance in LSW-mode | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=100 \mathrm{~mA},$ Loadswitch-mode enabled |  |  | 1 | $\Omega$ |
| 8.2.1 | VLoad_transient | Transient load regulation, $\Delta \mathrm{V}_{\text {OUT }}$ | $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.80 \mathrm{~V}$, $\mathrm{I}_{\text {OUT }}=$ $20 \%$ of IOUt_MAX to $80 \%$ of IOUt_MAX in $1 \mu \mathrm{~s}, \mathrm{C}_{\text {OUT }}=2.2 \mu \mathrm{~F}$ | -25 |  | 25 | mV |

TPS65220

### 6.9 General Purpose LDOs (LDO3, LDO4) (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 8.2.2 | VIINE_TRANSIENT | Transient line regulation, $\triangle$ VOUT / VOUT | On mode, not under dropout condition, $\mathrm{V}_{\mathrm{IN}}$ step $=600 \mathrm{mV} \mathrm{VP}_{\mathrm{PP}}, \mathrm{t}_{\mathrm{r}}$ $=t_{f}=10 \mu \mathrm{~s}$ | -25 |  | 25 | mV |
| 8.2.2a | Vline_regulation | DC line regulation, $\Delta \mathrm{V}_{\text {OUT }} / \mathrm{V}_{\text {OUT }}$ | $\mathrm{V}_{\text {INmin }} \leq \mathrm{V}_{\text {IN }} \leq \mathrm{V}_{\text {INmax }}, \mathrm{I}_{\text {OUT }}=\mathrm{I}_{\text {OUTmax }}$ | -1\% |  | 1\% |  |
| 8.2.3 | NOISE ${ }_{\text {RMS }}$ | RMS Noise | LDO-mode, $\mathrm{f}=100 \mathrm{~Hz}$ to 100 KHz , $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V}$, IOUT $=$ 300 mA |  | 15 |  | $\mu \mathrm{V}_{\text {RMS }}$ |
| 8.2.4 | $\mathrm{PSRR}_{1 \mathrm{KHZ}}$ | Power Supply Ripple Rejection | $\begin{aligned} & \text { LDO-mode, } \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}= \\ & 1.8 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=300 \mathrm{~mA} \end{aligned}$ |  | 71 |  | db |
| 8.2.5 | $\mathrm{PSRR}_{10 \mathrm{KHz}}$ | Power Supply Ripple Rejection | $\begin{aligned} & \text { LDO-mode, } \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}= \\ & 1.8 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=300 \mathrm{~mA} \end{aligned}$ |  | 64 |  | db |
| 8.2.6 | PSRR ${ }_{100 \mathrm{KHZ}}$ | Power Supply Ripple Rejection | $\begin{aligned} & \text { LDO-mode, } \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}= \\ & 1.8 \mathrm{~V}, \text { I OUT }=300 \mathrm{~mA} \end{aligned}$ |  | 61 |  | db |
| 8.2.7 | $\mathrm{PSRR}_{1 \mathrm{MHz}}$ | Power Supply Ripple Rejection | $\begin{aligned} & \text { LDO-mode, } \mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}= \\ & 1.8 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=300 \mathrm{~mA} \end{aligned}$ |  | 26 |  | db |
| 8.3.1 | lout | Output Current |  |  |  | 300 | mA |
| 8.3.2 | ICURRENT_LIMIT | Short Circuit Current Limit | $\mathrm{V}_{\text {IN }}=3.6 \mathrm{~V}, \mathrm{~V}_{\text {OUT }}=0 \mathrm{~V}$, Tested under a pulsed load condition | 400 |  | 900 | mA |
| 8.3.3 | IIN_RUSH | LDO inrush current | LDO- or LSW-mode, $\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$ and then LDO is enabled, $\mathrm{C}_{\text {OUT }}=$ $4 \mu \mathrm{~F}$, $\mathrm{I}_{\text {OUt }}=0 \mathrm{~mA}$ or 300 mA |  |  | 650 | mA |
| 8.3.4 | $\mathrm{R}_{\text {discharge }}$ |  | Active only when converter is disabled | 120 | 250 | 400 | $\Omega$ |
| 8.3.5a | $\mathrm{I}_{\mathrm{Q}}$ ACTIVE | Quiescent Current in ACTIVE state at $25^{\circ} \mathrm{C}$ | $\mathrm{V}_{\text {VSYS }}=\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, $\mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}$ Applies to LDO-mode, $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | 25 | 30 | $\mu \mathrm{A}$ |
| 8.3.5b | $\mathrm{I}_{\mathrm{Q}}$ ACTIVE | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ | $\mathrm{V}_{\text {VSYS }}=\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, IOUT $=0 \mathrm{~mA}$ Applies to LDO-mode, $T_{J}=-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  | 25 | 40 | $\mu \mathrm{A}$ |
| 8.3.5b | $\mathrm{I}_{\text {Q_ACTIVE }}$ | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | $\mathrm{V}_{\text {VSYS }}=\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, $\mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}$, Applies to LDO-mode, $T_{J}=-40^{\circ} \mathrm{C} \text { to } 150^{\circ} \mathrm{C}$ |  | 25 | 40 | $\mu \mathrm{A}$ |
| 8.3.5c | $\mathrm{I}_{\text {Q_ACTIVE }}$ | Quiescent Current in ACTIVE state at $25^{\circ} \mathrm{C}$ | $\mathrm{V}_{\mathrm{VSYS}}=\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}, \mathrm{I}_{\mathrm{OUT}}=0 \mathrm{~mA}$ <br> Applies to LSW-mode, $\mathrm{T}_{J}=25^{\circ} \mathrm{C}$ |  | 60 | 112 | $\mu \mathrm{A}$ |
| 8.3.5d | $\mathrm{I}_{\text {Q_ACtive }}$ | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ | $\mathrm{V}_{\text {VSYS }}=\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}$ <br> Applies to LSW-mode, $\mathrm{T}_{J}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C}$ |  | 70 | 145 | $\mu \mathrm{A}$ |
| 8.3.5d | $\mathrm{I}_{\text {Q_ACTIVE }}$ | Quiescent Current in ACTIVE state $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | $\mathrm{V}_{\mathrm{VSYS}}=\mathrm{V}_{\text {IN }}=3.3 \mathrm{~V}$, $\mathrm{I}_{\text {OUT }}=0 \mathrm{~mA}$, Applies to LSW-mode, $\mathrm{T}_{J}=-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |  | 70 | 145 | $\mu \mathrm{A}$ |
| 8.4.1 | $\mathrm{C}_{\text {IN }}$ | Input Filtering Capacitance (2) |  | 2.2 | 4.7 |  | $\mu \mathrm{F}$ |
| 8.4.2 | Cout | Output Filtering Capacitance ${ }^{(2)}$ | Connected from VLDOx to GND, LDO-mode | 1.6 | 2.2 | 4 | $\mu \mathrm{F}$ |
| 8.4.3a | Cout_total_fast | Total Capacitance at Output (Local + POL), fast ramp-time ${ }^{(3)}$ | 1 MHz < $\mathrm{f}<10 \mathrm{MHz}$, impedance between output and point-of-load maximum 6nH |  |  | 15 | $\mu \mathrm{F}$ |
| 8.4.3b | Cout_total_slow | Total Capacitance at Output (Local + POL), slow ramp-time ${ }^{(3)}$ | 1 MHz < f < 10 MHz , impedance between output and point-of-load maximum 6nH |  |  | 30 | $\mu \mathrm{F}$ |
| 8.4.4 | $\mathrm{C}_{\text {ESR }}$ | Filtering capacitor ESR max | 1 MHz to 10 MHz |  | 10 | 20 | $\mathrm{m} \Omega$ |
| Timing Requirements |  |  |  |  |  |  |  |

### 6.9 General Purpose LDOs (LDO3, LDO4) (continued)

over operating free-air temperature range (unless otherwise noted)

| POS | PARAMETER |  | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 8.5.1a | $\mathrm{t}_{\text {RAMP_FAST }}$ | Ramp Time fast | Measured from enable to $98 \%$ of target value, LDOmode, measured when enabled individually, assuming no residual voltage |  |  | 660 | $\mu \mathrm{s}$ |
| 8.5.1b | $t_{\text {RAMP_SLOW }}$ | Ramp Time slow | Measured from enable to 98\% of target value, LDOmode, measured when enabled individually, assuming no residual voltage |  |  | 2.3 | ms |
| 8.5.2a | $\mathrm{t}_{\text {RAMP_SLEW_FAST }}$ | Ramp Up Slew Rate fast | LDO- or LSW-mode, measured from 0.5 V to target value |  |  | 25 | $\mathrm{mV} / \mu \mathrm{s}$ |
| 8.5.2b | $\mathrm{t}_{\text {RAMP_SLEW_SLOW }}$ | Ramp Up Slew Rate slow | LDO- or LSW-mode, measured from 0.5 V to target value |  |  | 9 | $\mathrm{mV} / \mu \mathrm{s}$ |

(1) PVIN_LDOx must not exceed VSYS
(2) When DC voltage is applied to a ceramic capacitor, the effective capacitance is reduced due to DC bias effect. The table above therefore lists the minimum value as CAPACITANCE. In order to meet the minimum capacitance requirement, the nominal value of the capacitor may have to be scaled accordingly to take the drop of capacitance into account for a given dc voltage at the outputs of regulators.
(3) Additional capacitance, including local and POL, beyond the specified value can cause the LDO to become unstable

### 6.10 GPIOs and multi-function pins (EN/PB/VSENSE, nRSTOUT, nINT, GPO1, GPO2, GPIO, MODE/RESET, MODE/STBY, VSEL_SD/VSEL_DDR)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Electrical Characteristics |  |  |  |  |  |  |  |
| 9.1.1 | $\mathrm{V}_{\mathrm{OL}}$ | Low-level Output Voltage (opendrain) | $\mathrm{VIO}=3.6 \mathrm{~V}, \mathrm{I}_{\mathrm{OL}}=2 \mathrm{~mA}, \mathrm{GPO} 1$, GPO2, GPIO, nRSTOUT, nINT |  |  | 0.40 | V |
| 9.1.2 | VIL | Low-level Input Voltage | EN/PB, MODE/STBY, MODE/ RESET and VSEL_SD/VSEL_DDR, GPIO |  |  | 0.4 | V |
| 9.1.3 | $\mathrm{V}_{\mathrm{IH}}$ | High-level Input Voltage | EN/PB, MODE/STBY, MODE/ RESET and VSEL_SD/VSEL_DDR, GPIO | 1.26 |  |  | V |
| 9.1 .4 | V VSENSE | VSENSE Comparator Threshold (EN/PB/VSENSE) |  | 1.08 | 1.20 | 1.32 | V |
| 9.1 .5 | VVSENSE_HYS | VSENSE Comparator Hysteresis (EN/PB/VSENSE) |  | 8 | 30 | 55 | mV |
| 9.1 .6 | lıkg | Input leakage current (GPIO, EN/PB/VSENSE, MODE/STBY, MODE/RESET, VSEL_SD/VSEL/ DDR) | $\mathrm{V}_{\mathrm{IN}}=3.3 \mathrm{~V}$ |  |  | 1.0 | $\mu \mathrm{A}$ |
| 9.1.7 | $\mathrm{C}_{\text {IN }}$ | Internal input pin capacitance (GPIO, EN/PB/ VSENSE, MODE/STBY, MODE/ RESET, VSEL_SD/VSEL/DDR) |  |  |  | 10 | pF |
| 9.1 .8 | IPD | pull-down current, available 100us after VSYS is applied | on pins GPO1, GPO2, GPIO, MODE/STBY, MODE/RESET, VSEL_SD/VSEL_DDR, nINT, nRSTOUT | 18 | 25 | 35 | $n A$ |
| 9.1 .9 | ILKG_VSYS_ONLY | Pin leakage when VSYS is present, but digital supply VDD1P8 is not | SDA only |  |  | 1 | $\mu \mathrm{A}$ |
| 9.1.10 | VPIN_VSYS_ONLY | Pin voltage when VSYS is present, but digital supply VDD1P8 is not | GPO1, GPO2, GPIO, nRSTOUT, $\mathrm{nINT}, \mathrm{I}_{\mathrm{OL}}=2 \mathrm{~mA}$ |  |  | 0.4 | V |

### 6.10 GPIOs and multi-function pins (EN/PB/VSENSE, nRSTOUT, nINT, GPO1, GPO2, GPIO, MODE/RESET, MODE/STBY, VSEL_SD/VSEL_DDR) (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Timing Requirements |  |  |  |  |  |  |  |
| 9.2.1a | $\mathrm{t}_{\text {FALL }}$ | Output buffer fall time (90\% to 10\%) | GPO1, GPO2, GPIO, nRSTOUT, nINT, Cout $=10 \mathrm{pF}$ |  |  | 50 | ns |
| 9.2.1b | $t_{\text {RISE }}$ | GPIO Output buffer rise time (10\% to $90 \%$ ) | GPIO, applicable in Multi-PMICconfiguration |  |  | 5 | $\mu \mathrm{s}$ |
| 9.2.1.1 | ${ }_{\text {toly_FALL }}$ | Output buffer falling time delay (input crossing $50 \%$ to output crossing 50\%) | $\mathrm{C}_{\text {OUT }}=10 \mathrm{pF}$ |  |  | 50 | ns |
| 9.2.1.2 | $\mathrm{t}_{\text {FALL_PP }}$ | Push Pull Output buffer fall time (90\% to 10\%) | Only for nINT and GPO1, SCAN VSYS voltage $=3.3 \mathrm{~V}$ for SCAN, COUT $=50 \mathrm{pF}$ |  |  | 35 | ns |
| 9.2.2.1 | ${ }_{\text {tLIY_RISE }}$ | Open Drain Output buffer rising time delay <br> (digital input to output crossing 50\%) | $C_{\text {OUT }}=10 \mathrm{pF}, R_{\text {PU }}=1 \mathrm{k}$ (external pull up), $\mathrm{VIO}=1.8 \mathrm{~V}$ |  |  | 300 | ns |
| 9.2.2.2 | $\mathrm{t}_{\text {RISE_PP }}$ | Push Pull Output buffer rise time (10\% to 90\%) | Only for nINT and GPO1, SCAN VSYS voltage $=3.3 \mathrm{~V}$ for SCAN, COUT=50pF |  |  | 35 | ns |
| 9.2.2.3 | FLT_HIGH ${ }_{\text {Duration }}$ | Time the digital has allotted for the test to see if the pin can be pulled high internally | $C_{\text {Out }}=10 \mathrm{pF}$ | 15 |  |  | $\mu \mathrm{s}$ |
| 9.2.2.4 | FLT_LOW ${ }_{\text {Duration }}$ | Time the digital has allotted for the test to see if the pin can be pulled low internally | $C_{\text {OUT }}=10 \mathrm{pF}$ | 15 |  |  | $\mu \mathrm{s}$ |
| 9.2.2a | tpb_ON_SLOW | EN/PB/VSENSE, Wait Time PB, ON request, slow | PB, falling Edge | 540 | 600 | 660 | ms |
| 9.2.2b | tpb_On_FAST $^{\text {l }}$ | EN/PB/VSENSE, Wait Time PB, ON request, fast | PB, falling Edge | 180 | 200 | 220 | ms |
| 9.2.3 | ${ }_{\text {tpB_OFF }}$ | EN/PB/VSENSE, Wait Time PB, OFF request | PB, falling Edge | 7.2 | 8.0 | 8.8 | s |
| 9.2.4 | tpb_RISE_DEGL | EN/PB/VSENSE, Deglitch time PB, rising edge | PB , rising Edge, applicable after the successful long-press-OFF-request | 115 | 200 | 275 | ms |
| 9.2.5 | tpb_INT_DEGL $^{\text {d }}$ | EN/PB/VSENSE, Deglitch time PB, rising or falling edge | PB, rising or falling Edge | 59 | 100 | 137 | ms |
| 9.2.6 | ${ }_{\text {LEGL_EN_Rise_SIow }}$ | EN/PB/VSENSE, DeglitchTime EN slow, rising | EN, rising Edge | 45 | 50 | 55 | ms |
| 9.2.7 | tDEGL_EN_Rise_Fast | EN/PB/VSENSE, DeglitchTime EN fast, rising | EN, rising Edge | 60 | 120 | 150 | $\mu \mathrm{s}$ |
| 9.2.8 | $t_{\text {DEGL_EN_Fall }}$ | EN/PB/VSENSE, DeglitchTime EN, falling | EN, falling Edge | 50 | 70 | 93 | $\mu \mathrm{s}$ |
| 9.2.9 | tmegl_vsense_Rise | VSENSE rising: only gated by VSYS ${ }_{\text {POR_Rising }}$ and VSENSEvoltage | VSENSE, rising Edge |  | N/A |  |  |
| 9.2.10 | tmegl_vsense_Fall | EN/PB/VSENSE, DeglitchTime VSENSE, falling, regardless of fast/ slow setting | VSENSE, falling Edge | 50 | 70 | 93 | $\mu \mathrm{s}$ |
| 9.2.11 | tDEGL_EN/ vSENSE_I2C | EN/VSENSE falling edge deglitch time after I2C-triggered shutdown | EN/VSENSE falling edge after previous shutdown request by I2C (shorter than 9.2.8) | 12.5 | 25 | 37.5 | $\mu \mathrm{s}$ |
| 9.2.12 | tmegl_Reset | MODE/RESET, Deglitch Time RESET | RESET, rising and falling Edge | 90 | 120 | 150 | $\mu \mathrm{s}$ |

### 6.10 GPIOs and multi-function pins (EN/PB/VSENSE, nRSTOUT, nINT, GPO1, GPO2, GPIO, MODE/RESET, MODE/STBY, VSEL_SD/VSEL_DDR) (continued)

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 9.2.13 | $\mathrm{t}_{\text {DEGL_MFP }}$ | Deglitch Time MODE/STBY, MODE(not/RESET), VSEL_SD/ VSEL DDR | Rising and falling Edge | 90 | 120 | 150 | $\mu \mathrm{s}$ |
| 9.2.14 | teEGL_GPIO | Deglitch Time GPIO | Rising and falling Edge | 6.6 | 15.6 | 18 | $\mu \mathrm{s}$ |
| 9.2.15 | treaction_on | ON-request propagation delay (after deglitch) | Includes oscillator startup, sampling delay and reaction delay (excluding deglitch) |  | 75 | 103 | $\mu \mathrm{s}$ |
| 9.2.16 | $\mathrm{t}_{\text {REACTION_OFF }}$ | OFF-request propagation delay (after deglitch) | Includes sampling delay and reaction delay (excluding deglitch) | 39 | 56 | 73.5 | $\mu \mathrm{s}$ |

### 6.11 Voltage and Temperature Monitors

over operating free-air temperature range (unless otherwise noted)

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Electrical Characteristics |  |  |  |  |  |  |  |
| 10.1.1 | V ${ }^{\text {BUCKx_UV_TH_5, }}$ VLDOx_UV_TH_5 | Undervoltage monitoring for buck output, programable low-going threshold accuracy | UV_THR = 0x0 |  | -5\% |  |  |
| 10.1.2 | V ${ }_{\text {BUCKx_UV_TH_10, }}$ <br> VLDOx_UV_TH_10 | Undervoltage monitoring for buck output and LDO output, programable low-going threshold accuracy | UV_THR = 0x1 |  | -10\% |  |  |
| 10.1.3 |  | Undervoltage Threshold Accuracy, $\mathrm{V}_{\text {OUT }} \geq 1 \mathrm{~V}$ | $\mathrm{V}_{\text {OUT }} \geq 1 \mathrm{~V}$ | -1.5\% |  | +1.5\% |  |
| 10.1.4 | $\begin{aligned} & \text { V BUCKx_UV_L_ACC, } \\ & \text { V }_{\text {LDOx_UV_L_ACC }} \end{aligned}$ | Undervoltage Threshold Accuracy, $\mathrm{V}_{\text {OUT }}<1 \mathrm{~V}$ | $\mathrm{V}_{\text {OUT }}<1 \mathrm{~V}$ | -10 |  | +10 | mV |
| 10.1.5 | $V_{\text {BUCKx_UV_HYS }}$, <br> VLDOx_UV_HYS | Undervoltage Hysteresis |  | 0.25\% | 1\% | 1.75\% |  |
| 10.1.6 | V ${ }_{\text {BUCKx_SCG_TH }}$, <br> VLDOx_SCG_TH | Short-circuit (SCG) and residual voltage (RV) detection low-going threshold |  | 220 | 260 | 300 | mV |
| 10.1.7 | VBUCKx_SCG_HYS, <br> VLDOx_SCG_HYS | Short-circuit (SCG) and residual voltage (RV) detection threshold hysteresis |  |  | 75 |  | mV |
| 10.2.1a | TWARM_Rising | Temperature rising Warning Threshold (WARM) | for each of the four sensors | 130 | 140 | 150 | ${ }^{\circ} \mathrm{C}$ |
| 10.2.1b | TWARM_Falling | Temperature falling Warning Threshold (WARM) | for each of the four sensors | 125 | 135 | 145 | ${ }^{\circ} \mathrm{C}$ |
| 10.2.2a | THOT_Rising | Temperature rising Shutdown Threshold (TSD, HOT) | for each of the four sensors | 140 | 150 | 160 | ${ }^{\circ} \mathrm{C}$ |
| 10.2.2b | THOT_Falling | Temperature falling Shutdown Threshold (TSD, HOT) | for each of the four sensors | 130 | 140 | 150 | ${ }^{\circ} \mathrm{C}$ |
| 10.2.3 | $\mathrm{T}_{\mathrm{HYS}}$ | Temperature Hysteresis for WARM | for each of the four sensors |  | -5 |  | ${ }^{\circ} \mathrm{C}$ |
| Timing Requirements |  |  |  |  |  |  |  |
| 10.3.1a | $t_{\text {DEGLItch }}$ | Fault Detection Deglitch Time for Under Voltage (UV) and Short to GND (SCG) | Measured from UV/SCG event | 13 | 20 | 27 | $\mu \mathrm{s}$ |
| 10.3.1b | $t_{\text {DEGLITCH_OC_short }}$ | Fault Detection Deglitch Time for Over Current (OC), rising edge, short | Measured from OC event, rising edge | 26 | 35 | 45 | $\mu \mathrm{s}$ |

TPS65220

### 6.11 Voltage and Temperature Monitors (continued)

over operating free-air temperature range (unless otherwise noted)

| POS | PARAMETER |  | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 10.3.1c | $\mathrm{t}_{\text {DEGLITCH_OC_long }}$ | Fault Detection Deglitch Time for Over Current (OC), rising edge, long | Measured from OC event, rising edge | 1.6 | 2 | 2.2 | ms |
| 10.3.2a | $t_{\text {REACTION }}$ | Fault Reaction Time for Under Voltage (UV) and Short to GND (SCG) (including deglitch time) | Measured from UV/SCG event to nINT pulled low | 26 | 40 | 54 | $\mu \mathrm{s}$ |
| 10.3.2b | $\mathrm{t}_{\text {REACTION_OC_shor }}$ t | Fault Reaction Time for Over Current (OC) (including deglitch time) | Measured from UV/OC/SCG event to nINT pulled low | 45 | 65 | 81 | $\mu \mathrm{s}$ |
| 10.3.2c | $\mathrm{t}_{\text {REACTION_OC_long }}$ | Fault Detection Deglitch Time for Over Current (OC), rising edge, long | Measured from OC event, rising edge | 1.6 | 2 | 2.2 | ms |
| 10.3.2d | $t_{\text {REACTION_WARM }}$ | Fault Reaction Time for Temperature Warning (WARM), Thermal Shutdown (TSD / HOT) | Measured from WARM/HOT event to nINT pulled low |  |  | 525 | $\mu \mathrm{s}$ |

### 6.12 $\mathrm{I}^{2} \mathrm{C}$ Interface

Over operating free-air temperature range (unless otherwise noted). Device supports standard mode ( 100 kHz ), fast mode $(400 \mathrm{kHz})$, and fast mode+ ( 1 MHz ) when VIO is 3.3 V or 1.8 V .

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Electrical Characteristics |  |  |  |  |  |  |  |
| 11.1.1 | $\mathrm{V}_{\mathrm{OL}}$ | Low-level Output Voltage | $\mathrm{VIO}=3.6 \mathrm{~V}, \mathrm{I}_{\mathrm{OL}}=3 \mathrm{~mA}$ for Standard mode and Fast mode, $\mathrm{I}_{\mathrm{OL}}=20 \mathrm{~mA}$ for Fast mode+, SDA |  |  | 0.40 | V |
| 11.1.2 | $\mathrm{V}_{\text {IL }}$ | Low-level Input Voltage | SDA, SCL |  |  | 0.40 | V |
| 11.1 .3 | $\mathrm{V}_{\mathrm{IH}}$ | High-level Input Voltage | SDA, SCL | 1.26 |  |  | V |
| 11.1 .4 | $\mathrm{V}_{\text {HYST }}$ | Input buffer Hysteresis | EN_BP/VSENSE, MODE_RESET, MODE_STBY, SDA, SCL, GPIO | 100 |  | 500 | mV |
| 11.1 .5 | $\mathrm{C}_{\mathrm{B}}$ | Capacitive Load for SDA and SCL |  |  |  | 400 | pF |
| Timing Requirements |  |  |  |  |  |  |  |
| 11.2.1 | $f_{\text {SCL }}$ | Serial Clock Frequency | Standard mode |  |  | 100 | kHz |
| 11.2 .2 |  |  | Fast mode |  |  | 400 |  |
| 11.2 .3 |  |  | Fast mode+ |  |  | 1 | MHz |
| 11.3 .1 | tow | SCL low Time | Standard mode | 4.7 |  |  | $\mu \mathrm{s}$ |
| 11.3 .2 |  |  | Fast mode | 1.3 |  |  |  |
| 11.3 .3 |  |  | Fast mode+ | 0.50 |  |  |  |
| 11.4 .1 | $\mathrm{t}_{\text {HIGH }}$ | SCL high Time | Standard mode | 4.0 |  |  | $\mu s$ |
| 11.4 .2 |  |  | Fast mode | 0.60 |  |  |  |
| 11.4 .3 |  |  | Fast mode+ | 0.26 |  |  |  |
| 11.5.1 | $t_{\text {SU; DAT }}$ | Data setup Time | Standard mode | 250 |  |  | ns |
| 11.5.2 |  |  | Fast mode | 100 |  |  |  |
| 11.5 .3 |  |  | Fast mode+ | 50 |  |  |  |
| 11.6.1 | $t_{\text {HD ; DAT }}$ | Data hold Time | Standard mode | 10 |  | 3450 | ns |
| 11.6 .2 |  |  | Fast mode | 10 |  | 900 |  |
| 11.6 .6 |  |  | Fast mode+ | 10 |  |  |  |
| 11.7.1 | $\mathrm{t}_{\text {SU;STA }}$ | Setup Time for a Start or a REPEATED Start Condition | Standard mode | 4.7 |  |  | $\mu \mathrm{s}$ |
| 11.7 .2 |  |  | Fast mode | 0.60 |  |  |  |
| 11.7 .3 |  |  | Fast mode+ | 0.26 |  |  |  |

## $6.12 I^{2} \mathrm{C}$ Interface (continued)

Over operating free-air temperature range (unless otherwise noted). Device supports standard mode ( 100 kHz ), fast mode $(400 \mathrm{kHz})$, and fast mode+ ( 1 MHz ) when VIO is 3.3 V or 1.8 V .

| POS |  | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 11.8.1 | $\mathrm{thD}_{\text {; STA }}$ | Hold Time for a Start or a REPEATED Start Condition | Standard mode | 4.7 |  |  | $\mu \mathrm{s}$ |
| 11.8.2 |  |  | Fast mode | 0.60 |  |  |  |
| 11.8.3 |  |  | Fast mode+ | 0.26 |  |  |  |
| 11.9.1 | $\mathrm{t}_{\text {BuF }}$ | Bus free Time between a STOP and Start Condition | Standard mode | 4.7 |  |  | $\mu \mathrm{s}$ |
| 11.9.2 |  |  | Fast mode | 1.3 |  |  |  |
| 11.9.3 |  |  | Fast mode+ | 0.50 |  |  |  |
| 11.10 .1 | tsu;sto | Setup Time for a STOP Condition | Standard mode | 0.60 |  |  | $\mu \mathrm{s}$ |
| 11.10.2 |  |  | Fast mode | 0.60 |  |  |  |
| 11.10.3 |  |  | Fast mode+ | 0.26 |  |  |  |
| 11.10.1 | $\mathrm{tr}_{\text {DA }}$ | Rise Time of SDA Signal | Standard mode, $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=$ $10 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ |  |  | 1000 | ns |
| 11.10.2 |  |  | Fast mode, $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=1 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ | 20 |  | 300 |  |
| 11.10.3 |  |  | Fast mode + , $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=330$ $\Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ |  |  | 120 |  |
| 11.12.1 | $\mathrm{t}_{\mathrm{fDA}}$ | Fall Time of SDA Signal | Standard mode, $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=$ $10 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ |  |  | 300 | ns |
| 11.12.2 |  |  | Fast mode, $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=1 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ | 6.5 |  | 300 |  |
| 11.12.3 |  |  | Fast mode + , $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=330$ $\Omega$ and $C_{B}=400 \mathrm{pF}$ | 6.5 |  | 120 |  |
| 11.13.1 | trcL | Rise Time of SCL Signal | Standard mode, $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=$ $10 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ |  |  | 1000 | ns |
| 11.13 .2 |  |  | Fast mode, $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=1 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ | 20 |  | 300 |  |
| 11.13 .3 |  |  | $\begin{aligned} & \text { Fast mode }+, \mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=330 \\ & \Omega \text { and } \mathrm{C}_{\mathrm{B}}=400 \mathrm{pF} \end{aligned}$ |  |  | 120 |  |
| 11.14 .1 | $\mathrm{t}_{\mathrm{fCL}}$ | Fall Time of SCL Signal | $\begin{aligned} & \text { Standard mode, } \mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}= \\ & 10 \mathrm{k} \Omega \text { and } \mathrm{C}_{\mathrm{B}}=400 \mathrm{pF} \end{aligned}$ |  |  | 300 | ns |
| 11.14 .2 |  |  | Fast mode, $\mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=1 \mathrm{k} \Omega$ and $\mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ | 6.5 |  | 300 |  |
| 11.14 .3 |  |  | $\text { Fast mode }+ \text {, } \mathrm{VIO}=1.8 \mathrm{~V}, \mathrm{R}_{\mathrm{PU}}=330$ $\Omega \text { and } \mathrm{C}_{\mathrm{B}}=400 \mathrm{pF}$ | 6.5 |  | 120 |  |
| 11.15 .1 | ${ }_{\text {tsp }}$ | Pulse Width of Spike suppressed (SCL and SDA Spikes that are less than the indicated Width are suppressed) | Fast mode, and fast mode+ |  |  | 50 | ns |

### 6.13 Typical Characteristics



Figure 6-1. Efficiency BUCK1


Figure 6-3. BUCK1 Load-step response - High Bandwidth, forced PWM

$\mathrm{V}_{\text {IN }}=5.0 \mathrm{~V} \quad \mathrm{~V}_{\text {OUT }}=1.2 \mathrm{~V} \quad \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
$\mathrm{l}_{\text {OUT }}=1 \mathrm{~mA}$ to 1 A to $1 \mathrm{~mA}, \mathrm{t}_{\text {rise }}=\mathrm{t}_{\text {fall }}=1 \mu \mathrm{~s} \quad C_{\text {OUT_total }}=57 \mu \mathrm{~F}$
Figure 6-5. BUCK3 Load-step response - Low Bandwidth, forced PWM

$\mathrm{V}_{\text {IN }}=5 \mathrm{~V} \quad \mathrm{~V}_{\text {OUT }}=1.8 \mathrm{~V} \quad \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
Figure 6-2. Efficiency BUCK23


Figure 6-4. BUCK2 Load-step response - Low Bandwidth, forced PWM


Figure 6-6. LDO1 Load-step response


Figure 6-7. LDO2 Load-step response


Figure 6-8. LDO3 Load-step response


Figure 6-9. LDO4 Load-step response

SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

## 7 Detailed Description

### 7.1 Overview

The TPS65220 provides three step-down converters, four LDOs, three general-purpose I/Os and three multiFunction pins. The system can be supplied by a single cell Li-lon battery, two primary cells or a regulated supply. The device is characterized across a $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ temperature range, which makes the PMIC an excellent choice for various industrial automotive applications.
The I2C interface provides comprehensive features for using TPS65220. All rails, both GPOs and the GPIO can be enabled or disabled. Voltage thresholds for the undervoltage monitoring can be customized.
The integrated voltage supervisor monitors Buck 1-3 and LDO1-4 for undervoltage. The monitor has two sensitivity settings. A power good signal is provided to report the successful ramp of the seven rails and GPOs. The nRSTOUT pin is pulled low until the device enters ACTIVE state. When powering down from ACTIVEor STBY-state, nRSTOUT is pulled low again. The nRSTOUT pin has an open-drain output. A fault-pin, nINT, notifies the SoC about faults.

Buck1 step-down converter can supply up to 3.5 A of current, Buck2 and Buck3 can supply up to 2 A each. The default output voltages for each converter can be adjusted through the I2C interface. All three buck-converters feature dynamic voltage scaling. The step-down converters operate in a low power mode at light load or can be forced into PWM operation for noise sensitive applications.

LDO1 and LDO2 support output currents of 400 mA at an output voltage range of 0.6 V to 3.4 V . These LDOs support bypass mode, acting as a load-switch, and allow voltage-changes during operation for applications like SD-card-supply, adjusting the IO-supply of the SD-card from 3.3 V to 1.8 V after initialization.
LDO3 and LDO4 support output currents of 300 mA at an output voltage range of 1.2 V to 3.3 V . These LDOs support load-switch-mode, but not bypass mode.

The I2C-interface, IOs, GPIOs, and multi-function-pins (MFP) allow a seamless interface to a wide range of SoCs.

All configurations of the rails, for example output-voltages, sequencing, are backed up by EEPROM. Please refer to the Technical Reference Manual (TRM) of the chosen configuration.

### 7.2 Functional Block Diagram



Figure 7-1. Functional Block Diagram

### 7.3 Feature Description

### 7.3.1 Power-Up Sequencing

The TPS65220 allows flexible sequencing of the rails. The order of the rails, including GPO1, GPO2, GPIO for the external rails, and the nRSTOUT pin is defined by the NVM. Prior to starting the power-up sequence, the device checks if the voltage on all rails fell below the SCG-threshold to avoid starting into a pre-biased rail. The sequence is timing based. In addition, the previous rail must have passed the UV-threshold, else the subsequent rail is not enabled. If UV is masked, the sequence proceeds even if the UV-threshold is not reached. GPO1, GPO2, GPIO, and LDOs configured in bypass- or LSW-mode are not monitored for under-voltage, thus their outputs do not gate subsequent rails.

In case the sequence is interrupted due to an unmasked fault on a rail, the device powers down. The TPS65220 attempts to power up two more times. If both of those re-tries fail to enter ACTIVE state, the device remains in INITIALIZE state until VSYS is power-cycled. While it is encouraged to keep this retry-counter active, one can disable it by setting bit MASK_RETRY_COUNT in INT_MASK_UV register.

To disable the retry-counter, set bit MASK_RETRY_COUNT in INT_MASK_UV register. When set, the device attempts to retry infinitely.

The TPS65220 allows to configure the power-down sequence independent from the power-up sequence. The sequences are configured in the non-volatile memory.
At initial power-up, the device monitors the VSYS supply voltage and allows power-up and transition to INITIALZE state only if VSYS passed the VSYSPOR_Rising threshold.
The power-up sequence is configured as follows:

- The slot (respectively the position in the sequence) for each rail and GPO1, GPO2, GPIO, and nRSTOUT is defined using the corresponding *_SEQUENCE_SLOT registers, the four MSB for the power-up sequence, the four LSB for the power-down sequence.
- The duration of each slot is defined in the POWER_UP_SLOT_DURATION_x registers and can be configured as $0 \mathrm{~ms}, 1.5 \mathrm{~ms}, 3 \mathrm{~ms}$ or 10 ms . In total, 16 slots can be configured, allowing the sequence to span over multiple TPS65220-devices if more rails need to be supported.
- In addition to the timing as defined above, the power-up-sequence is also gated by the UV-monitor: a subsequent rail only gets enabled after the previous one passed the under-voltage threshold (unless UV is masked). If a rail has not reached the $U V$-threshold by the end of $t_{\text {RAMP }}$ (respectively $t_{\text {RAMP_Lsw, }} t_{\text {RAMP_sLow, }}$, $t_{\text {RAMP_FAST }}$ ), the sequence is aborted and the device sequences down at the end of the slot-duration. For the respective rail, the device sets INT_BUCK_x_y_IS_SET respectively INT_LDO_x_y_IS_SET bit in INT_SOURCE register and BUCKx_UV respectively LDOx_UV bit in INT_BUCK_x_y respectively INT_LDO_x_y register as well as bit TIMEOUT in the INT_TIMEOUT_RV_SD register.
- The initiation of the sequence is gated by the successful discharge of all rails, irrespective if enabled during the sequence or not. If the device is unable to discharge all rails below the SCG-threshold, the device sets INT_BUCK_x_y_IS_SET respectively INT_LDO_x_y_IS_SET bit in INT_SOURCE register and BUCKx_RV respectively LDOx_RV bit if the residual voltage is still present after 4 ms to 5 ms and the device remains in INITIALIZE state.
- The initiation of the sequence is gated by the die-temperature: if any one of the WARM detections is unmasked, the device does not power-up until the temperature on all sensors fell below $T_{\text {WARM_falling }}$ threshold if INITIALIZE state was entered due to a thermal event, respectively until the temperature on all sensors is below $T_{\text {WARM_rising }}$ threshold if INITIALIZE state was entered from OFF-state. If all thermal sensors are masked (WARM detection not causing a power-down), the device does not power-up until the temperature on all sensors is below $\mathrm{T}_{\text {HOT_falling }}$ threshold

Note
All rails get discharged prior to enable (irrespective if discharge-function is disabled).
An ON-request is deglitched to not trigger on noise. After the deglitch time, the device takes approximately 300 $\mu$ s until the first slot of the sequence starts. In case discharging of pre-biased rails is not completed by that time, the start of the sequence is further gated until all rails have discharged below SCG-voltage level.

Below graphic shows the power-up-sequence for NVM-ID 0x01, revision 0x2 as an example:


* depends on EN / PB / VSENSE and long/short configuration, $\sim 0$ if FSD is enabled
${ }^{* *}$ if applicable, slot-duration needs to adopt for enable- \& ramp-time of external rail
Figure 7-2. Power-up sequencing (example)

For details on ON-requests please see Push Button and Enable Input (PB/EN/VSENSE).

## CAUTION

I2C commands must only be issued after EEPROM-load completed.

### 7.3.2 Power-Down Sequencing

An OFF-request or a shut-down-fault triggers the power-down sequence. The OFF-request can be triggered by a falling edge on EN/PB/VSENSE if configured for EN or VSENSE respectively a long press of the push-button if configured as PB or by an I2C-command to I2C_OFF_REQ in MFP_CTRL register. This bit self-clears.
An I2C-triggered shut-down requires a renewed ON-request on the EN/PB/VSENSE pin. In case of EN- or VSENSE-configuration, a low-going edge followed by a high-going-edge is required on the EN/PB/VSENSE-pin. The falling-edge deglitch time for EN or VSENSE configuration $t_{\text {DEGL_EN/VSENSE_12 }}$ is shorter than the deglitchtime for pin-induced OFF-requests (tdegl_en_Fall and teegl_vsense_fall). The deglitch-times for PB-configuration remain.
In many cases, the power-down sequence follows the reverse power-up sequence. In some applications, all rails can be required to shut down at the same time with no delay between rails or require wait-times to allow discharging of rail.
The power-down sequence is configured as follows:

- The slot (respectively the position in the sequence) for each rail and GPO1, GPO2, GPIO, and nRSTOUT is defined using the corresponding *_SEQUENCE_SLOT registers, the four MSB for the ON-sequence, the four LSB for the down-sequencing.
- The duration of each slot is defined in the POWER_DOWN_SLOT_DURATION_x registers and can be configured as $0 \mathrm{~ms}, 1.5 \mathrm{~ms}, 3 \mathrm{~ms}$ or 10 ms . In total, 16 slots can be configured, allowing the sequence to span over multiple TPS65220-devices if more rails need to be supported.
- In addition to the slot-duration, the power-down sequence is also gated by the previous rail being discharged below the SCG-threshold, unless active discharge is disabled on the previous rail. If that does not occur, the power-down of subsequent rails is paused. To allow for power-down in case of biased or shorted rails, the sequence continues despite an incomplete discharge of the previous rail after eight times the slot-duration (or 12 ms in case of slot-duration of 0 ms ).
- To bypass the discharge-check, set the bit BYPASS_RAILS_DISCHARGED_CHECK in register GENERAL_CONFIG to ' 1 '.


## Note

In case active discharge on a rail is disabled, unsuccessful discharge of the rail within the slot duration does not gate the disable of the subsequent rail, but the sequence is purely timing based. In case of residual voltage, the RV-bit is be set regardless.

Active discharge is enabled by default and not NVM based. Thus, if desired, discharge need to be disabled after each VSYS-power-cycle. During RESET or OFF-request, the discharge configuration is not reset, as long as VSYS is present. However, in INITIALIZE state and prior to the power-up-sequence, all rails get discharged, regardless of the setting.

During the power-down-sequence, non-EEPROM-backed bits get reset, with the exception of unmasked interrupt bits and *_DISCHARGE_EN bits.
Below graphic shows the power-down-sequence for NVM-ID 0x01, revision 0x2 as an example:


* discharge-duration depends on Vout, Cout and load. Slot-duration needs to adopt. Slot-duration extends up to $8 x$ its configured value.

Figure 7-3. Power-down sequencing (example)

## CAUTION

Do not change the registers related to an ongoing sequence by I 2 C -command!
Non-NVM-bits are not accessible for approximately $80 \mu$ s after starting a transition into INITIALIZE state.

### 7.3.3 Push Button and Enable Input (EN/PB/VSENSE)

The EN/PB/VSENSE pin is used to enable the PMIC. The pin can be configured in three ways:

- Device enable (EN):
- This pin needs to be pulled high to enable the device. Pulling this pin low disables the device.
- The deglitch-time of the EN-pin is configured by EN_PB_VSENSE_DEGL in MFP_2_CONFIG register.
- The power-up sequence starts if the EN input is above the $\mathrm{V}_{\mathrm{IL}}$-threshold low for the configured $t_{\text {DEGL_EN_Rise. }}$
- To signify the power-up based on an EN/PB/VSENSE pin-event, the device sets bit POWER_UP_FROM_EN_PB_VSENSE in POWER_UP_STATUS_REG register. This bit does not assert the nINT pin. Write W 1 C to clear the bit.
- The power-down sequence starts if the EN input is below the $\mathrm{V}_{\mathbb{I H}}$-threshold for $\mathrm{t}_{\text {DEGL_EN_Fall }}$.
- In case of a shut-down fault, no renewed on-request is required. The device automatically executes the power-up sequence if EN input is still above the $\mathrm{V}_{\mathrm{IH}}$-threshold. ( EN considered level-sensitive)
- In case of a cold reset (regardless if by RESET-pin or I2C-request), no renewed on-request is required. The device automatically executes the power-up sequence if EN input is still above the $\mathrm{V}_{\mathbb{1 H}}$-threshold. (EN considered level-sensitive)
- Push-Button (PB):
- The PB pin is a CMOS-type input used to power-up the PMIC. Typically, the PB pin is connected to a momentary switch to ground and an external pullup resistor.
- The hold-time of the push-button is configured by EN_PB_VSENSE_DEGL in MFP_2_CONFIG register.
- The power-up sequence starts if the PB input is below the $\mathrm{V}_{\mathrm{IL}}$-threshold low for the configured $\mathrm{t}_{\text {PB_ }} \mathrm{oN}$.
- To signify the power-up based on an EN/PB/VSENSE pin-event, the device sets bit POWER_UP_FROM_EN_PB_VSENSE in POWER_UP_STATUS_REG register. This bit does not assert the nINT pin. Write W1C to clear the bit.
- The PB pin has a rising-edge deglitch tPB_RISE_DEGL $^{\text {to filter bouncing of the switch }}$
- The power-down sequence starts if the P $\bar{B}$ input is held low for $t_{\text {PB }}$ OFF-time (not configurable).
- In case of a shut-down fault, no renewed on-request is required. The device automatically executes the power-up sequence without a PB-press.
- In case of a cold reset (regardless if by RESET-pin or I2C-request), no renewed on-request is required. The device automatically executes the power-up sequence without a PB-press.
- A push-button press is only recognized after VSYS is above VSYS_POR-threshold or the PB must be held long enough after VSYS is above VSYS_POR-threshold.
- Following bits in the signify the PB-press events:
- PB_FALLING_EDGE_DETECTED: PB was pressed for a time-interval longer than tpb_INT_dEGL since the previous time this bit was cleared. This bit when set, does assert nINT pin (if config bit MASK_INT_FOR_PB='0'). Write W1C to clear.
- PB_RISING_EDGE_DETECTED: PB was released for a time-interval longer than tPB_INT_DEGL since the previous time this bit was cleared. This bit when set, does assert nINT pin (if config bit MASK_INT_FOR_PB='0'). Write W1C to clear.
- PB_REAL_TIME_STATUS: Deglitched (tpB_INT_DEGL) real-time status of PB pin. Valid only when EN/PB/VSENSE pin is configured as PB. This bit does not assert the nINT pin.
- Power-fail comparator input (VSENSE):
- Connected to a resistor divider from the supply-line of the pre-regulator, this pin can be used to sense the supply-voltage to the pre-regulator.
- The deglitch-time of the VSENSE-pin is configurable by EN_PB_VSENSE_DEGL in MFP_2_CONFIG register.
- Power-up is gated by VSYS being above the VSYS POR_Rising-threshold and the VSENSE input is above $^{\text {- }}$ the $\mathrm{V}_{\text {VSENSE- }}$-threshold (not deglitched)
- The power-up sequence starts if the VSENSE input rises above $\mathrm{V}_{\text {VSENSE }}$.
- To signify the power-up based on an EN/PB/VSENSE pin-event, the device sets bit POWER_UP_FROM_EN_PB_VSENSE in POWER_UP_STATUS_REG register. This bit does not assert the nINT pin. Write W1C to clear the bit.
- The power-down sequence starts if the VSENSE input falls below the $\mathrm{V}_{\text {VSENSE-threshold }}$ for $t_{\text {DEGL_VSENSE_Fall }}$, to avoid an un-sequenced power-off due to the loss of VSYS-supply-voltage.
- In case of a shut-down fault, no renewed on-request is required. The device automatically executes the power-up sequence if VSENSE input is still above the $\mathrm{V}_{\text {VSENSE- }}$-threshold.
- In case of a cold reset (regardless if by RESET-pin or I2C-request), no renewed on-request is required. The device automatically executes the power-up sequence if VSENSE input is still above the $\mathrm{V}_{\text {VSENSE }}{ }^{-}$ threshold.
- OFF-request by I2C-command
- An OFF-request can also be triggered by an I2C-command to I2C_OFF_REQ in MFP_CTRL register.
- After an OFF-request, a new ON-request is required:
- In case of EN-configuration, the EN input requires a rising edge (EN considered edge-sensitive)
- In case of PB-configuration, the PB needs to be pressed for a valid ON-request
- In case of VSENSE-configuration, the VSENSE input requires a rising edge (VSENSE considered edge-sensitive). This ON request can be triggered by power cycling the pre-regulator.
- The falling-edge deglitch time for EN or VSENSE configuration tDEGL_ENVISENSE_I2C $^{\text {is }}$ shorter than the deglitch-time for pin-induced OFF-requests ( $\mathrm{t}_{\text {DEGL_EN_Fall }}$ and $\mathrm{t}_{\text {DEGL_VSENSE_Fall }}$ ). The deglitch-times for PB-configuration remain.
- First Supply detection (FSD)
- First Supply detection (FSD) allows power-up as soon as supply voltage is applied, even if EN/PB/ VSENSE pin is at OFF_REQ status.
- FSD can be used in combination with any ON-request configuration, EN, PB or VSENSE.
- FSD can be enabled by setting PU_ON_FSD bit in MFP_2_CONFIG.
- At first power-up the EN/PB/VSENSE pin is treated as if the pin had a valid ON request.
- Once VSYS is above the VSYS POR_Rising-threshold, the PMIC $^{\text {P }}$
- loads the EEPROM
- enters INITIALIZE state
- perform the discharge-check
- initiates the power-up-sequence, regardless of the EN/PB/VSENSE-pin-state.
- To signify the power-up based on FSD, the device sets bit POWER_UP_FROM_FSD in

POWER_UP_STATUS_REG register. The nINT-pin does not toggle based on this bit. Write W1C to clear the bit.

- Thereafter, the EN/PB/VSENSE-pin is treated as if the pin had a valid ON-request, until we enter ACTIVE state (at the expiration of the last slot in the power-up-sequence).
- After that the device adheres to post-deglitch EN/PB/VSENSE-pin-status: if pin status has changed prior to entering ACTIVE state or in ACTIVE state, the device does adhere to the pin state. For example, if the EN/PB/VSENSE-pin is configured for EN, the device does power down in case the EN-pin is low (for longer than the deglitch time) at the time the device enters ACTIVE state.
- The duration for how long the ON-request is considered valid, regardless of the pin-state, can be controlled by length of nRSTOUT slot (and empty slots thereafter), as the PMIC enters ACTIVE state only after the last slot of the sequence expired.


### 7.3.4 Reset to SoC (nRSTOUT)

The reset output (nRSTOUT) is an open-drain output, intended to release the reset to the SoC or FPGA at the end of the power-up sequence. The timing for nRSTOUT is configured in the sequence. nRSTOUT is driven low until the device enters ACTIVE state or when powering-down from ACTIVE- or STBY-state. The pin is driven high during ACTIVE- and STBY-state.

### 7.3.5 Buck Converters (Buck1, Buck2, and Buck3)

The TPS65220 integrates three buck converters. Buck1 is capable of supporting up to 3.5 A and Buck2/Buck3 are capable of supporting up to 2 A of load current. The buck converters have an input voltage range from 2.5 V to 5.5 V , and can be connected either directly to the system power or the output of a another buck converter. The output voltage is programmable in the range of 0.6 V to 3.4 V : in 25 mV -steps up to 1.4 V , in 100 mV -steps between 1.4 V and 3.4 V .

- The ON/OFF state of the buck converters in ACTIVE state is controlled by the corresponding BUCKx_EN bit in the ENABLE_CTRL register.
- The ON/OFF state of the buck converters in STBY state is controlled by the corresponding BUCKx_STBY_EN bit in the STBY_1_CONFIG register.
- In INITIALIZE state, the buck converters are off, regardless of bit-settings.


## CAUTION

In case of buck-regulators that are not to be used at all, the FB_Bx pin must be tied to GND and the LX_Bx pin must be left floating.

- The converters activity can be controlled by the sequencer or through I2C communication.


## Buck-switch-modes:

## - Fixed frequency mode

- The converters can be forced into fixed frequency mode for best EMI-control by setting bit BUCK_FF_ENABLE bit in BUCKS_CONFIG register. If fixed-frequency mode is enabled, the regulators also support optional spread-spectrum. Spread-spectrum can be enabled by setting bit BUCK_SS_ENABLE in BUCKS_CONFIG register. Both of these settings are global for all three buck converters. If fixed-frequency mode is enabled, the regulators support individual out-of-phase switching: the phase-relation of the buck rails can be configured in $90^{\circ}$-steps in relation to the phase of Buck1 by BUCKx_PHASE_CONFIG in the BUCKS_CONFIG register. This bit must only change when this regulator is disabled.
- Quasi-fixed-frequency mode
- The converters can operate in forced-PWM mode, irrespective of load-current, or can be allowed to enter pulse-frequency-modulation (PFM) for low load-currents. The mode is controlled by either the MODE/ STBY pin or the MODE/RESET pin if either of those is configured as 'MODE', or by an I2C-command to MODE_I2C_CTRL bit in MFP_1_CONFIG register (see pin-configuration and I2C-command in 'PWM/PFM and Low Power Modes (MODE/-̄TTBY)' and PWM/PFM and Reset (MODE/RESET)' section.
- During a transition to ACTIVE state or to INITIALIZE state, the buck converters are forced to PWM, irrespective of the pin-state. PFM-entry is only allowed when the device enters ACTIVE state, upon completion of the sequence and expiration of the last power-up-slot.
- In case of a DVFS-induced output voltage change, the TPS65220 temporarily forces the buck-regulators into PWM until the voltage change completed. If PFM is allowed, the entry and exit into PFM is loadcurrent dependent. PFM starts when the inductor current reaches 0 A , which is the case at a load current approximately calculated by:
- $\mathrm{I}_{\text {LOAD }}=\left\{\left[\left(\mathrm{V}_{\text {PVIN_Bx }}-\mathrm{V}_{\text {BUCKx }}\right) / \mathrm{L}\right] \times\left(\mathrm{V}_{\text {BUCKx }} / \mathrm{V}_{\text {PVIN_Bx }}\right) \times\left(1 / f_{\text {SSw }}\right)\right\} / 2$

CAUTION
The user MUST NOT CHANGE the BUCK_FF_ENABLE! The bit is pre-configured by the manufacturer.

- The converters can be individually configured further for a high-bandwidth-mode for optimum transientresponse or lower bandwidth, allowing minimum output filter capacitance. The selection is done by the BUCKx_BW_SEL bits in GENERAL_CONFIG register and is available for both configurations, fixedfrequency and quasi-fixed-frequency. This bit must only change if this regulator is disabled. Please note the higher output-capacitance requirements for high bandwidth use case!
- If VSEL_SD/VSEL_DRR is configured as 'VSEL_DDR' by the VSEL_DDR_SD bit in MFP_1_CONFIG register, the output voltage of Buck3 can be controlled by pulling the VSEL_SD/VSEL_DDR pin high, low or leave the pin floating. These settings supports DDR3LV, DDR4, and DDR4LV supply voltages without an EEPROM change.


## CAUTION

The VSEL_DDR-pin needs to be hard-wired and must not change during operation.

- The buck converters have an active discharge function. The discharge function can be disabled individually per rail in the DISCHARGE_CONFIG register. If discharge is enabled, the device discharges the output is discharged to ground whenever a rail is disabled.
- Prior to a sequence into ACTIVE state (from INITIALIZE or STBY state), the device discharges the disabled rails regardless of the discharge-configuration to avoid starting into a pre-biased output.
- If a rail is enabled by an $\mathrm{I} 2 \mathrm{C}-\mathrm{command}$, active discharge is not enforced, but the rail is only enabled if the output voltage is below the SCG-threshold.
- This register is not EEPROM-backed and does reset if the device enters OFF-state.
- When in INITIALIZE state (during RESET or an I2C-OFF-request), the discharge configuration is not reset. Note: the power-down-sequence can be violated if the discharge function is disabled.
All Buck Converters support Dynamic Voltage Frequency Scaling (DVFS). The output-voltage can be changed during the operation to optimize the operating voltage for the operation point of the SoC in the lower output voltage range between 0.6 V and 1.4 V . The voltage change is controlled by writing to BUCK1_VOUT respectively BUCK2_VOUT or BUCK3_VOUT registers. During a DVFS-induced voltage transition, the active discharge function is temporarily enabled, irrespective of the discharge-configuration.


## Output Capacitance Requirements

The buck converters require sufficient output-capacitance for stability. The required minimum and supported maximum capacitance depends on the configuration:

- for fixed-frequency, low-bandwidth configuration, a minimum capacitance of 12 uF is required and a maximum total capacitance of 36 uF is supported
- for quasi-fixed-frequency, low-bandwidth configuration, a minimum capacitance of 10 uF is required and a maximum total capacitance of 75 uF is supported
- for fixed-frequency, high-bandwidth configuration, a minimum capacitance of 48uF is required and a maximum total capacitance of 144 uF is supported
- for quasi-fixed-frequency, high-bandwidth configuration, a minimum capacitance of 30 uF is required and a maximum total capacitance of 220 uF is supported


## Buck Fault Handling

- The TPS65220 detects under voltages on the buck converter outputs. The reaction to the detection of an under-voltage is dependent on the configuration of the respective BUCKx_UV bit and the MASK_EFFECT bit in INT_MASK_BUCKS. If not masked, the device sets bit INT_BUCK_1_2_IS_SET respectively INT_BUCK_3_IS_SET bit in INT_SOURCE register and bit BUCKx_UV in INT_BUCK_1_2 respectively INT_BUCK_3 register.

During a voltage transition (for example, when triggered by a DVFS induced voltage change), the device blanks the undervoltage detection by default and activates the undervoltage detection when the voltage transition completed.

If the device detects an undervoltage during the sequence into ACTIVE state (from INITIALIZE or STBY) and UV is not masked, the power-down-sequence starts at the end of the current slot.

If the device detects an undervoltage in ACTIVE-state or STBY-state and UV is not masked, the power-down sequence starts immediately. OC-detection is not maskable.

- The TPS65220 provides cycle-by-cycle current-limit on the buck converter outputs. If the device detects over-current for $t_{\text {DEGLITCH_oc_short }}$, respectively for $\mathrm{t}_{\text {DEGLITCH_oc_long }}$ (configurable individually per rail with EN_LONG_DEGL_FOR_OC_BUCKx in OC_DEGL_CONFIG register; applicable for rising-edge only), the
device sets INT_BUCK_1_2_IS_SET respectively INT_BUCK_3_IS_SET bit in INT_SOURCE register and bit BUCKx_OC (for positive over-current) respectively BUCKx_NEG_OC (for negative over-current) in INT_BUCK_1_2 respectively INT_BUCK_3 register.

During a voltage transition (for example, when triggered by a DVFS induced voltage change), the over current detection is blanked and only gets activated when the voltage transition is completed.

If the over-current occurs during the sequence into ACTIVE state (from INITIALIZE or STBY), the device disables the affected rail immediately and starts the power-down-sequence at the end of the current slot.

If the over-current occurs in ACTIVE-state or STBY-state, the device disables the affected rail immediately and starts the power-down sequence.

OC-detection is not maskable, but the deglitch-time is configurable. It is strongly recommended to use $t_{\text {DEGLITCH_Oc_short. }}$ Extended over-current can lead to increased aging or overshoot upon recovery.

- The TPS $\overline{6} 52 \overline{2} 0$ detects short-to-ground (SCG) faults on the buck-outputs. The reaction to the detection of an SCG event is to set INT_BUCK_1_2_IS_SET respectively INT_BUCK_3_IS_SET bit in INT_SOURCE register and bit BUCKx_SCG in INT_BUCK_1_2 respectively INT_BUCK_3 register. The affected rail is disabled immediately. The device sequences down all outputs and transitions into the INITIALIZE state.

SCG-detection is not maskable.
If a rail gets enabled, the device blanks SCG detection initially to allow the rail to ramp above the SCGthreshold.

- The TPS65220 detects residual voltage (RV) faults on the buck-outputs. The reaction to the detection of an RV event is to set INT_RV_IS_SET bit in INT_SOURCE register and bit BUCKx_RV in INT_RV register. The RV-detection is not maskable, but the nINT-reaction can be configured globally for all rails by MASK_INT_FOR_RV in INT_MASK_WARM register. The BUCKx_RV-flag is set regardless of masking, INT_RV_IS_SET bit is only set if nINT is asserted. The fault-reaction time and potential state-transition depends on the situation when residual voltage is detected:
- If the device detects residual voltage during an ON-request in the INITIALIZE state, the device gates power-up and the device remains in INITIALIZE state. If the RV-condition exists for more than 4 ms to 5 ms , the device sets BUCKx_RV-bit. If the RV-condition is not present any more, the device transitions to ACTIVE state.
- If the device detects residual voltage during power-up, ACTIVE_TO_STANDBY, or STANDBY_TO_ACTIVE sequences, the sequence is aborted and the device powers down.
- If the device detects residual voltage for more than 80 ms on any rail that was disabled during STBY state during a request to leave STBY state, the device transitions into INITIALIZE state. The device sets the BUCKx_RV-bit if the condition persists for 4 ms to 5 ms , but less than 80 ms .
- If the device detects residual voltage during power-up, ACTIVE_TO_STANDBY, or STANDBY_TO_ACTIVE sequences, the sequence is aborted and the device powers down.
- If residual voltage is detected during an EN-command of the rail by I2C, the BUCKx_RV-flag is set immediately, but no state transition occurs.
- The buck converters have a local over-temperature sensor. The reaction to a temperature warning is dependent on the configuration of the respective SENSOR_x_WARM_MASK bit in MASK_CONFIG register and the MASK_EFFECT bits in INT_MASK_BUCKS register. If the temperature at the sensor exceeds TWARM_Rising and is not masked, the device sets INT_SYSTEM_IS_SET bit in INT_SOURCE register and SENSORR_x_WARM bit in INT_SYSTEM register. In case the sensor detects a temperature exceeding $\mathrm{T}_{\text {HOT_Rising }}$, the converters power dissipation and junction temperature exceeds safe operating value. The device powers down all active outputs immediately and sets INT_SYSTEM_IS_SET bit in INT_SOURCE register and SENSOR_x_HOT bit in INT_SYSTEM register. The TPS65220 automatically recovers once the temperature drops below the $T_{\text {WARM_Falling }}$ threshold value (or below the $\mathrm{T}_{\text {HOT_Falling }}$ threshold value in case T_WARM is masked). The _HOT bit remains set and needs to be cleared by writing ' 1 '. The HOT-detection is not maskable.


## CAUTION

The buck can only supply output currents up to the respective current limit, including during start-up. Depending on the charge-current into the filter- and load-capacitance, the device potentially cannot drive the full output current to the load while ramping. As a rule of thumb, for a total load-capacitance exceeding $50 \mu \mathrm{~F}$, the load current must not exceed $25 \%$ of the rated output current. This limit applies also for dynamic output-voltage changes.

## CAUTION

The TPS65220 does not offer differential feedback pins. The device does not support remote sensing. Since a single-ended trace is susceptible to noise and must be as short as possible and thus connect directly to the output filter.

Table 7-1. BUCK output voltage settings

| BUCKx_VSET [decimal] | BUCKx_VSET [binary] | BUCKx_VSET [hexadecimal] | VOUT (Buck1 \& Buck2 and Buck3) [V] |
| :---: | :---: | :---: | :---: |
| 0 | 000000 | 00 | 0.600 |
| 1 | 000001 | 01 | 0.625 |
| 2 | 000010 | 02 | 0.650 |
| 3 | 000011 | 03 | 0.675 |
| 4 | 000100 | 04 | 0.700 |
| 5 | 000101 | 05 | 0.725 |
| 6 | 000110 | 06 | 0.750 |
| 7 | 000111 | 07 | 0.775 |
| 8 | 001000 | 08 | 0.800 |
| 9 | 001001 | 09 | 0.825 |
| 10 | 001010 | OA | 0.850 |
| 11 | 001011 | OB | 0.875 |
| 12 | 001100 | OC | 0.900 |
| 13 | 001101 | OD | 0.925 |
| 14 | 001110 | OE | 0.950 |
| 15 | 001111 | OF | 0.975 |
| 16 | 010000 | 10 | 1.000 |
| 17 | 010001 | 11 | 1.025 |
| 18 | 010010 | 12 | 1.050 |
| 19 | 010011 | 13 | 1.075 |
| 20 | 010100 | 14 | 1.100 |
| 21 | 010101 | 15 | 1.125 |
| 22 | 010110 | 16 | 1.150 |
| 23 | 010111 | 17 | 1.175 |
| 24 | 011000 | 18 | 1.200 |
| 25 | 011001 | 19 | 1.225 |
| 26 | 011010 | 1A | 1.250 |
| 27 | 011011 | 1B | 1.275 |
| 28 | 011100 | 1C | 1.300 |
| 29 | 011101 | 1D | 1.325 |
| 30 | 011110 | 1E | 1.350 |
| 31 | 011111 | 1F | 1.375 |
| 32 | 100000 | 20 | 1.400 |

TPS65220
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Table 7-1. BUCK output voltage settings (continued)

| BUCKx_VSET [decimal] | BUCKx_VSET [binary] | BUCKx_VSET [hexadecimal] | VOUT (Buck1 \& Buck2 and Buck3) [V] |
| :---: | :---: | :---: | :---: |
| 33 | 100001 | 21 | 1.500 |
| 34 | 100010 | 22 | 1.600 |
| 35 | 100011 | 23 | 1.700 |
| 36 | 100100 | 24 | 1.800 |
| 37 | 100101 | 25 | 1.900 |
| 38 | 100110 | 26 | 2.000 |
| 39 | 100111 | 27 | 2.100 |
| 40 | 101000 | 28 | 2.200 |
| 41 | 101001 | 29 | 2.300 |
| 42 | 101010 | 2A | 2.400 |
| 43 | 101011 | 2B | 2.500 |
| 44 | 101100 | 2C | 2.600 |
| 45 | 101101 | 2D | 2.700 |
| 46 | 101110 | 2E | 2.800 |
| 47 | 101111 | 2F | 2.900 |
| 48 | 110000 | 30 | 3.000 |
| 49 | 110001 | 31 | 3.100 |
| 50 | 110010 | 32 | 3.200 |
| 51 | 110011 | 33 | 3.300 |
| 52 | 110100 | 34 | 3.400 |
| 53 | 110101 | 35 | 3.400 |
| 54 | 110110 | 36 | 3.400 |
| 55 | 110111 | 37 | 3.400 |
| 56 | 111000 | 38 | 3.400 |
| 57 | 111001 | 39 | 3.400 |
| 58 | 111010 | 3A | 3.400 |
| 59 | 111011 | 3B | 3.400 |
| 60 | 111100 | 3 C | 3.400 |
| 61 | 111101 | 3D | 3.400 |
| 62 | 111110 | 3E | 3.400 |
| 63 | 111111 | 3F | 3.400 |

### 7.3.5.1 Dual Random Spread Spectrum (DRSS)

The bucks provide a digital spread spectrum which reduces the EMI of the power supply over a wide frequency range. Setting BUCK_SS_ENABLE to 1 enables the spread spectrum on all three bucks. Spread Spectrum is only applicable if the bucks are configured for fixed frequency, BUCK_FF_ENABLE set to 1. The internal modulator dithers the internal clock when the spread spectrum is enabled.

DRSS (a) combines a low-frequency triangular modulation profile (b) with a high frequency cycle-by-cycle random modulation profile (c). The low frequency triangular modulation improves performance in lower radio frequency bands (for example, the AM band), while the high frequency random modulation improves performance in higher radio frequency bands (for example, the FM band). In addition, the frequency of the triangular modulation is further modulated randomly to reduce the likelihood of any audible tones. To minimize output voltage ripple caused by spread spectrum, duty cycle is modified on a cycle-by-cycle basis to maintain a nearly constant duty cycle when dithering is enabled. See Figure 7-4 as an example of the modulation.


Figure 7-4. Dual Random Spread Spectrum

### 7.3.6 Linear Regulators (LDO1 through LDO4)

The TPS65220 offers a total of four linear regulators, where LDO1 and LDO2 share their properties and LDO3 and LDO4 share theirs.

## LDO1 and LDO2: $400 \mathrm{~mA}, 0.6 \mathrm{~V}$.. 3.4 V

Both, LDO1 and LDO2 are general-purpose LDOs intended to provide power to analog circuitry on the SOC or peripherals. The LDOs have an input voltage range from 1.5 V to 5.5 V , and can be connected either directly to the system power or the output of a Buck converter. The output voltage is programmable in the range of 0.6 V to 3.4 V in 50 mV -steps. Both LDOs support up to 400 mA . The LDOs can be configured in by-pass-mode, acting as load-switches. If configured in bypass-mode, the desired output voltage still needs to be specified in LDOx_VOUT register. The LDOs also support output-voltage changes while enabled, supporting functions like SD-card-IO-supply, changing from 3.3 V to 1.8 V after initialization, either in LDO-mode at a supply-voltage above 3.3 V or with a 3.3 V supply changing between bypass-mode and LDO-mode. The LDOs also support Load-switch mode (LSW_mode): in this case, output voltages of 1.5 V up to 5.5 V are supported. The desired voltage does not need to be configured in the LDOx_VOUT register.

- In case of SD-card-supply, one of the LDOs can be controlled by the VSEL_SD/VSEL_DDR, configured as VSEL_SD. Which LDO is controlled is selected by VSEL_RAIL bit in MFP_1_CONFIG register. The polarity of the pin can be configured via VSEL_SD_POLARITY bit in MFP_1_CONFIG register.

Alternatively, an I2C communication to VSEL_SD_I2C_CTRL in MFP_1_CONFIG register controls the change of the output voltage. Therefore, even if VSEL_SD/VSEL_DDR pin is configured as VSEL_DDR, the VSEL_RAIL bit still needs to be configured to define which LDO is affected by the I2C-command.

- The LDOs can be configured as linear regulators or operate in bypass-mode or be configured as a loadswitch (LSW-mode). The mode is configured by LDOx_LSW_CONFIG and LSW_BYP_CONFIG bits in LDOx_VOUT register.


## CAUTION

If an LDO is configured in bypass-mode, the output voltage must be configured and the PVIN_LDOx supply voltage must match the configured output voltage. PVIN_LDOx voltage must be within (configured VOUT) and (configured VOUT +200 mV ). Violation of this can result in instability.

In bypass- or LSW-mode, the LDO acts as a switch, where VOUT is VIN minus the drop over the FET-resistance ( $\mathrm{R}_{\text {BYPASS }}, \mathrm{R}_{\text {LSW }}$ ).

## Output Capacitance Requirements

The LDO regulators require sufficient output-capacitance for stability. The required minimum and supported maximum capacitance depends on the configuration:

- in LDO-mode, a minimum capacitance of 1.6 uF is required and a maximum total load capacitance (output filter and point-of-load combined) of 20 uF is supported
- in LSW- or bypass-mode, a minimum capacitance of 1.6 uF is required and a maximum total capacitance (output filter and point-of-load combined) of 50 uF is supported


## LDO3 and LDO4: $300 \mathrm{~mA}, 1.2 \mathrm{~V}$.. 3.3 V

Both, LDO3 and LDO4 are general-purpose LDOs intended to provide power to analog circuitry on the SoC or peripherals. The LDOs have an input voltage range from 2.2 V to 5.5 V , and can be connected either directly to the system power or the output of a Buck converter. Note, these LDOs need a headroom between VSYS and the LDO-output voltage of minimum 150 mV . The output voltage is programmable in the range of 1.2 V to 3.3 V in 50 mV -steps. Both LDOs support up to 300 mA . The LDOs can be configured to act as load-switches. In this case, output voltages of 2.2 V up to 5.5 V are supported. The desired voltage does not need to be configured in the LDOx_VOUT register.
These LDOs support a fast-ramp-mode with limited output capacitance and a slow-ramp-mode, allowing for larger total load capacitance.

## Output Capacitance Requirements

The LDO regulators require sufficient output-capacitance for stability. The required minimum and supported maximum capacitance depends on the configuration:

- for slow-ramp LDO-mode or LSW-mode, a minimum capacitance of 1.6 uF is required and a maximum total capacitance (output filter and point-of-load combined) of 30 uF is supported
- for fast-ramp LDO-mode or LSW-mode, a minimum capacitance of 1.6 uF is required and a maximum total capacitance (output filter and point-of-load combined) of 15 uF is supported


## LDO1, LDO2, LDO3 and LDO4

- The ON/OFF state of the LDOs in ACTIVE state is controlled by the corresponding LDOx_EN bit in the ENABLE_CTRL register.
- The ON/OFF state of the LDOs in STBY state is controlled by the corresponding LDOx_STBY_EN bit in the STBY_1_CONFIG register.
- In INITIALIZE state, the LDOs are off, regardless of bit-settings.


## CAUTION

In case of linear regulators that are not to be used at all, the VLDOx pin must be left floating.

- Each of the LDOs can be configured as linear regulators or be configured as a load-switch (LSW-mode). LDO1 and LDO2 can also operate in bypass-mode. The mode is configured by LDOx_LSW_CONFIG and LSW_BYP_CONFIG bits in LDOx_VOUT register individually per regulator.


## CAUTION

A mode change between LDO(/bypass) and LSW-mode must only be performed, when the regulator is disabled!
(A change between LDO and bypass-mode (supported by LDO1 and LDO2 only) is supported during operation.)

- The LDOs have an active discharge function. Whenever LDOx is disabled, the output is discharged to ground. The discharge function can be disabled individually per rail in the DISCHARGE_CONFIG register.
- Prior to a sequence into ACTIVE state (from INITIALIZE or STBY state), the device discharges the disabled rails regardless of the discharge-configuration to avoid starting into a pre-biased output.
- If a rail is enabled by an I2C-command, active discharge is not enforced, but the rail is only enabled if the output voltage is below the SCG-threshold.
- This register is not EEPROM-backed and is reset if the device enters OFF-state.
- When in INITIALIZE state (during RESET or an I2C-OFF-request), the discharge configuration is not reset. Note: the power-down-sequence can be violated if the discharge function is disabled


## LDO Fault Handling

- The TPS65220 detects under-voltages on the LDO-outputs. The reaction to the detection of an undervoltage is dependent on the configuration of the LDOx_UV_MASK bit in INT_MASK_LDOS register and the MASK_EFFECT in INT_MASK_BUCKS register. If not masked, the device sets bit INT_LDO_1_2_IS_SET respectively INT_LDO_3_4_IS_SET bit in INT_SOURCE register and bit LDOx_UV in INT_LDO_1_2 register respectively INT_LDO_3_4 register.

During a voltage transition (at power-up or triggered by toggling VSEL_SD-pin or an I2C-command), the device blanks the undervoltage detection by default and activates the undervoltage detection when the voltage transition completed.

If the device detects an undervoltage during the sequence into ACTIVE state (from INITIALIZE or STBY) and UV is not masked, the power-down-sequence starts at the end of the current slot.

If the device detects an undervoltage in ACTIVE-state or STBY-state and UV is not masked, the power-down sequence starts immediately. OC-detection is not maskable.

## CAUTION

If a LDO is configured in bypass-mode or LSW-mode, UV-detection is not supported.

- The TPS65220 provides current-limit on the LDO-outputs. If the PMIC detects over-current for $t_{\text {DEGLITCH_OC_short }}$, respectively for $\mathrm{t}_{\text {DEGLITCH_OC_long }}$ (configurable individually per rail with EN_LONG_DEGL_FOR_OC_LDOx in OC_DEGL_CONFIG register; applicable for rising-edge only), the device sets INT_LDO_1_2_IS_SET respectively INT_LDO_3_4_IS_SET bit in INT_SOURCE register and bit LDOx_OC in INT_LDO_1_2 respectively INT_LDO_3_4 register. The effected rail is disabled immediately.

During a voltage transition (at power-up or triggered by toggling VSEL_SD-pin or an I2C-command), the overcurrent detection is blanked and gets activated when the voltage transition completed.

If the over-current occurs during the sequence into ACTIVE state (from INITIALIZE or STBY), the device disables the affected rail immediately and starts the power-down-sequence at the end of the current slot.

If the over-current occurs in ACTIVE-state or STBY-state, the device disables the affected rail immediately and starts the power-down sequence.

OC-detection is not maskable, but the deglitch-time is configurable. It is strongly recommended to use $t_{\text {DEGLITCH_oc_short. }}$ Extended over-current can lead to increased aging or overshoot upon recovery.

- The TPS $\overline{6} 52 \overline{2} 0$ detects short-to-ground (SCG) faults on the LDO-outputs. The reaction to the detection of an SCG event is to set INT_LDO_1_2_IS_SET respectively INT_LDO_3_4_IS_SET bit in INT_SOURCE register and bit LDOx_SCG in INT_LDO_1_2 register respectively INT_LDO_3_4 register. The affected rail is disabled immediately. The device sequences down all outputs and transitions into INTIALIZE state.

SCG-detection is not maskable.
If a rail gets enabled, the device blanks SCG detection initially to allow the rail to ramp above the SCGthreshold.

- The TPS65220 detects residual voltage (RV) faults on the LDO-outputs. The reaction to the detection of an RV event is to set INT_RV_IS_SET bit in INT_SOURCE register and bit LDOx_RV in INT_RV register. The RV-detection is not maskable, but the nINT-reaction can be configured globally for all rails by MASK_INT_FOR_RV in INT_MASK_WARM register. The device sets the LDOx_RV-flag regardless of masking, INT_RV_IS_SET bit is only set if nINT is asserted. The fault-reaction time and potential statetransition depends on the situation when the faults are detected:
- If the device detects residual voltage during an ON-request in the INITIALIZE state, the PMIC gates power-up and the device remains in INITIALIZE state. If the RV-condition is detected for more than 4 ms to 5 ms , the device sets the LDOx_RV-bit but remains in INITIALIZE state as long as the RV-condition
exists. If the RV-condition is not present any more, the device transitions to ACTIVE state, provided the ON-request is still valid.
- If the device detects residual voltage during power-up, ACTIVE_TO_STANDBY, or STANDBY_TO_ACTIVE sequences, the sequence is aborted and the device powers down.
- If the device detects residual voltage for more than 80 ms on any rail that was disabled during STBY state during a request to leave STBY state, the device transitions into INITIALIZE state. The device sets the LDOx_RV-bit if the condition persists for 4 ms to 5 ms , but less than 80 ms .
- If the device detects residual voltage during power-up, ACTIVE_TO_STANDBY, or STANDBY_TO_ACTIVE sequences, the sequence is aborted and the device powers down.
- If the device detects residual voltage during an EN-command of the rail by I2C, the LDOx_RV-bit is set immediately, but no state transition occurs.
- The LDOs have a local over-temperature sensor. The reaction to a temperature warning is dependent on the configuration of the respective SENSOR_x_WARM_MASK bit in and the MASK_EFFECT bit in INT_MASK_BUCKS register. If the temperature at the sensor exceeds TWARM_Rising and is not masked, the device sets INT_SYSTEM_IS_SET bit in INT_SOURCE register and SENSOR_x_WARM bit in INT_SYSTEM register. In case the sensor detects a temperature exceeding $\mathrm{T}_{\text {HOT_Rising }}$, the converters power dissipation and junction temperature exceeds safe operating value. The device powers down all active outputs immediately and sets INT_SYSTEM_IS_SET bit in INT_SOURCE register and SENSOR_x_HOT bit in INT_SYSTEM register. The TPS65220 automatically recovers once the temperature drops below the $T_{\text {WARM_FAlling }}$ threshold value (or below the THOT_FAlling threshold value in case T_WARM $^{\text {is masked). The }}$ _HOT bit remains set and needs to be cleared by writing '1'. The HOT-detection is not maskable.

Table 7-2. LDO output voltage settings

| LDOx_VSET [decimal] | LDOx_VSET [binary] | LDOx_ VSET [hexadecimal] | VOUT (LDO1 and LDO2, LDO mode) [V] | VOUT (LDO1 and LDO2, bypassmode) [V] | VOUT (LDO3 and LDO4, LDO mode) [V] |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 000000 | 00 | 0.60 | reserved | 1.20 |
| 1 | 000001 | 01 | 0.65 | reserved | 1.20 |
| 2 | 000010 | 02 | 0.70 | reserved | 1.20 |
| 3 | 000011 | 03 | 0.75 | reserved | 1.20 |
| 4 | 000100 | 04 | 0.80 | reserved | 1.20 |
| 5 | 000101 | 05 | 0.85 | reserved | 1.20 |
| 6 | 000110 | 06 | 0.90 | reserved | 1.20 |
| 7 | 000111 | 07 | 0.95 | reserved | 1.20 |
| 8 | 001000 | 08 | 1.00 | reserved | 1.20 |
| 9 | 001001 | 09 | 1.05 | reserved | 1.20 |
| 10 | 001010 | OA | 1.10 | reserved | 1.20 |
| 11 | 001011 | OB | 1.15 | reserved | 1.20 |
| 12 | 001100 | 0C | 1.20 | reserved | 1.20 |
| 13 | 001101 | OD | 1.25 | reserved | 1.25 |
| 14 | 001110 | OE | 1.30 | reserved | 1.30 |
| 15 | 001111 | OF | 1.35 | reserved | 1.35 |
| 16 | 010000 | 10 | 1.40 | reserved | 1.40 |
| 17 | 010001 | 11 | 1.45 | reserved | 1.45 |
| 18 | 010010 | 12 | 1.50 | 1.50 | 1.50 |
| 19 | 010011 | 13 | 1.55 | 1.55 | 1.55 |
| 20 | 010100 | 14 | 1.60 | 1.60 | 1.60 |
| 21 | 010101 | 15 | 1.65 | 1.65 | 1.65 |

Table 7-2. LDO output voltage settings (continued)

| LDOx_VSET [decimal] | LDOx_VSET [binary] | LDOx_VSET [hexadecimal] | VOUT (LDO1 and LDO2, LDO mode) [V] | VOUT (LDO1 and LDO2, bypassmode) [V] | VOUT (LDO3 and LDO4, LDO mode) [V] |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 22 | 010110 | 16 | 1.70 | 1.70 | 1.70 |
| 23 | 010111 | 17 | 1.75 | 1.75 | 1.75 |
| 24 | 011000 | 18 | 1.80 | 1.80 | 1.80 |
| 25 | 011001 | 19 | 1.85 | 1.85 | 1.85 |
| 26 | 011010 | 1A | 1.90 | 1.90 | 1.90 |
| 27 | 011011 | 1B | 1.95 | 1.95 | 1.95 |
| 28 | 011100 | 1C | 2.00 | 2.00 | 2.00 |
| 29 | 011101 | 1D | 2.05 | 2.05 | 2.05 |
| 30 | 011110 | 1E | 2.10 | 2.10 | 2.10 |
| 31 | 011111 | 1F | 2.15 | 2.15 | 2.15 |
| 32 | 100000 | 20 | 2.20 | 2.20 | 2.20 |
| 33 | 100001 | 21 | 2.25 | 2.25 | 2.25 |
| 34 | 100010 | 22 | 2.30 | 2.30 | 2.30 |
| 35 | 100011 | 23 | 2.35 | 2.35 | 2.35 |
| 36 | 100100 | 24 | 2.40 | 2.40 | 2.40 |
| 37 | 100101 | 25 | 2.45 | 2.45 | 2.45 |
| 38 | 100110 | 26 | 2.50 | 2.50 | 2.50 |
| 39 | 100111 | 27 | 2.55 | 2.55 | 2.55 |
| 40 | 101000 | 28 | 2.60 | 2.60 | 2.60 |
| 41 | 101001 | 29 | 2.65 | 2.65 | 2.65 |
| 42 | 101010 | 2A | 2.70 | 2.70 | 2.70 |
| 43 | 101011 | 2B | 2.75 | 2.75 | 2.75 |
| 44 | 101100 | 2C | 2.80 | 2.80 | 2.80 |
| 45 | 101101 | 2D | 2.85 | 2.85 | 2.85 |
| 46 | 101110 | 2E | 2.90 | 2.90 | 2.90 |
| 47 | 101111 | 2F | 2.95 | 2.95 | 2.95 |
| 48 | 110000 | 30 | 3.00 | 3.00 | 3.00 |
| 49 | 110001 | 31 | 3.05 | 3.05 | 3.05 |
| 50 | 110010 | 32 | 3.10 | 3.10 | 3.10 |
| 51 | 110011 | 33 | 3.15 | 3.15 | 3.15 |
| 52 | 110100 | 34 | 3.20 | 3.20 | 3.20 |
| 53 | 110101 | 35 | 3.25 | 3.25 | 3.25 |
| 54 | 110110 | 36 | 3.30 | 3.30 | 3.30 |
| 55 | 110111 | 37 | 3.35 | 3.35 | 3.30 |
| 56 | 111000 | 38 | 3.40 | 3.40 | 3.30 |
| 57 | 111001 | 39 | 3.40 | 3.40 | 3.30 |
| 58 | 111010 | 3A | 3.40 | 3.40 | 3.30 |

Table 7-2. LDO output voltage settings (continued)

| LDOx_VSET <br> [decimal] | LDOx_VSET [binary] | LDOx_VSET [hexa- <br> decimal] | VOUT (LDO1 and <br> LDO2, LDO mode) <br> [V] | VOUT (LDO1 <br> and LDO2, bypass- <br> mode) [V] | VOUT (LDO3 and <br> LDO4, LDO mode) <br> [V] |
| :--- | :--- | :--- | :--- | :--- | :--- |
| 59 | 111011 | $3 B$ | 3.40 | 3.40 | 3.30 |
| 60 | 111100 | $3 C$ | 3.40 | 3.40 | 3.30 |
| 61 | 111101 | $3 D$ | 3.40 | 3.40 | 3.30 |
| 62 | 111110 | $3 E$ | 3.40 | 3.40 | 3.30 |
| 63 | 111111 | $3 F$ | 3.40 | 3.40 |  |

### 7.3.7 Interrupt Pin (nINT)

During power-up, the output of the nINT pin does depend on whether any INT_SOURCE flags are set and the configuration of the MASK_EFFECT bit in INT_MASK_BUCKS register-. If one or more flags are set, then nINT pin is pulled low and is only released high after those flags have been cleared by writing ' 1 ' to them. Note, the nINT-pin can only transition 'high' if a VIO-voltage for the pull-up is available.
In ACTIVE or STBY state, the nINT pin signals any event or fault condition to the host processor. Whenever a fault or event occurs in the IC, the corresponding interrupt bit is set in the INT register, and the open-drain output is driven low. In case the device transitions to INITIALIZE state, the nINT pin is pulled low as well, regardless if the transition is triggered by an OFF-request or a fault.

If the fault is no longer present, a W1C (write '1' to clear) needs to be performed on the failure bits. This command also allows the nINT-pin to release (return to Hi-Z state).

If a failure persists, the corresponding bit remains set and the INT pin remains low.
The UV-faults can be individually masked per rail in INT_MASK_UV registers. The thermal sensors can individually be masked by SENSOR_x_WARM_MASK in the MASK_CONFIG register. The effect of the masking for UV and WARM is defined globally by MASK_EFFECT bits in MASK_CONFIG register.

The nINT reaction for RV-faults is defined globally by MASK_INT_FOR_RV bits in MASK_CONFIG register.

- $00 b=$ no state change, no nINT reaction, no bit set
- $01 b=$ no state change, no nINT reaction, bit set
- $10 b=$ no state change, nINT reaction, bit set (same as 11b)
- $11 \mathrm{~b}=$ no state change, nINT reaction, bit set (same as 10b)


## CAUTION

Masking poses a risk to the device or the system. In case the masking is performed by I2Ccommand, the masking bits do get reset to EEPROM-based default after transitioning to INITIALIZE state. Bits corresponding to faults newly configured via I2C as SD-faults do not get cleared.

It is strongly discouraged to mask OC- and UV-detection on the same rail.

### 7.3.8 PWM/PFM and Low Power Modes (MODE/STBY)

The TPS65220 supports low power modes through the I2C-control or through the MODE/STBY pin. The configuration of the pin is selected by MODE_STBY_CONFIG in MFP_2_CONFIG register. The polarity of this pin can be configured by writing to MODE_STBY_POLARITY in MFP_1_CONFIG register. The polarityconfiguration must not change after power-up. Only either MODE/RESET or MODE/STBY must be configured as MODE. If both are configured as MODE, MODE/RESET takes priority and MODE/STBY is ignored.

## MODE/STBY configured as 'MODE':

- If configured as 'MODE', the pin-status determines the switching-mode of the buck-converters. This selection is only applicable in quasi-fixed-frequency mode.
- Forcing this pin for longer than $t_{\text {DEGLITCH_MFP }}$ forces the buck-regulators into PWM-mode (irrespective of load current). De-asserting this pin low allows the buck regulators to enter PFM-mode. The entry into PFM and exit from PFM is governed by the load current. Only one pin, either MODE/STBY or MODE/RESET must be configured as 'MODE'.
- The selection of auto-PFM/forced-PWM can also be controlled by writing to the bit MODE_I2C_CTRL in MFP_1_CONFIG register.
- A change of the MODE does not cause a state-transition.
- During power-up of any one of the three bucks, a MODE change is blanked on this rail and only takes effect after the ramp completed.


## MODE/STBY configured as 'STBY':

- Forcing this pin for longer than tDEGLITCH_MFP sequences down the rails selected to turn off in the STBY_1_CONFIG respectively the STBY_2_CONFIG register. De-asserting this pin sequences the selected rails on again.
- A transition into and out of STBY state can also be controlled by writing to the bit STBY_I2C_CTRL in MFP_CTRL register, provided I2C communication is supported during STBY state.
- A change of the MODE/STBY pin configured as 'STBY' does cause a state-transition by definition.
- Regardless of the pin-setting, the device always powers up into ACTIVE state. The device reacts to the STBY-pin-state or I2C-commands only after entering ACTIVE state.


## MODE/STBY configured as 'MODE \& STBY':

- The pin can be configured to perform both functions, MODE and STBY simultaneously
- Forcing this pin for longer than $t_{\text {DEGLITCH MFP }}$ sequences down the rails selected to turn off in the STBY_1_CONFIG respectively the STBY_2_CONFIG register and allows auto-PFM entry (only applicable in quasi-fixed-frequency mode). De-asserting this pin sequences the selected rails on again and forces the buck-regulators to forced-PWM. Polarity settings need to be harmonized for this configuration.
- If a transition into and out of STBY state is commanded by writing to the bit STBY_I2C_CTRL in MFP_CTRL register (provided I2C communication is supported during STBY state), a separate command for the MODEchange is required by writing to the bit MODE_I2C_CTRL in MFP_1_CONFIG register.
- A change of the MODE/STBY pin configured as 'MODE\&STBY' does cause a state-transition by definition.
- By default STBY is deasserted and the pin is ignored until the device completed the power-up-sequence. During power-up of any one of the three bucks, a MODE-change is blanked on this rail and only takes effect after the ramp completed. A state-change commanded by STBY-pin is reacted to even during the ramp of rails (except during INITIALIZE-to-ACTIVE transition).
Please see the truth-table for pin- and I2C-commands in Section PWM/PFM and Reset (MODE/RESET)


### 7.3.9 PWM/PFM and Reset (MODE/RESET)

This pin can be configured as an alternative MODE pin (in case MODE/STBY is configured for STBY-function) or as a RESET pin. The configuration of the pin is selected by MODE_RESET_CONFIG in MFP_2_CONFIG register. The polarity of this pin can be configured by writing to MODE_RESET_POLARITY in MFP_1_CONFIG register. The polarity-configuration must not change after power-up. Only MODE/RESET or MODE/STBY must be configured as MODE. If both are configured as MODE, MODE/RESET takes priority and MODE/STBY is ignored.

## MODE/RESET configured as 'MODE':

- If configured as 'MODE', the pin-status determines the switching-mode of the buck-converters. This selection is only applicable in quasi-fixed-frequency mode.
- Forcing this pin for longer than $t_{\text {DEGLITCH_MFP }}$ forces the buck-regulators into PWM-mode (irrespective of load current). De-asserting this pin low allows the buck regulators to enter PFM-mode. The entry into PFM and exit from PFM is governed by the load current. Only one pin, either MODE/STBY or MODE/RESET must be configured as 'MODE'.
- The selection of auto-PFM/forced-PWM can also be controlled by writing to the bit MODE_I2C_CTRL in MFP_1_CONFIG register.
- A change of the MODE does not cause a state-transition.
- During power-up of any one of the three bucks, a MODE-change is blanked on this rail and only takes effect after the ramp completed.


## MODE/RESET configured as 'RESET':

- In RESET configuration, this pin is edge sensitive, but still applies the deglitch time. Consequently, toggling this pin and holding the pin for longer than $t_{\text {DEGLITCH_RESET }}$ causes a reset.
- By default, RESET is deasserted and RESET requests, via pin or I2C, are only serviced if the device is in ACTIVE state, STBY state, or transitions between these 2 states.
- The TPS65220 supports WARM or COLD reset. The configuration is made by bit WARM_COLD_RESET_CONFIG in MFP_2_CONFIG register.
- If configured for COLD reset, the device executes the power down sequence and transitions to INITIALIZE state. Then, EEPROM is reloaded and rails power-up again in normal power-up-sequence, provided there are no faults and no OFF-request. The execution of a COLD-reset sets the bit COLD_RESET_ISSUED in POWER_UP_STATUS_REG register. The read-out of this bit allows to track if a COLD-reset was performed. The bit gets set regardless if the reset was commanded by I2C or by the pin. The nINT-pin does not toggle based on this bit. Write W1C to clear the bit.
- If configured for WARM reset, all enabled rails remain on, but the output voltage of rails that support dynamic voltage change is reset to the boot-voltage. Specifically, following configurations get reset to their boot-value: BUCK1_VSET, BUCK2_VSET, BUCK3_VSET, LDO1_VSET, LDO2_VSET, LDO1_BYP_CONFIG, LDO2_BYP_CONFIG and VSEL_SD_I2C_CTRL.

All other bits, even in the same register, remain at their current state. For example, LDOx_LSW_CONFIG, BUCKx_BW_SEL, BUCKx_UV_THR_SEL and the MFP_1_CONFIG register bits do NOT get reset during a WARM-reset.

WARM Reset cannot override the VSEL_SD-pin command. In other words: even if a WARM Reset occurs, if the VSEL_SD pin is commanding 1.8 V -LDO mode, that remain in effect.

- A reset can also be triggered by writing to the bit WARM_RESET_I2C_CTRL respectively the bit COLD_RESET_I2C_CTRL in MFP_CTRL register.


## Note

Shut-down-faults and OFF-requests take priority over a RESET-request. If a RESET-requests occurs simultaneously with one of those, the device enters INITIALIZE state and requires a new ON-request to start up.

Reset requests, via pin or 12 c , are only serviced in ACTIVE state, STBY state, or a transition between these two states.

Please see below truth-table for pin- and I2C-commands.
Table 7-3. MODE/STBY configuration

| Pin Name | Pin Configuration (MODE_STBY_CON FIG) | Pin Polarity (MODE_STBY_POL ARITY) | Pin state (schematic) | $\begin{aligned} & \text { I2C control } \\ & \text { (MODE_I2C_CTRL) } \end{aligned}$ | Resulting Function |
| :---: | :---: | :---: | :---: | :---: | :---: |
| MODE/STBY | MODE | $x$ | x | 1h | forced PWM |
| MODE/STBY | MODE | Oh | L | Oh | auto-PFM |
| MODE/STBY | MODE | Oh | H | Oh | forced PWM |
| MODE/STBY | MODE | 1h | L | Oh | forced PWM |
| MODE/STBY | MODE | 1h | H | Oh | auto-PFM |
| MODE/STBY | STBY | 0 | L | x | STBY |
| MODE/STBY | STBY | 0 | H | x | ACTIVE |
| MODE/STBY | STBY | 1 | L | x | ACTIVE |
| MODE/STBY | STBY | 1 | H | x | STBY |

Table 7-4. MODE/RESET configuration

| Pin Name | Pin Configuration <br> (MODE_RESET_CO <br> NFIG) | Pin Polarity <br> (MODE_RESET_POL <br> ARIT Y) | Pin state <br> (schematic) | I2C control <br> (MODE_I2C_CTRL) | Resulting Function |
| :--- | :--- | :--- | :--- | :--- | :--- |
| MODE/RESET | MODE* | x | MODE* | x | L |

The * for MODE indicates that the MODE/RESET pin takes priority in case both, MODE/RESET and MODE/ STBY are configured as 'MODE', and thus the respective pin to be observed is MODE/RESET.

### 7.3.10 Voltage Select pin (VSEL_SD/VSEL_DDR)

The function of this pin is configured by VSEL_DDR_SD in MFP_1_CONFIG.
When configured as VSEL_SD, the bit VSEL_RAIL in MFP_1_CONFIG register selects LDO1 or LDO2 to be controlled by the pin. The configuration must not change after power-up.

## VSEL_SD/VSEL_DDR configured as 'VSEL_SD': SD-card-IO-select:

The polarity of this pin can be configured by writing to VSEL_SD_POLARITY in MFP_1_CONFIG register. Toggling the pin changes the output voltage of the selected LDO between hard-coded 1.8 V and the voltage configured in LDOx_VOUT. For the SD-card-IO-supply, LDOx_VOUT must be configured for 3.3 V . A change of the VSEL_SD status does not cause a state-transition.

## CAUTION

In SD-card-configuration, customer must configure the pin-polarity and drive the pin so that the LDO delivers 3.3 V at start-up.

## VSEL_SD/VSEL_DDR configured as 'VSEL_DDR':

Pulling this pin high sets the output voltage of Buck3 to 1.35 V (DDR3LV), leaving the pin floating sets the output voltage of Buck3 to 1.2 V (DDR4, LP-DDR3, some LP-DDR2), pulling the pin low sets the output voltage of the Buck3 voltage configured in BUCK3_VOUT. For LP-DDR4, BUCK3_VOUT must be configured to 1.1 V .

## CAUTION

This function needs to be hard-wired and must not change during operation.

## CAUTION

The VSEL_RAIL still needs to be configured for the LDO that supplies the SD-card-IO-voltage, as an I2C-command toggles the selected LDO-rail for the SD-card. The VSEL_SD_POLARITY bit has no effect if the pin is configured as VSEL_DDR.

The Table below shows the various combinations.

Table 7-5. VSEL_SD/VSEL_DDR configuration options

| Pin Configuration (VSEL_DDR_SD) | Pin Polarity (VSEL_SD_POLARITY) | Rail selection (VSEL_RAIL) | PIN state (schematic) | I2C control (VSEL_SD_I2C_ CTRL) | Resulting Function |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0:DDR | n/a | $\begin{aligned} & 0=\text { LDO1 } \\ & 1=\text { LDO2 } \\ & \text { (needed for I2C } \\ & \text { control) } \end{aligned}$ | L | $\begin{aligned} & \text { Oh: } \text { LDOx = 1.8V } \\ & \text { 1h: } \text { LDOx = } \\ & \text { LDOx_VSET } \end{aligned}$ | BUCK3 = Buck3_VSET |
| 0:DDR | n/a | $\begin{aligned} & 0=\text { LDO1 } \\ & 1=\text { LDO2 } \\ & \text { (needed for I2C } \\ & \text { control) } \end{aligned}$ | open | $\begin{aligned} & \text { Oh: } \text { LDOx = 1.8V } \\ & 1 \mathrm{~h}: \text { LDOx = } \\ & \text { LDOx_VSET } \end{aligned}$ | BUCK3 $=1.2 \mathrm{~V}$ |
| 0:DDR | n/a | $\begin{aligned} & \hline 0=\text { LDO1 } \\ & 1=\text { LDO2 } \\ & \text { (needed for I2C } \\ & \text { control) } \end{aligned}$ | H | $\begin{aligned} & \text { Oh: LDOx = 1.8V } \\ & \text { 1h: LDOx = } \\ & \text { LDOx_VSET } \end{aligned}$ | BUCK3 $=1.35$ |
| 1:SD | 0 | 0 =LDO1 | L | x | LDO1 $=1.8 \mathrm{~V}$ |
| 1:SD | 0 | 0 =LDO1 | H | x | LDO1 = LDO1_VSET |
| 1:SD | 1 | 0 =LDO1 | L | x | LDO1 = LDO1_VSET |
| 1:SD | 1 | 0 =LDO1 | H | x | LDO1 $=1.8 \mathrm{~V}$ |
| 1:SD | 0 | 1 =LDO2 | L | x | LDO2 $=1.8 \mathrm{~V}$ |
| 1:SD | 0 | 1 =LDO2 | H | x | LDO2 = LDO2_VSET |
| 1:SD | 1 | 1 =LDO2 | L | x | LDO2 = LDO2_VSET |
| 1:SD | 1 | 1 =LDO2 | H | x | LDO2 $=1.8 \mathrm{~V}$ |

### 7.3.11 General Purpose Inputs or Outputs (GPO1, GPO2, and GPIO)

GPO1 and GPO2 pins are always configured as an output.
The GPIO-pin is an input/output, however, the input-functionality is only used in multi-PMIC configuration. In single-PMIC configuration, the pin can be used as an output. The state can be read by polling the bit GPIO_STATUS bit in MFP_CTRL register.
The I/O-configuration of the GPIO-pin is done by the MULTI_DEVICE_ENABLE bit in MFP_1_CONFIG register.
If configured as outputs, these pins can be used to sequence external rails. The GP(I)Os can be included in the sequence or be controlled via I2C-interface, writing to GPOx_EN respectively GPIO_EN bit in GENERAL_CONFIG register. The GPO is released high if activated.
The GPIO function is to be used if multiple TPS65220 need to be synchronized, in case more rails need to be supplied. See application section on usage. See section "Multi-PMIC operation" for details.
The polarity of these pins is not changeable.

### 7.3.12 $\mathrm{I}^{2} \mathrm{C}$-Compatible Interface

The default $I^{2} \mathrm{C} 1$ 7-bit device address of the TPS65220 is set to $0 \times 30$ ( 0 b0110000 in binary), but can be changed if needed, for example for multi-PMIC-operation.
The $I^{2} \mathrm{C}$-compatible synchronous serial interface provides access to the configurable functions and registers on the device. This protocol uses a two-wire interface for bidirectional communications between the devices connected to the bus. The two interface lines are the serial data line (SDA), and the serial clock line (SCL). Every device on the bus is assigned a unique address and acts as either a controller or a target depending on whether it generates or receives the serial clock SCL. The SCL and SDA lines must each have a pullup resistor placed somewhere on the line and remain HIGH even when the bus is idle. The TPS65220 supports standard mode ( 100 kHz ), fast mode ( 400 kHz ), and fast mode plus ( 1 MHz ) when VIO is 3.3 V or 1.8 V .

### 7.3.12.1 Data Validity

The data on the SDA line must be stable during the HIGH period of the clock signal (SCL). In other words, the state of the data line can only be changed when clock signal is LOW.


Figure 7-5. Data Validity Diagram

### 7.3.12.2 Start and Stop Conditions

The device is controlled through an $I^{2} \mathrm{C}$-compatible interface. START and STOP conditions classify the beginning and end of the $I^{2} \mathrm{C}$ session. A START condition is defined as the SDA signal going from HIGH to LOW while the SCL signal is HIGH. A STOP condition is defined as the SDA signal going from LOW to HIGH while the SCL signal is HIGH. The $I^{2} \mathrm{C}$ controller device always generates the START and STOP conditions.


Figure 7-6. Start and Stop Sequences
The $I^{2} \mathrm{C}$ bus is considered busy after a START condition and free after a STOP condition. The $I^{2} \mathrm{C}$ controller device can generate repeated START conditions during data transmission. A START and a repeated START condition are equivalent function-wise. Figure $7-7$ shows the SDA and SCL signal timing for the $I^{2} \mathrm{C}$-compatible bus. For timing values, see the Specification section.


Figure 7-7. $1^{2} \mathrm{C}$-Compatible Timing

### 7.3.12.3 Transferring Data

Every byte put on the SDA line must be eight bits long, with the most significant bit (MSB) being transferred first. Each byte of data has to be followed by an acknowledge bit. The acknowledge related clock pulse is generated by the controller device. The controller device releases the SDA line (HIGH) during the acknowledge clock pulse. The device pulls down the SDA line during the 9th clock pulse, signifying an acknowledge. The device generates an acknowledge after each byte has been received.

There is one exception to the acknowledge after every byte rule. When the controller device is the receiver, it must indicate to the transmitter an end of data by not-acknowledging (negative acknowledge) the last byte clocked out of the target device. This negative acknowledge still includes the acknowledge clock pulse (generated by the controller device), but the SDA line is not pulled down.
After the START condition, the bus controller device sends a chip address. This address is seven bits long followed by an eighth bit which is a data direction bit (READ or WRITE). For the eighth bit, a 0 indicates a WRITE and a 1 indicates a READ. The second byte selects the register to which the data is written. The third byte contains data to write to the selected register. Figure 7-8 shows an example bit format of device address $110000-\mathrm{Bin}=60 \mathrm{Hex}$.


Figure 7-8. Example Device Address


Figure 7-9. I $^{2}$ C Write Cycle without CRC


When READ function is to be accomplished, a WRITE function must precede the READ function as shown above.
Figure 7-10. $I^{2}$ C Read Cycle without CRC

### 7.4 Device Functional Modes



1) in case of a RESET or a SD-fault, the device transitions from INITIALIZE state to the ACTIVE state without a new Push-button-ON_Request. In EN or VSENSE configuration, the ON-request must still be valid to transition to ACTIVE state.
2) If INITIALIZE state was entered due to a Thermal-Shut-Down, the temperature monitors remain active until the temperature on all sensors fell below $T_{\text {WARM }}$ threshold. Thermal-Shut-Down causes immediate shut-shutdown, no sequencing down

Figure 7-11. State diagram

### 7.4.1 Modes of Operation

### 7.4.1.1 OFF State

In OFF state, the PMIC is insufficiently supplied. Neither internal logic nor external rails are available. If VSYS exceeds VSYS_POR voltage and the internal 1.8V-rail (VDD1P8) is in regulation, the device enters the INITIALIZE state.

### 7.4.1.2 INITIALIZE State

In INITIALIZE state, the device is completely shut down with the exception of a few circuits to monitor the EN/PB/VSENSE input. Whenever entering the INITIALIZE state, the PMIC reads the memory and loads the registers to their EEPROM-default values. The ${ }^{2} \mathrm{C}$ communication interface is turned off .

Entry to INITIALIZE state is gated if any one of the thermal sensors is above the $T_{\text {WARM_Rising }}$ threshold and WARM-detection is not masked.

The EEPROM loading takes approximately 2.3 ms . The power-up sequence can only execute after the EEPROM-load and if all rails are discharged below the $\mathrm{V}_{\text {BUCKx_SCG_TH }}$ respectively $\mathrm{V}_{\text {LDOx_SCG_TH }}$ threshold.

If INITIALIZE state was entered from OFF state, bit POWER_UP_FROM_OFF in POWER_UP_STATUS_REG register is set and remains set until a write-1-clear is issued. Read-out of this bit allows to determine if INITIALZE state was entered from OFF state or due to a Shut-down-fault or OFF-request.

In INITIALIZE state, the nINT pin status is dependent if faults are and masking thereof. If no faults are present or nINT-reaction for those are masked, nINT-pin is pulled high, provided a VIO-voltage for the pull-up is available.

To transition from the INITIALIZE state to the ACTIVE state, one of the ON-requests must occur:

- The EN input is 'high' (if EN/PB/VSENSE is configured as 'EN' or 'VSENSE')
- The PB input is pulled low for at least $t_{\text {PB_ON_SLOw }}$ respectively $t_{\text {PB_ON_FAST }}$ (if EN/PB/VSENSE is configured as 'PB')


## Note

The DISCHARGE_CONFIG register is purposefully omitted from RESET when entering INITIALIZE state from ACTIVE or STBY state. When entering INITIALIZE state from OFF state, the EEPROM content is loaded. If the discharge configuration changed after power-up, a different start-up behavior can occur, depending if the INITIALIZE state was entered from OFF state or from ACTIVE/STBY.

### 7.4.1.3 ACTIVE State

The ACTIVE state is the normal mode of operation when the system is up and running. All enabled bucks converters and LDOs are operational and can be controlled through the I2C interface. After a wake-up event, the PMIC discharges potential residual voltages on the outputs, regardless of the discharge-configuration. ACTIVE state can also be directly entered from STBY state by de-asserting the STBY pin high or by an I2C command. See STBY state description for details. To transition to STBY, the STBY pin must be forced or an I2C command to STBY_I2C_CTRL in MFP_CTRL register must be issued.

To transition to INITIALIZE state, one of the following OFF_Requests must occur:

- The EN input is 'low' (if EN/PB/VSENSE is configured as 'EN' or 'VSENSE')
- The PB input is pulled low for at least $t_{\text {PB_OfF }}$ (if EN/PB/VSENSE is configured as 'PB')
- An I2C OFF-request is issued

If a shut-down-fault (SD_Fault) occurs while in the ACTIVE state, TPS65220 sequences down the active outputs and transition to the INITIALIZE state. The device does transition to ACTIVE state without a new
Push-button-ON_Request. In EN or VSENSE configuration, the ON-request must still be valid to transition to ACTIVE state.

### 7.4.1.4 STBY State

STBY state is a low-power mode of operation intended to support system standby. The mode can be entered by the MODE/STBY pin, if configured as 'STBY' or by an I2C-command to STBY_I2C_CTRL in MFP_CTRL
register. Typically, the majority of power rails are turned off with the exception of rails required by the SoC during this state. Which rails power down in STBY state can be configured in STBY_1_CONFIG and STBY_2_CONFIG register.

The monitoring functions are all available: Under-voltage- (UV), Short-to-GND- (SCG) and Over-current- (OC) detection, thermal warning (WARM) and thermal-shutdown (TSD/HOT) remain active.

The device enters ACTIVE state if STBY is de-asserted or an I2C command is received (provided VIO-supply remained active). Before starting the STBY to ACTIVE sequence, disabled rails are discharged. In case this fails to complete within 80 ms , the device also runs into a timeout-condition and transitions to INITIALIZE state. The device sets bit TIMEOUT in the INT_TIMEOUT_RV_SD register and the fault flags for the rail that caused the shut-down.

The sequence into and out of STBY state is the same as for power-down respectively for power-up. Rails that remain on in STBY are skipped, but their respective slots are still executed.

## CAUTION

The device cannot transition from INITIALIZE state to STBY state directly, it must first enter ACTIVE state.

## CAUTION

Only rails that were enabled in ACTIVE state can remain enabled in STBY. Previously disabled rails cannot be turned on in STBY-state. Activity in STBY-state requires a AND-combination of LDOx_EN / BUCKx_EN and LDOx_STBY_EN/BUCKx_STBY_EN.

## CAUTION

Do not change the registers related to an ongoing sequence by I2C-command!
Non-NVM-bits are not accessible for $\sim 80$ us after starting a transition into INITIALIZE state.

### 7.4.1.5 Fault Handling

## Detectable Faults

The TPS65220 offers various fault-detections. Per default, all of them lead to a sequenced shut-down. Some of them are maskable and the reaction to masked faults is configurable.
The device provides the following fault-detections on the supply voltage (VSYS) and internal voltage supply (VDD1P8):

- Undervoltage on VSYS, resulting in transition to OFF state or gating start-up
- Overvoltage-protection on VSYS, resulting in transition to OFF state
- Under- or Overvoltage on internal 1.8 V -supply (VDD1P8), resulting in transition to OFF state or gating start-up.

None of these faults are maskable.
The TPS65220 provides the following fault-detections on the buck- and LDO-outputs:

- Undervoltage detection (UV)
- Over Current detection (OC), triggering on positive as well as (for buck-converters) negative current-limit
- Short-to-GND detection (SCG)
- Temperature warning (WARM) and Thermal Shut Down (TSD / HOT)
- Residual Voltage (RV) and Residual Voltage - Shutdown (RV_SD)
- Timeout (TO)

SCG, OC, HOT, RV_SD and TO are not maskable. If any one of those occurs, the device powers down. Positive and negative current limit share the same mask-bit per regulator.

The reaction to UV, RV and WARM faults is configurable. If not masked, a fault triggers a sequenced shut-down. UV, RV and WARM can be masked individually per regulator in INT_MASK_BUCKS, INT_MASK_LDOS and INT_MASK_WARM registers. No state-transition occurs in case of a masked fault. Whether bits are set and if nINT is pulled low can be configured globally by MASK_EFFECT bits in MASK_CONFIG register. Positive and negative current limit share the same mask-bit per regulator.

- $00 \mathrm{~b}=$ no state change, no nINT reaction, no bit set
- $01 \mathrm{~b}=$ no state change, no nINT reaction, bit set
- $10 b=$ no state change, nINT reaction, bit set (same as 11 b )
- $11 \mathrm{~b}=$ no state change, nINT reaction, bit set (same as 10b)

For any fault that corresponds to a shut-down condition, the fault-bit remains asserted until a W1C (write-oneclear) operation is performed via I2C (assuming the fault is not present any more). In case of a shut-down fault, no renewed on-request is required. The device automatically executes the power up sequence if the fault is no longer present as long as EN/VSENSE is still high and no PB-press is required for a restart.
For any fault that is not a shut-down condition (for example because the fault is masked), the bit is cleared when going to the INITIALIZE state.

## Thermal Warning and Shutdown

There are two thermal thresholds: Thermal-warning (WARM) and Thermal Shutdown (TSD / HOT).

- Thermal Warning, WARM-threshold:
- if the temperature exceeds TWARM_Rising threshold, the SENSOR_x_WARM-bit is set and the PMIC sequences down (unless masked).
- if the temperature fell below Twarm_Falling threshold, the device powers up again, without a new Push-button-ON_Request. In EN or VSENSE configuration, the ON-request must still be valid to transition to ACTIVE state.
- if the temperature exceeds TwARM_Rising threshold, but SENSOR_x_WARM_MASK bit is /bits are set, the PMIC remains in ACTIVE state. Fault-reporting occurs as configured by MASK_EFFECT bits. The processor makes the decision to either sequence the power down or throttles back on the running applications to reduce the power consumption and hopefully avoiding a Thermal Shutdown situation.
- Thermal Shutdown, HOT-threshold, applicable if WARM-threshold is masked:
- if the temperature exceeds THOT_Rising threshold, the SENSOR_x_HOT-bit is set and the PMIC powers off all rails immediately. This power down is simultaneously and not sequenced.
- in case ALL sensors are masked for WARM-detection (all SENSOR_x_WARM_MASK bits are set), the PMIC does power back up once the temperature drops below the THOT_Falling $^{\text {threshold, provided a }}$ a valid ON-request is present.
- in case any one of the sensors is unmasked for WARM-detection, the PMIC does power back up once the temperature drops below the TWARM_Falling threshold, without a new Push-button-ON_Request. In EN or VSENSE configuration, the ON-request must still be valid to transition to ACTIVE state.


## Residual Voltage

Residual voltage checks are performed at various occasions: before starting the INITIALIZE- to ACTIVEtransition and any time before a rail is enabled, regardless if during the sequence, by 12 C -command or during the STBY- to ACTIVE-transition. RV-checks are also performed during the sequences, to detect if a rail that is supposed to be disabled is pulled up by another rail. The treatment of RV-faults depends on the situation when the fault occurs:

- INITIALIZE to ACTIVE:
- if residual voltage is detected for more than 4 ms to 5 ms prior to the execution of the sequence, the respective INT_RV_IS_SET bit in INT_SOURCE register and LDOx_RV respectively BUCKx_RV bit in INT_RV register is set and remains set, even if the discharge is successful at a later time and the ON-request is executed.
- if the residual voltage is detected during the sequence, this constitutes a shutdown-fault: the device initiates the power-down-sequence at the end of the slot-duration. The device sets the

TPS65220
respective INT_TIMEOUT_RV_SD_IS_SET bit in INT_SOURCE register, LDOx_RV_SD respectively BUCKx_RV_SD bit and bit TIMEOUT in INT_TIMEOUT_RV_SD register.

- ACTIVE to STBY:
- if active discharge is enabled and residual voltage is detected after eight times the power-down slotduration, this constitutes a shutdown-fault: the device sequences down at the end of the slot. The device sets INT_TIMEOUT_RV_SD_IS_SET bit in INT_SOURCE register, the LDOx_RV_SD respectively BUCKx_RV_SD bit and the bit TIMEOUT in INT_TIMEOUT_RV_SD register.
- if the residual voltage is detected during the sequence, this constitutes a shutdown-fault: the device sequences down at the end of the slot-duration and sets bit INT_TIMEOUT_RV_SD_IS_SET in INT_SOURCE register and LDOx_RV_SD respectively BUCKx_RV_SD bit in INT_TIMEOUT_RV_SD register.
- STBY to ACTIVE:
- if residual voltage is detected prior to the execution of the sequence for more than 4 ms to 5 ms , the device sets INT_RV_IS_SET bit in INT_SOURCE register and LDOx_RV respectively BUCKx_RV bit in INT_RV register. The bit remains set, even if the discharge is successful before timeout expires and the STBY-to-ACTIVE-sequence is executed.
- if residual voltage is detected for more than 80 ms prior to the execution of the sequence, this constitutes a shutdown-fault: the device sequences down and sets the bit INT_TIMEOUT_RV_SD_IS_SET in INT_SOURCE register and LDOx_RV_SD respectively BUCKx_RV_SD bit in INT_TIMEOUT_RV_SD register. In addition, the device sets the bit TIMEOUT in INT_TIMEOUT_RV_SD register.
- if the residual voltage is detected during the sequence, this constitutes a shutdown-fault: the device sequences down at the end of the slot-duration and sets the INT_TIMEOUT_RV_SD_IS_SET bit in INT_SOURCE register and LDOx_RV_SD respectively BUCKx_RV_SD bit in INT_TIMEOUT_RV_SD register. The TIMEOUT bit is not set in this case.
- ACTIVE to INITIALIZE or STBY to INITIALIZE
- if the residual voltage is detected at the end of the power-down slot-duration of the respective rail, this gates the disabling of the subsequent rail for up to eight times the slot-duration, but then the powersequence continues regardless of the residual voltage. No bit is set in this case.
- MASKING of RV-bits
- the reaction of the nINT-pin reaction in case of residual voltage detection is maskable for LDOx_RV respectively BUCKx_RV bits by MASK_INT_FOR_RV bit in MASK_CONFIG register.
- neither the bit nor the shutdown-fault-reaction in case of residual voltage detection is maskable for LDOx_RV_SD respectively BUCKx_RV_SD bits.
- Timeout
- Timeout occurs if residual voltage cannot be discharged in time. The bit TIMEOUT in INT_TIMEOUT_RV_SD register is set. See details above.


## Note

In case active discharge on a rail is disabled, the unsuccessful discharge of that rail within the slot duration does not gate the disable of the subsequent rail.

During power-down, the device sets neither RV-bits nor RV_SD-bits for rails with disabled discharge.

## CAUTION

For every detected Shut-Down fault, irrespective if prior to the sequence due to unsuccessful discharge, during the power-up-sequence or in ACTIVE or STBY state, the retry counter (RETRY_COUNT in POWER_UP_STATUS_REG register) is incremented. The device attempts two retries to power-up. If both fail, a power-cycle on VSYS is required to reset the retry counter. Any successful power-up also resets the retry counter.

If faults are masked and do not cause a shut-down, the retry counter does not increment.
To disable the retry-counter, set bit MASK_RETRY_COUNT in INT_MASK_UV register. When set, the device attempts to retry infinitely.

Below table gives an overview of the fault-behavior in ACTIVE and STBY states if unmasked and whether a fault is maskable.

## CAUTION

Masking of faults can pose a risk to the device or the system, including but not limited to starting into a pre-biased output.

It is strongly discouraged to mask OC- and UV-detection on the same rail.

Table 7-6. Fault Handling

| Block | Fault | ACTIVE or STBY state (if fault <br> NOT masked) | ACTIVE or STBY state (if fault IS masked) |
| :--- | :--- | :--- | :--- |
| BUCK \& LDO | Residual voltage - shutdown- <br> Fault - RV_SD *) | Fault triggers a sequenced shut- <br> down to INITIALIZE state | Not maskable |
| BUCK \& LDO | Residual voltage - RV | Fault does not trigger state- <br> change | Fault does not trigger state-change |
| BUCK \& LDO | Undervoltage - UV | Fault triggers a sequenced shut- <br> down to INITIALIZE state | Fault does not trigger state-change |
| BUCK \& LDO | Overcurrent - OC | Fault triggers a sequenced shut- <br> down to INITIALIZE state | Fault does not trigger state-change |
| BUCK \& LDO | Temperature warning - WARM | Fault triggers a sequenced shut- <br> down to INITIALIZE state | Not maskable |
| BUCK \& LDO | Fault triggers a sequenced shut- <br> down to INITIALIZE state | Yes |  |
| BUCK \& LDO | Temperature shut-down - HOT | Fault triggers an immediate <br> shut-down to INITIALIZE state <br> (not sequenced) | Not maskable |
| BUCK \& LDO | Undervoltage - UV | Fault triggers an immediate <br> shut-down to OFF state (not <br> sequenced) | Not maskable |
| VSYS | Overvoltage - OV | Fault triggers an immediate <br> shut-down to OFF state (not <br> sequenced) | Not maskable |
| Vndervoltage or Overvoltage - | Fault triggers an immediate <br> shut-down to OFF state (not <br> sequenced) | Not maskable |  |
| VSYS or OV | Tatate |  |  |

*) RV_SD and TIMEOUT faults can only occur during a sequence

### 7.5 User Registers

The registers up to register 27h, USER_GENERAL_NVM_STORAGE_REG are backed up by EEPROM. The reset value corresponds to the configuration of the orderable part number and is signified by an ' X ' herein. Please refer to the Technical Reference Manual (TRM) of the respective orderable part-number.
The registers 28 h through 37 h are not EEPROM-backed and reset to the value shown in the register map.
Registers 00h, TI_DEV_ID, 01h, NVM_ID, 28h, MANUFACTURING_VER and 41h, FACTORY_CONFIG_2 are hard-wired and cannot be changed by the user.

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### 7.6 Device Registers

Table 7-7 lists the memory-mapped registers for the Device registers. All register offset addresses not listed in Table 7-7 should be considered as reserved locations and the register contents should not be modified.

Table 7-7. DEVICE Registers

| Offset | Acronym | Register Name | Section |
| :---: | :---: | :---: | :---: |
| Oh | TI_DEV_ID | Device ID | Go |
| 1h | NVM_ID | NVM configuration ID | Go |
| 2h | ENABLE_CTRL | Enable/Push-Button/Vsense Control | Go |
| 3h | BUCKS_CONFIG | Generic Buck Configuration | Go |
| 4h | LDO4_VOUT | LDO4 Configuration | Go |
| 5 h | LDO3_VOUT | LDO3 Configuration | Go |
| 6h | LDO2_VOUT | LDO2 Configuration | Go |
| 7h | LDO1_VOUT | LDO1 Configuration | Go |
| 8h | BUCK3_VOUT | Buck3 Configuration | Go |
| 9 h | BUCK2_VOUT | Buck2 Configuration | Go |
| Ah | BUCK1_VOUT | Buck1 Configuration | Go |
| Bh | LDO4_SEQUENCE_SLOT | Power-up and -down slot for LDO4 | Go |
| Ch | LDO3_SEQUENCE_SLOT | Power-up and -down slot for LDO3 | Go |
| Dh | LDO2_SEQUENCE_SLOT | Power-up and -down slot for LDO2 | Go |
| Eh | LDO1_SEQUENCE_SLOT | Power-up and -down slot for LDO10 | Go |
| Fh | BUCK3_SEQUENCE_SLOT | Power-up and -down slot for Buck3 | Go |
| 10h | BUCK2_SEQUENCE_SLOT | Power-up and -down slot for Buck2 | Go |
| 11h | BUCK1_SEQUENCE_SLOT | Power-up and -down slot for Buck1 | Go |
| 12h | nRST_SEQUENCE_SLOT | Power-up and -down slot for nRSTOUT | Go |
| 13h | GPIO_SEQUENCE_SLOT | Power-up and -down slot for GPIO | Go |
| 14h | GPO2_SEQUENCE_SLOT | Power-up and -down slot for GPO2 | Go |
| 15h | GPO1_SEQUENCE_SLOT | Power-up and -down slot for GPO1 | Go |
| 16h | ```POWER_UP_SLOT_DURATION _1``` | Slot-duration at power-up for slot0-3 | Go |
| 17h | POWER_UP_SLOT_DURATION _2 | Slot-duration at power-up for slot4-7 | Go |
| 18h | POWER_UP_SLOT_DURATION 3 | Slot-duration at power-up for slot8-11 | Go |
| 19h | POWER_UP_SLOT_DURATION - 4 | Slot-duration at power-up for slot12-15 | Go |
| 1Ah | POWER_DOWN_SLOT_DURATI ON_1 | Slot-duration at power-down for slot0-3 | Go |
| 1Bh | POWER_DOWN_SLOT_DURATI ON_2 | Slot-duration at power-down for slot4-7 | Go |
| 1Ch | POWER_DOWN_SLOT_DURATI ON_3 | Slot-duration at power-down for slot8-11 | Go |
| 1Dh | POWER_DOWN_SLOT_DURATI ON_4 | Slot-duration at power-down for slot12-15 | Go |
| 1Eh | GENERAL_CONFIG | LDO-undervoltage and GPO-enable | Go |
| 1Fh | MFP_1_CONFIG | Multi-Function pin configuration1 | Go |
| 20h | MFP_2_CONFIG | Multi-Function pin configuration2 | Go |
| 21h | STBY_1_CONFIG | STBY configuration LDOs and Bucks | Go |
| 22h | STBY_2_CONFIG | STBY configuration GPIO and GPO | Go |
| 23h | OC_DEGL_CONFIG | Overcurrent deglitch time per rail | Go |

Table 7-7. DEVICE Registers (continued)

| Offset | Acronym | Register Name | Section |
| :---: | :--- | :--- | :--- |
| 24 h | INT_MASK_UV | Undervoltage fault-masking | Go |
| 25 h | MASK_CONFIG | WARM-masking and mask-effect | Go |
| 26 h | I2C_ADDRESS_REG | I2C-address | Go |
| 27 h | USER_GENERAL_NVM_STORA <br> GE_REG | User-configurable register (NVM-backed) | Go |
| 28 h | MANUFACTURING_VER | Silicon-revision (read-only) | Go |
| 29 h | MFP_CTRL | I2C-control for RESET, STBY, OFF | Go |
| $2 A \mathrm{~h}$ | DISCHARGE_CONFIG | Discharge configuration per rail | Go |
| $2 B h$ | INT_SOURCE | Interrupt source | Go |
| 2 Ch | INT_LDO_3_4 | OC, UV, SCG for LDO3 and LDO4 | Go |
| 2 Dh | INT_LDO_1_2 | OC, UV, SCG for LDO1 and LDO2 | Go |
| $2 E h$ | INT_BUCK_3 | OC, UV, SCG for Buck3 | Go |
| $2 F h$ | INT_BUCK_1_2 | OC, UV, SCG for Buck1 and Buck2 | Go |
| 30 h | INT_SYSTEM | WARM and HOT fault flags | Go |
| 31 h | INT_RV | RV (residual voltage) per rail | Go |
| 32 h | INT_TIMEOUT_RV_SD | RV (residual voltage) per rail causing shut- |  |
| down | Go |  |  |
| 33 h | INT_PB | PushButton status and edge-detection | Go |
| 34 h | USER_NVM_CMD_REG | DIY - user programming commands | Go |
| 35 h | POWER_UP_STATUS_REG | Power-up status and STATE | Go |
| 36 h | SPARE_2 | Spare register (not NVM-backed) | Go |
| 37 h | SPARE_3 | Spare register (not NVM-backed) |  |
| 41 h | FACTORY_CONFIG_2 | Revision of NVM-configuration (read only) |  |
|  |  |  |  |

Complex bit access types are encoded to fit into small table cells. Table 7-8 shows the codes that are used for access types in this section.

Table 7-8. Device Access Type Codes

| Access Type | Code | Description |
| :--- | :--- | :--- |
| Read Type |  |  |
| R | R | Read |
| Write Type | W | Write |
| W | W <br> 1C | Write <br> 1 to clear |
| W1C | W | Write |
| WSelfCIFF |  |  |
| Reset or Default Value | Value after reset or the default <br> value |  |
| $-n$ |  |  |

### 7.6.1 TI_DEV_ID Register (Offset = Oh) [Reset = X]

TI_DEV_ID is shown in Figure 7-12 and described in Table 7-9.
Return to the Summary Table.
Figure 7-12. TI_DEV_ID Register
$\left.\begin{array}{|lllllll|}\hline 7 & 6 & 5 & 4 & 3 & 2 & 1\end{array}\right]$

Table 7-9. TI_DEV_ID Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
| $7-0$ | TI_DEVICE_ID | R/W | X | TI_DEVICE_ID[7]: $0-$ TA: $-40 \circ \mathrm{oC}$ to 105oC, TJ: -40oC to 1250C 1 <br> - TA: -40oC to 125oC, TJ: -40oC to 150oC TI_DEVICE_ID[6:0] $=$ <br> Device GPN Note: This register can be programmed only by the <br> manufacturer! Refer to Technical Reference Manual / User's Guide <br> for specific numbering and associated configuration. (Default from <br> NVM memory) |

### 7.6.2 NVM_ID Register (Offset $=\mathbf{1 h}$ ) [Reset $=\mathrm{X}]$

NVM_ID is shown in Figure 7-13 and described in Table 7-10.
Return to the Summary Table.
Figure 7-13. NVM_ID Register

| 7 | 6 | 5 | 4 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TI_NVM_ID |  |  |  |  |  |  |
| R/W-X |  |  |  |  |  |  |

Table 7-10. NVM_ID Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
| $7-0$ | TI_NVM_ID | R/W | X | NVM ID of the IC Note: This register can be programmed only by the <br> manufacturer! Refer to Technical Reference Manual / User's Guide <br> for specific numbering and associated configuration. (Default from <br> NVM memory) |

### 7.6.3 ENABLE_CTRL Register (Offset = 2h) [Reset = X]

ENABLE_CTRL is shown in Figure 7-14 and described in Table 7-11.
Return to the Summary Table.
Figure 7-14. ENABLE_CTRL Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | LDO4_EN | LDO3_EN | LDO2_EN | LDO1_EN | BUCK3_EN | BUCK2_EN | BUCK1_EN |
| R-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |  |

Table 7-11. ENABLE_CTRL Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | LDO4_EN | R/W | X | Enable LDO4 regulator (Default from NVM memory) <br> Oh = Disabled <br> 1h = Enabled |
| 5 | LDO3_EN | R/W | X | Enable LDO3 regulator (Default from NVM memory) <br> Oh = Disabled <br> 1h = Enabled |
| 4 | LDO2_EN | R/W | X | Enable LDO2 regulator (Default from NVM memory) <br> Oh = Disabled <br> 1h = Enabled |
| 3 | LDO1_EN | R/W | X | Enable LDO1 regulator (Default from NVM memory) <br> Oh = Disabled <br> 1h = Enabled |
| 2 | BUCK3_EN | R/W | X | Enable BUCK3 regulator (Default from NVM memory) <br> Oh = Disabled <br> 1h = Enabled |
| 1 | BUCK2_EN | R/W | X | Enable BUCK2 regulator (Default from NVM memory) <br> Oh = Disabled <br> 1h = Enabled |
| 0 | BUCK1_EN | Enable BUCK1 regulator (Default from NVM memory) <br> Oh = Disabled <br> 1h = Enabled |  |  |

### 7.6.4 BUCKS_CONFIG Register (Offset $=3 \mathrm{~h}$ ) [Reset $=\mathrm{X}$ ]

BUCKS_CONFIG is shown in Figure 7-15 and described in Table 7-12.
Return to the Summary Table.
Figure 7-15. BUCKS_CONFIG Register

| 7 | 6 | 5 | 4 | 3 | 2 |
| :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-12. BUCKS_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | USER_NVM_SPARE_2 | R/W | X | Spare bit in user NVM space (Default from NVM memory) |
| 6 | USER_NVM_SPARE_1 | R/W | X | Spare bit in user NVM space (Default from NVM memory) |
| 5 | BUCK_SS_ENABLE | R/W | X | Spread spectrum enabled on Bucks (only applicable in FF-mode) <br> (Default from NVM memory) <br> Oh = Spread spectrum disabled <br> 1h = Spread spectrum enabled |
| 4 | BUCK_FF_ENABLE | R/W | X | All Bucks set into fixed frequency mode NOTE: MUST NOT CHANGE AT ANY TIME! (Default from NVM memory) <br> Oh = Quasi-fixed frequency mode <br> 1h = Fixed frequency mode |
| 3-2 | BUCK3_PHASE_CONFIG | R/W | X | Phase of BUCK3 clock. Applicable if Bucks are configured for fixed frequency. NOTE: ONLY CHANGE WHILE RAIL IS DISABLED! <br> (Default from NVM memory) <br> Oh $=0$ degrees <br> 1h = 90 degrees <br> $2 \mathrm{~h}=180$ degrees <br> $3 \mathrm{~h}=270$ degrees |
| 1-0 | BUCK2_PHASE_CONFIG | R/W | X | Phase of BUCK2 clock. Applicable if Bucks are configured for fixed frequency. NOTE: ONLY CHANGE WHILE RAIL IS DISABLED! <br> (Default from NVM memory) <br> Oh $=0$ degrees <br> 1h $=90$ degrees <br> $2 \mathrm{~h}=180$ degrees <br> $3 \mathrm{~h}=270$ degrees |

### 7.6.5 LDO4_VOUT Register (Offset = 4h) [Reset = X]

LDO4_VOUT is shown in Figure 7-16 and described in Table 7-13.
Return to the Summary Table.
Figure 7-16. LDO4_VOUT Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-13. LDO4_VOUT Register Field Descriptions
$\left.\begin{array}{|c|l|l|l|l|}\hline \text { Bit } & \text { Field } & \text { Type } & \text { Reset } & \text { Description } \\ \hline 7 & \text { LDO4_SLOW_PU_RAMP } & \text { R/W } & \text { X } & \begin{array}{l}\text { LDO4 Power-up ramp When set high, slows down the power-up } \\ \text { ramp to } \sim \text { 3ms. Cout max 30uF When set low, ramp time is } \sim 660 \mathrm{us.} \\ \text { Cout max 15uF (Default from NVM memory) }\end{array} \\ \text { Oh = Fast ramp for power-up ( } \sim 660 \mathrm{us} \text { ) } \\ \text { 1h = Slow ramp for power-up ( } \sim \text { 3ms) }\end{array}\right)$

Table 7-13. LDO4_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 5-0 | LDO4_VSET | R/W | X | Voltage selection for LDO4. The output voltage range is from 1.2 V to 3.3V. (Default from NVM memory) <br> Oh $=1.200 \mathrm{~V}$ <br> $1 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $2 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $3 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $4 h=1.200 \mathrm{~V}$ <br> $5 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $6 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $7 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $8 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $9 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $\mathrm{Ah}=1.200 \mathrm{~V}$ <br> $\mathrm{Bh}=1.200 \mathrm{~V}$ <br> $\mathrm{Ch}=1.200 \mathrm{~V}$ <br> $\mathrm{Dh}=1.250 \mathrm{~V}$ <br> $\mathrm{Eh}=1.300 \mathrm{~V}$ <br> $\mathrm{Fh}=1.350 \mathrm{~V}$ <br> $10 \mathrm{~h}=1.400 \mathrm{~V}$ <br> $11 \mathrm{~h}=1.450 \mathrm{~V}$ <br> $12 \mathrm{~h}=1.500 \mathrm{~V}$ <br> $13 \mathrm{~h}=1.550 \mathrm{~V}$ <br> $14 \mathrm{~h}=1.600 \mathrm{~V}$ <br> $15 \mathrm{~h}=1.650 \mathrm{~V}$ <br> $16 \mathrm{~h}=1.700 \mathrm{~V}$ <br> $17 \mathrm{~h}=1.750 \mathrm{~V}$ <br> $18 \mathrm{~h}=1.800 \mathrm{~V}$ <br> $19 \mathrm{~h}=1.850 \mathrm{~V}$ <br> $1 \mathrm{Ah}=1.900 \mathrm{~V}$ <br> $1 \mathrm{Bh}=1.950 \mathrm{~V}$ <br> $1 \mathrm{Ch}=2.000 \mathrm{~V}$ <br> $1 \mathrm{Dh}=2.050 \mathrm{~V}$ <br> $1 \mathrm{Eh}=2.100 \mathrm{~V}$ <br> $1 \mathrm{Fh}=2.150 \mathrm{~V}$ <br> $20 \mathrm{~h}=2.200 \mathrm{~V}$ <br> $21 \mathrm{~h}=2.250 \mathrm{~V}$ <br> $22 \mathrm{~h}=2.300 \mathrm{~V}$ <br> $23 \mathrm{~h}=2.350 \mathrm{~V}$ <br> $24 \mathrm{~h}=2.400 \mathrm{~V}$ <br> $25 \mathrm{~h}=2.450 \mathrm{~V}$ <br> $26 \mathrm{~h}=2.500 \mathrm{~V}$ <br> $27 \mathrm{~h}=2.550 \mathrm{~V}$ <br> $28 \mathrm{~h}=2.600 \mathrm{~V}$ <br> $29 \mathrm{~h}=2.650 \mathrm{~V}$ <br> $2 \mathrm{Ah}=2.700 \mathrm{~V}$ <br> $2 \mathrm{Bh}=2.750 \mathrm{~V}$ <br> $2 \mathrm{Ch}=2.800 \mathrm{~V}$ <br> $2 \mathrm{Dh}=2.850 \mathrm{~V}$ <br> $2 \mathrm{Eh}=2.900 \mathrm{~V}$ <br> $2 \mathrm{Fh}=2.950 \mathrm{~V}$ <br> $30 \mathrm{~h}=3.000 \mathrm{~V}$ <br> $31 \mathrm{~h}=3.050 \mathrm{~V}$ <br> $32 \mathrm{~h}=3.100 \mathrm{~V}$ <br> $33 \mathrm{~h}=3.150 \mathrm{~V}$ <br> $34 \mathrm{~h}=3.200 \mathrm{~V}$ <br> $35 \mathrm{~h}=3.250 \mathrm{~V}$ <br> $36 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $37 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $38 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $39 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Ah}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Bh}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Ch}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Dh}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Eh}=3.300 \mathrm{~V}$ |

Table 7-13. LDO4_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
|  |  |  |  | 3 Fh $=3.300 \mathrm{~V}$ |

### 7.6.6 LDO3_VOUT Register (Offset = 5h) [Reset = X]

LDO3_VOUT is shown in Figure 7-17 and described in Table 7-14.
Return to the Summary Table.
Figure 7-17. LDO3_VOUT Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-14. LDO3_VOUT Register Field Descriptions
$\left.\begin{array}{|c|l|l|l|l|}\hline \text { Bit } & \text { Field } & \text { Type } & \text { Reset } & \text { Description } \\ \hline 7 & \text { LDO3_SLOW_PU_RAMP } & \text { R/W } & \text { X } & \begin{array}{l}\text { LDO3 Power-up ramp When set high, slows down the power-up } \\ \text { ramp to } \sim \text { 3ms. Cout max 30uF When set low, ramp time is } \sim 660 \text { us. } \\ \text { Cout max 15uF (Default from NVM memory) }\end{array} \\ \text { 0h = Fast ramp for power-up ( } \sim 660 \mathrm{us} \text { ) } \\ \text { 1h = Slow ramp for power-up ( } \sim \text { 3ms) }\end{array}\right)$

Table 7-14. LDO3_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 5-0 | LDO3_VSET | R/W | X | Voltage selection for LDO3. The output voltage range is from 1.2 V to 3.3V. (Default from NVM memory) <br> $0 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $1 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $2 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $3 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $4 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $5 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $6 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $7 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $8 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $9 \mathrm{~h}=1.200 \mathrm{~V}$ <br> $\mathrm{Ah}=1.200 \mathrm{~V}$ <br> $\mathrm{Bh}=1.200 \mathrm{~V}$ <br> $\mathrm{Ch}=1.200 \mathrm{~V}$ <br> $\mathrm{Dh}=1.250 \mathrm{~V}$ <br> $\mathrm{Eh}=1.300 \mathrm{~V}$ <br> $\mathrm{Fh}=1.350 \mathrm{~V}$ <br> $10 \mathrm{~h}=1.400 \mathrm{~V}$ <br> $11 \mathrm{~h}=1.450 \mathrm{~V}$ <br> $12 \mathrm{~h}=1.500 \mathrm{~V}$ <br> $13 \mathrm{~h}=1.550 \mathrm{~V}$ <br> $14 \mathrm{~h}=1.600 \mathrm{~V}$ <br> $15 \mathrm{~h}=1.650 \mathrm{~V}$ <br> $16 \mathrm{~h}=1.700 \mathrm{~V}$ <br> $17 \mathrm{~h}=1.750 \mathrm{~V}$ <br> $18 \mathrm{~h}=1.800 \mathrm{~V}$ <br> $19 \mathrm{~h}=1.850 \mathrm{~V}$ <br> $1 \mathrm{Ah}=1.900 \mathrm{~V}$ <br> $1 \mathrm{Bh}=1.950 \mathrm{~V}$ <br> $1 \mathrm{Ch}=2.000 \mathrm{~V}$ <br> $1 \mathrm{Dh}=2.050 \mathrm{~V}$ <br> $1 \mathrm{Eh}=2.100 \mathrm{~V}$ <br> $1 \mathrm{Fh}=2.150 \mathrm{~V}$ <br> $20 \mathrm{~h}=2.200 \mathrm{~V}$ <br> $21 \mathrm{~h}=2.250 \mathrm{~V}$ <br> $22 \mathrm{~h}=2.300 \mathrm{~V}$ <br> $23 \mathrm{~h}=2.350 \mathrm{~V}$ <br> $24 \mathrm{~h}=2.400 \mathrm{~V}$ <br> $25 \mathrm{~h}=2.450 \mathrm{~V}$ <br> $26 \mathrm{~h}=2.500 \mathrm{~V}$ <br> $27 \mathrm{~h}=2.550 \mathrm{~V}$ <br> $28 \mathrm{~h}=2.600 \mathrm{~V}$ <br> $29 \mathrm{~h}=2.650 \mathrm{~V}$ <br> $2 \mathrm{Ah}=2.700 \mathrm{~V}$ <br> $2 \mathrm{Bh}=2.750 \mathrm{~V}$ <br> $2 \mathrm{Ch}=2.800 \mathrm{~V}$ <br> $2 \mathrm{Dh}=2.850 \mathrm{~V}$ <br> $2 \mathrm{Eh}=2.900 \mathrm{~V}$ <br> $2 \mathrm{Fh}=2.950 \mathrm{~V}$ <br> $30 \mathrm{~h}=3.000 \mathrm{~V}$ <br> $31 \mathrm{~h}=3.050 \mathrm{~V}$ <br> $32 \mathrm{~h}=3.100 \mathrm{~V}$ <br> $33 \mathrm{~h}=3.150 \mathrm{~V}$ <br> $34 \mathrm{~h}=3.200 \mathrm{~V}$ <br> $35 \mathrm{~h}=3.250 \mathrm{~V}$ <br> $36 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $37 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $38 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $39 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Ah}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Bh}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Ch}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Dh}=3.300 \mathrm{~V}$ <br> $3 \mathrm{Eh}=3.300 \mathrm{~V}$ |

Table 7-14. LDO3_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
|  |  |  |  | 3 Fh $=3.300 \mathrm{~V}$ |

### 7.6.7 LDO2_VOUT Register (Offset $=\mathbf{6 h}$ ) [Reset = X]

LDO2_VOUT is shown in Figure 7-18 and described in Table 7-15.
Return to the Summary Table.
Figure 7-18. LDO2_VOUT Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-15. LDO2_VOUT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | LDO2_LSW_CONFIG | R/W | X | LDO2 LDO/Bypass or LSW Mode. NOTE: ONLY CHANGE WHILE <br> RAIL IS DISABLED! (Default from NVM memory) <br> 0h = Not Applicable (LDO2 not configured as load-switch) <br> 1h = LDO1 configured as Load-switch |
| 6 | LDO2_BYP_CONFIG | R/W | X | LDO2 LDO or Bypass Mode. (Default from NVM memory) <br> Oh = LDO2 configured as LDO (only applicable if <br> LDO2_LSW_CONFIG 0x0) <br> 1h = LDO2 configured as Bypass (only applicable if <br> LDO2_LSW_CONFIG 0x0) |

Table 7-15. LDO2_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 5-0 | LDO2_VSET | R/W | X | Voltage selection for LDO2. The output voltage range is from 0.6 V to 3.4 V in LDO mode and 1.5 V to 3.4 V in bypass-mode. (Default from NVM memory) $\mathrm{Oh}=0.600 \mathrm{~V}$ $1 \mathrm{~h}=0.650 \mathrm{~V}$ $2 \mathrm{~h}=0.700 \mathrm{~V}$ $3 \mathrm{~h}=0.750 \mathrm{~V}$ $4 \mathrm{~h}=0.800 \mathrm{~V}$ $5 \mathrm{~h}=0.850 \mathrm{~V}$ $6 \mathrm{~h}=0.900 \mathrm{~V}$ $7 \mathrm{~h}=0.950 \mathrm{~V}$ $8 \mathrm{~h}=1.000 \mathrm{~V}$ $9 \mathrm{~h}=1.050 \mathrm{~V}$ $\mathrm{Ah}=1.100 \mathrm{~V}$ $\mathrm{Bh}=1.150 \mathrm{~V}$ $\mathrm{Ch}=1.200 \mathrm{~V}$ $\mathrm{Dh}=1.250 \mathrm{~V}$ $\mathrm{Eh}=1.300 \mathrm{~V}$ $\mathrm{Fh}=1.350 \mathrm{~V}$ $10 \mathrm{~h}=1.400 \mathrm{~V}$ $11 \mathrm{~h}=1.450 \mathrm{~V}$ $12 \mathrm{~h}=1.500 \mathrm{~V}$ $13 \mathrm{~h}=1.550 \mathrm{~V}$ $14 \mathrm{~h}=1.600 \mathrm{~V}$ $15 \mathrm{~h}=1.650 \mathrm{~V}$ $16 \mathrm{~h}=1.700 \mathrm{~V}$ $17 \mathrm{~h}=1.750 \mathrm{~V}$ $18 \mathrm{~h}=1.800 \mathrm{~V}$ $19 \mathrm{~h}=1.850 \mathrm{~V}$ $1 \mathrm{Ah}=1.900 \mathrm{~V}$ $1 \mathrm{Bh}=1.950 \mathrm{~V}$ $1 \mathrm{Ch}=2.000 \mathrm{~V}$ $1 \mathrm{Dh}=2.050 \mathrm{~V}$ $1 \mathrm{Eh}=2.100 \mathrm{~V}$ $1 F h=2.150 \mathrm{~V}$ $20 \mathrm{~h}=2.200 \mathrm{~V}$ $21 \mathrm{~h}=2.250 \mathrm{~V}$ $22 \mathrm{~h}=2.300 \mathrm{~V}$ $23 \mathrm{~h}=2.350 \mathrm{~V}$ $24 \mathrm{~h}=2.400 \mathrm{~V}$ $25 \mathrm{~h}=2.450 \mathrm{~V}$ $26 \mathrm{~h}=2.500 \mathrm{~V}$ $27 \mathrm{~h}=2.550 \mathrm{~V}$ $28 \mathrm{~h}=2.600 \mathrm{~V}$ $29 \mathrm{~h}=2.650 \mathrm{~V}$ $2 \mathrm{Ah}=2.700 \mathrm{~V}$ $2 \mathrm{Bh}=2.750 \mathrm{~V}$ $2 \mathrm{Ch}=2.800 \mathrm{~V}$ $2 \mathrm{Dh}=2.850 \mathrm{~V}$ $2 \mathrm{Eh}=2.900 \mathrm{~V}$ $2 \mathrm{Fh}=2.950 \mathrm{~V}$ $30 \mathrm{~h}=3.000 \mathrm{~V}$ $31 \mathrm{~h}=3.050 \mathrm{~V}$ $32 \mathrm{~h}=3.100 \mathrm{~V}$ $33 \mathrm{~h}=3.150 \mathrm{~V}$ $34 \mathrm{~h}=3.200 \mathrm{~V}$ $35 \mathrm{~h}=3.250 \mathrm{~V}$ $36 \mathrm{~h}=3.300 \mathrm{~V}$ $37 \mathrm{~h}=3.350 \mathrm{~V}$ $38 \mathrm{~h}=3.400 \mathrm{~V}$ $39 \mathrm{~h}=3.400 \mathrm{~V}$ $3 \mathrm{Ah}=3.400 \mathrm{~V}$ $3 B h=3.400 V$ $3 \mathrm{Ch}=3.400 \mathrm{~V}$ $3 \mathrm{Dh}=3.400 \mathrm{~V}$ $3 \mathrm{Eh}=3.400 \mathrm{~V}$ |

Table 7-15. LDO2_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
|  |  |  |  | $3 \mathrm{Fh}=3.400 \mathrm{~V}$ |

### 7.6.8 LDO1_VOUT Register (Offset = 7h) [Reset = X]

LDO1_VOUT is shown in Figure 7-19 and described in Table 7-16.
Return to the Summary Table.
Figure 7-19. LDO1_VOUT Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-16. LDO1_VOUT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | LDO1_LSW_CONFIG | R/W | X | LDO1 LDO/Bypass or LSW Mode. NOTE: ONLY CHANGE WHILE <br> RAIL IS DISABLED! (Default from NVM memory) <br> 0h = Not Applicable (LDO1 not configured as load-switch) <br> 1h = LDO1 configured as Load-switch |
| 6 | LDO1_BYP_CONFIG | R/W | X | LDO1 LDO or Bypass Mode. (Default from NVM memory) <br> 0h = LDO1 configured as LDO (only applicable if <br> LDO1_LSW_CONFIG 0x0) <br> 1h = LDO1 configured as Bypass (only applicable if <br> LDO1_LSW_CONFIG 0x0) |

Table 7-16. LDO1_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 5-0 | LDO1_VSET | R/W | X | Voltage selection for LDO1. The output voltage range is from 0.6 V to 3.4 V in LDO-mode and 1.5 V to 3.4 V in bypass-mode. (Default from NVM memory) $0 \mathrm{~h}=0.600 \mathrm{~V}$ <br> $1 \mathrm{~h}=0.650 \mathrm{~V}$ <br> $2 \mathrm{~h}=0.700 \mathrm{~V}$ <br> $3 \mathrm{~h}=0.750 \mathrm{~V}$ <br> $4 \mathrm{~h}=0.800 \mathrm{~V}$ <br> $5 \mathrm{~h}=0.850 \mathrm{~V}$ <br> $6 \mathrm{~h}=0.900 \mathrm{~V}$ <br> $7 \mathrm{~h}=0.950 \mathrm{~V}$ <br> $8 \mathrm{~h}=1.000 \mathrm{~V}$ <br> $9 \mathrm{~h}=1.050 \mathrm{~V}$ <br> $\mathrm{Ah}=1.100 \mathrm{~V}$ <br> $\mathrm{Bh}=1.150 \mathrm{~V}$ <br> $\mathrm{Ch}=1.200 \mathrm{~V}$ <br> Dh $=1.250 \mathrm{~V}$ <br> $\mathrm{Eh}=1.300 \mathrm{~V}$ <br> $\mathrm{Fh}=1.350 \mathrm{~V}$ <br> $10 \mathrm{~h}=1.400 \mathrm{~V}$ <br> $11 \mathrm{~h}=1.450 \mathrm{~V}$ <br> $12 \mathrm{~h}=1.500 \mathrm{~V}$ <br> $13 \mathrm{~h}=1.550 \mathrm{~V}$ <br> $14 \mathrm{~h}=1.600 \mathrm{~V}$ <br> $15 \mathrm{~h}=1.650 \mathrm{~V}$ <br> $16 \mathrm{~h}=1.700 \mathrm{~V}$ <br> $17 \mathrm{~h}=1.750 \mathrm{~V}$ <br> $18 \mathrm{~h}=1.800 \mathrm{~V}$ <br> $19 \mathrm{~h}=1.850 \mathrm{~V}$ <br> $1 \mathrm{Ah}=1.900 \mathrm{~V}$ <br> $1 \mathrm{Bh}=1.950 \mathrm{~V}$ <br> $1 \mathrm{Ch}=2.000 \mathrm{~V}$ <br> $1 \mathrm{Dh}=2.050 \mathrm{~V}$ <br> $1 \mathrm{Eh}=2.100 \mathrm{~V}$ <br> $1 \mathrm{Fh}=2.150 \mathrm{~V}$ <br> $20 \mathrm{~h}=2.200 \mathrm{~V}$ <br> $21 \mathrm{~h}=2.250 \mathrm{~V}$ <br> $22 \mathrm{~h}=2.300 \mathrm{~V}$ <br> $23 \mathrm{~h}=2.350 \mathrm{~V}$ <br> $24 \mathrm{~h}=2.400 \mathrm{~V}$ <br> $25 \mathrm{~h}=2.450 \mathrm{~V}$ <br> $26 \mathrm{~h}=2.500 \mathrm{~V}$ <br> $27 \mathrm{~h}=2.550 \mathrm{~V}$ <br> $28 \mathrm{~h}=2.600 \mathrm{~V}$ <br> $29 \mathrm{~h}=2.650 \mathrm{~V}$ <br> $2 \mathrm{Ah}=2.700 \mathrm{~V}$ <br> $2 \mathrm{Bh}=2.750 \mathrm{~V}$ <br> $2 \mathrm{Ch}=2.800 \mathrm{~V}$ <br> $2 \mathrm{Dh}=2.850 \mathrm{~V}$ <br> $2 \mathrm{Eh}=2.900 \mathrm{~V}$ <br> $2 \mathrm{Fh}=2.950 \mathrm{~V}$ <br> $30 \mathrm{~h}=3.000 \mathrm{~V}$ <br> $31 \mathrm{~h}=3.050 \mathrm{~V}$ <br> $32 \mathrm{~h}=3.100 \mathrm{~V}$ <br> $33 \mathrm{~h}=3.150 \mathrm{~V}$ <br> $34 \mathrm{~h}=3.200 \mathrm{~V}$ <br> $35 \mathrm{~h}=3.250 \mathrm{~V}$ <br> $36 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $37 \mathrm{~h}=3.350 \mathrm{~V}$ <br> $38 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $39 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Ah}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Bh}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Ch}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Dh}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Eh}=3.400 \mathrm{~V}$ |

Table 7-16. LDO1_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
|  |  |  |  | 3 Fh $=3.400 \mathrm{~V}$ |

### 7.6.9 BUCK3_VOUT Register (Offset = 8h) [Reset = X]

BUCK3_VOUT is shown in Figure 7-20 and described in Table 7-17.
Return to the Summary Table.
Figure 7-20. BUCK3_VOUT Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BUCK3_BW_S <br> EL | BUCK3_UV_TH <br> R_SEL |  | BUCK3_VSET |  |  |  |
| R/W-X | R/W-X |  | R/W-X |  |  |  |

Table 7-17. BUCK3_VOUT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | BUCK3_BW_SEL | R/W | X | BUCK3 Bandwidth selection. NOTE: ONLY CHANGE WHILE RAIL <br> IS DISABLED! (Default from NVM memory) <br> Oh = low bandwidth <br> 1h = high bandwidth |
| 6 | BUCK3_UV_THR_SEL | R/W | X | UV threshold selection for BUCK3. (Default from NVM memory) <br> Oh = -5\% UV detection <br> 1h $=-10 \%$ UV detection |

Table 7-17. BUCK3_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 5-0 | BUCK3_VSET | R/W | X | Voltage selection for BUCK3. The output voltage range is from 0.6 V to 3.4 V . (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0.600 \mathrm{~V} \\ & 1 \mathrm{~h}=0.625 \mathrm{~V} \end{aligned}$ <br> $2 \mathrm{~h}=0.650 \mathrm{~V}$ <br> $3 \mathrm{~h}=0.675 \mathrm{~V}$ <br> $4 \mathrm{~h}=0.700 \mathrm{~V}$ <br> $5 \mathrm{~h}=0.725 \mathrm{~V}$ <br> $6 \mathrm{~h}=0.750 \mathrm{~V}$ <br> $7 \mathrm{~h}=0.775 \mathrm{~V}$ <br> $8 \mathrm{~h}=0.800 \mathrm{~V}$ <br> $9 \mathrm{~h}=0.825 \mathrm{~V}$ <br> $\mathrm{Ah}=0.850 \mathrm{~V}$ $\mathrm{Bh}=0.875 \mathrm{~V}$ $\mathrm{Ch}=0.900 \mathrm{~V}$ $\mathrm{Dh}=0.925 \mathrm{~V}$ $\mathrm{Eh}=0.950 \mathrm{~V}$ $\mathrm{Fh}=0.975 \mathrm{~V}$ $10 \mathrm{~h}=1.000 \mathrm{~V}$ $11 \mathrm{~h}=1.025 \mathrm{~V}$ $12 \mathrm{~h}=1.050 \mathrm{~V}$ $13 \mathrm{~h}=1.075 \mathrm{~V}$ $14 \mathrm{~h}=1.100 \mathrm{~V}$ $15 \mathrm{~h}=1.125 \mathrm{~V}$ $16 \mathrm{~h}=1.150 \mathrm{~V}$ $17 \mathrm{~h}=1.175 \mathrm{~V}$ $18 \mathrm{~h}=1.200 \mathrm{~V}$ $19 \mathrm{~h}=1.225 \mathrm{~V}$ $1 \mathrm{Ah}=1.250 \mathrm{~V}$ $1 \mathrm{Bh}=1.275 \mathrm{~V}$ $1 \mathrm{Ch}=1.300 \mathrm{~V}$ $1 \mathrm{Dh}=1.325 \mathrm{~V}$ $1 \mathrm{Eh}=1.350 \mathrm{~V}$ $1 \mathrm{Fh}=1.375 \mathrm{~V}$ $20 \mathrm{~h}=1.400 \mathrm{~V}$ $21 \mathrm{~h}=1.500 \mathrm{~V}$ $22 \mathrm{~h}=1.600 \mathrm{~V}$ $23 \mathrm{~h}=1.700 \mathrm{~V}$ $24 \mathrm{~h}=1.800 \mathrm{~V}$ $25 \mathrm{~h}=1.900 \mathrm{~V}$ $26 \mathrm{~h}=2.000 \mathrm{~V}$ $27 \mathrm{~h}=2.100 \mathrm{~V}$ $28 \mathrm{~h}=2.200 \mathrm{~V}$ $29 \mathrm{~h}=2.300 \mathrm{~V}$ $2 \mathrm{Ah}=2.400 \mathrm{~V}$ $2 \mathrm{Bh}=2.500 \mathrm{~V}$ $2 \mathrm{Ch}=2.600 \mathrm{~V}$ $2 \mathrm{Dh}=2.700 \mathrm{~V}$ $2 \mathrm{Eh}=2.800 \mathrm{~V}$ $2 \mathrm{Fh}=2.900 \mathrm{~V}$ $30 \mathrm{~h}=3.000 \mathrm{~V}$ $31 \mathrm{~h}=3.100 \mathrm{~V}$ $32 \mathrm{~h}=3.200 \mathrm{~V}$ $33 \mathrm{~h}=3.300 \mathrm{~V}$ $34 \mathrm{~h}=3.400 \mathrm{~V}$ $35 \mathrm{~h}=3.400 \mathrm{~V}$ $36 \mathrm{~h}=3.400 \mathrm{~V}$ $37 \mathrm{~h}=3.400 \mathrm{~V}$ $38 \mathrm{~h}=3.400 \mathrm{~V}$ $39 \mathrm{~h}=3.400 \mathrm{~V}$ $3 \mathrm{Ah}=3.400 \mathrm{~V}$ $3 \mathrm{Bh}=3.400 \mathrm{~V}$ $3 \mathrm{Ch}=3.400 \mathrm{~V}$ $3 \mathrm{Dh}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Eh}=3.400 \mathrm{~V}$ |

Table 7-17. BUCK3_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
|  |  |  |  | $3 \mathrm{Fh}=3.400 \mathrm{~V}$ |

### 7.6.10 BUCK2_VOUT Register (Offset = 9h) [Reset = X]

BUCK2_VOUT is shown in Figure 7-21 and described in Table 7-18.
Return to the Summary Table.
Figure 7-21. BUCK2_VOUT Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-18. BUCK2_VOUT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | BUCK2_BW_SEL | R/W | X | BUCK2 Bandwidth selection. NOTE: ONLY CHANGE WHILE RAIL <br> IS DISABLED! (Default from NVM memory) <br> Oh = low bandwidth <br> 1h = high bandwidth |
| 6 | BUCK2_UV_THR_SEL | R/W | X | UV threshold selection for BUCK2. (Default from NVM memory) <br> Oh = -5\% UV detection <br> 1h $=-10 \%$ UV detection |

Table 7-18. BUCK2_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 5-0 | BUCK2_VSET | R/W | X | Voltage selection for BUCK2. The output voltage range is from 0.6 V to 3.4 V . (Default from NVM memory) $\mathrm{Oh}=0.600 \mathrm{~V}$ $1 \mathrm{~h}=0.625 \mathrm{~V}$ $2 \mathrm{~h}=0.650 \mathrm{~V}$ $3 \mathrm{~h}=0.675 \mathrm{~V}$ $4 \mathrm{~h}=0.700 \mathrm{~V}$ $5 \mathrm{~h}=0.725 \mathrm{~V}$ $6 \mathrm{~h}=0.750 \mathrm{~V}$ $7 \mathrm{~h}=0.775 \mathrm{~V}$ $8 \mathrm{~h}=0.800 \mathrm{~V}$ $9 \mathrm{~h}=0.825 \mathrm{~V}$ $\mathrm{Ah}=0.850 \mathrm{~V}$ $\mathrm{Bh}=0.875 \mathrm{~V}$ $\mathrm{Ch}=0.900 \mathrm{~V}$ $\mathrm{Dh}=0.925 \mathrm{~V}$ $\mathrm{Eh}=0.950 \mathrm{~V}$ $\mathrm{Fh}=0.975 \mathrm{~V}$ $10 \mathrm{~h}=1.000 \mathrm{~V}$ $11 \mathrm{~h}=1.025 \mathrm{~V}$ $12 \mathrm{~h}=1.050 \mathrm{~V}$ $13 \mathrm{~h}=1.075 \mathrm{~V}$ $14 \mathrm{~h}=1.100 \mathrm{~V}$ $15 \mathrm{~h}=1.125 \mathrm{~V}$ $16 \mathrm{~h}=1.150 \mathrm{~V}$ $17 \mathrm{~h}=1.175 \mathrm{~V}$ $18 \mathrm{~h}=1.200 \mathrm{~V}$ $19 \mathrm{~h}=1.225 \mathrm{~V}$ <br> $1 \mathrm{Ah}=1.250 \mathrm{~V}$ <br> $1 \mathrm{Bh}=1.275 \mathrm{~V}$ <br> $1 \mathrm{Ch}=1.300 \mathrm{~V}$ <br> $1 \mathrm{Dh}=1.325 \mathrm{~V}$ <br> $1 \mathrm{Eh}=1.350 \mathrm{~V}$ <br> $1 \mathrm{Fh}=1.375 \mathrm{~V}$ <br> $20 \mathrm{~h}=1.400 \mathrm{~V}$ <br> $21 \mathrm{~h}=1.500 \mathrm{~V}$ <br> $22 \mathrm{~h}=1.600 \mathrm{~V}$ <br> $23 \mathrm{~h}=1.700 \mathrm{~V}$ <br> $24 \mathrm{~h}=1.800 \mathrm{~V}$ <br> $25 \mathrm{~h}=1.900 \mathrm{~V}$ <br> $26 \mathrm{~h}=2.000 \mathrm{~V}$ <br> $27 \mathrm{~h}=2.100 \mathrm{~V}$ <br> $28 \mathrm{~h}=2.200 \mathrm{~V}$ <br> $29 \mathrm{~h}=2.300 \mathrm{~V}$ <br> $2 \mathrm{Ah}=2.400 \mathrm{~V}$ <br> $2 \mathrm{Bh}=2.500 \mathrm{~V}$ <br> $2 \mathrm{Ch}=2.600 \mathrm{~V}$ <br> $2 \mathrm{Dh}=2.700 \mathrm{~V}$ <br> $2 \mathrm{Eh}=2.800 \mathrm{~V}$ <br> $2 \mathrm{Fh}=2.900 \mathrm{~V}$ <br> $30 \mathrm{~h}=3.000 \mathrm{~V}$ <br> $31 \mathrm{~h}=3.100 \mathrm{~V}$ <br> $32 \mathrm{~h}=3.200 \mathrm{~V}$ <br> $33 \mathrm{~h}=3.300 \mathrm{~V}$ <br> $34 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $35 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $36 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $37 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $38 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $39 \mathrm{~h}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Ah}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Bh}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Ch}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Dh}=3.400 \mathrm{~V}$ <br> $3 \mathrm{Eh}=3.400 \mathrm{~V}$ |

Table 7-18. BUCK2_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
|  |  |  |  | $3 F \mathrm{~F}=3.400 \mathrm{~V}$ |

### 7.6.11 BUCK1_VOUT Register (Offset $=\mathbf{A h}$ ) [Reset $=\mathbf{X}]$

BUCK1_VOUT is shown in Figure 7-22 and described in Table 7-19.
Return to the Summary Table.
Figure 7-22. BUCK1_VOUT Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-19. BUCK1_VOUT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | BUCK1_BW_SEL | R/W | X | BUCK1 Bandwidth selection. NOTE: ONLY CHANGE WHILE RAIL <br> IS DISABLED! (Default from NVM memory) <br> Oh = low bandwidth <br> 1h = high bandwidth |
| 6 | BUCK1_UV_THR_SEL | R/W | X | UV threshold selection for BUCK1. (Default from NVM memory) <br> Oh = -5\% UV detection <br> 1h $=-10 \%$ UV detection |

Table 7-19. BUCK1_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 5-0 | BUCK1_VSET | R/W | X | Voltage selection for BUCK1. The output voltage range is from 0.6 V to 3.4V. (Default from NVM memory) $\mathrm{Oh}=0.600 \mathrm{~V}$ $1 \mathrm{~h}=0.625 \mathrm{~V}$ $2 \mathrm{~h}=0.650 \mathrm{~V}$ $3 \mathrm{~h}=0.675 \mathrm{~V}$ $4 \mathrm{~h}=0.700 \mathrm{~V}$ $5 \mathrm{~h}=0.725 \mathrm{~V}$ $6 \mathrm{~h}=0.750 \mathrm{~V}$ $7 \mathrm{~h}=0.775 \mathrm{~V}$ $8 \mathrm{~h}=0.800 \mathrm{~V}$ $9 \mathrm{~h}=0.825 \mathrm{~V}$ $\mathrm{Ah}=0.850 \mathrm{~V}$ $\mathrm{Bh}=0.875 \mathrm{~V}$ $\mathrm{Ch}=0.900 \mathrm{~V}$ $\mathrm{Dh}=0.925 \mathrm{~V}$ $\mathrm{Eh}=0.950 \mathrm{~V}$ $\mathrm{Fh}=0.975 \mathrm{~V}$ $10 \mathrm{~h}=1.000 \mathrm{~V}$ $11 \mathrm{~h}=1.025 \mathrm{~V}$ $12 \mathrm{~h}=1.050 \mathrm{~V}$ $13 \mathrm{~h}=1.075 \mathrm{~V}$ $14 \mathrm{~h}=1.100 \mathrm{~V}$ $15 \mathrm{~h}=1.125 \mathrm{~V}$ $16 \mathrm{~h}=1.150 \mathrm{~V}$ $17 \mathrm{~h}=1.175 \mathrm{~V}$ $18 \mathrm{~h}=1.200 \mathrm{~V}$ $19 \mathrm{~h}=1.225 \mathrm{~V}$ $1 \mathrm{Ah}=1.250 \mathrm{~V}$ $1 \mathrm{Bh}=1.275 \mathrm{~V}$ $1 \mathrm{Ch}=1.300 \mathrm{~V}$ $1 \mathrm{Dh}=1.325 \mathrm{~V}$ $1 \mathrm{Eh}=1.350 \mathrm{~V}$ $1 \mathrm{Fh}=1.375 \mathrm{~V}$ $20 \mathrm{~h}=1.400 \mathrm{~V}$ $21 \mathrm{~h}=1.500 \mathrm{~V}$ $22 \mathrm{~h}=1.600 \mathrm{~V}$ $23 \mathrm{~h}=1.700 \mathrm{~V}$ $24 \mathrm{~h}=1.800 \mathrm{~V}$ $25 \mathrm{~h}=1.900 \mathrm{~V}$ $26 \mathrm{~h}=2.000 \mathrm{~V}$ $27 \mathrm{~h}=2.100 \mathrm{~V}$ $28 \mathrm{~h}=2.200 \mathrm{~V}$ $29 \mathrm{~h}=2.300 \mathrm{~V}$ $2 \mathrm{Ah}=2.400 \mathrm{~V}$ $2 \mathrm{Bh}=2.500 \mathrm{~V}$ $2 \mathrm{Ch}=2.600 \mathrm{~V}$ $2 \mathrm{Dh}=2.700 \mathrm{~V}$ $2 \mathrm{Eh}=2.800 \mathrm{~V}$ $2 \mathrm{Fh}=2.900 \mathrm{~V}$ $30 \mathrm{~h}=3.000 \mathrm{~V}$ $31 \mathrm{~h}=3.100 \mathrm{~V}$ $32 \mathrm{~h}=3.200 \mathrm{~V}$ $33 \mathrm{~h}=3.300 \mathrm{~V}$ $34 \mathrm{~h}=3.400 \mathrm{~V}$ $35 \mathrm{~h}=3.400 \mathrm{~V}$ $36 \mathrm{~h}=3.400 \mathrm{~V}$ $37 \mathrm{~h}=3.400 \mathrm{~V}$ $38 \mathrm{~h}=3.400 \mathrm{~V}$ $39 \mathrm{~h}=3.400 \mathrm{~V}$ $3 \mathrm{Ah}=3.400 \mathrm{~V}$ $3 \mathrm{Bh}=3.400 \mathrm{~V}$ $3 \mathrm{Ch}=3.400 \mathrm{~V}$ $\begin{aligned} & 3 \mathrm{Dh}=3.400 \mathrm{~V} \end{aligned}$ $3 \mathrm{Eh}=3.400 \mathrm{~V}$ |

Table 7-19. BUCK1_VOUT Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
|  |  |  |  | $3 \mathrm{Fh}=3.400 \mathrm{~V}$ |

### 7.6.12 LDO4_SEQUENCE_SLOT Register (Offset = Bh) [Reset = X]

LDO4_SEQUENCE_SLOT is shown in Figure 7-23 and described in Table 7-20.
Return to the Summary Table.
Figure 7-23. LDO4_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| LDO4_SEQUENCE_ON_SLOT |  | LDO4_SEQUENCE_OFF_SLOT |  |  |  |
| R/W-X | R/W-X |  |  |  |  |

Table 7-20. LDO4_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | LDO4_SEQUENCE_ON_ SLOT | R/W | X | LDO4 slot number for power-up (Default from NVM memory) $\text { Oh = slot } 0$ <br> $1 \mathrm{~h}=$ slot 1 <br> $2 \mathrm{~h}=$ slot 2 <br> $3 \mathrm{~h}=$ slot 3 <br> $4 \mathrm{~h}=$ slot 4 <br> $5 h=$ slot 5 <br> $6 \mathrm{~h}=$ slot 6 <br> $7 \mathrm{~h}=$ slot 7 <br> $8 \mathrm{~h}=$ slot 8 <br> $9 \mathrm{~h}=$ slot 9 <br> Ah = slot 10 <br> $\mathrm{Bh}=$ slot 11 <br> Ch $=$ slot 12 <br> Dh $=$ slot 13 <br> Eh $=$ slot 14 <br> Fh $=$ slot 15 |
| 3-0 | LDO4_SEQUENCE_OFF_ SLOT | R/W | X | $\begin{aligned} & \text { LDO4 slot number for power-down (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\operatorname{slot} 4 \\ & 5 \mathrm{~h}=\operatorname{slot} 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\operatorname{slot} 8 \\ & 9 \mathrm{~h}=\operatorname{slot} 9 \\ & \text { Ah = slot } 10 \\ & \text { Bh = slot } 11 \\ & \text { Ch = slot } 12 \\ & \text { Dh }=\text { slot } 13 \\ & \text { Eh }=\text { slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |

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### 7.6.13 LDO3_SEQUENCE_SLOT Register (Offset = Ch) [Reset = X]

LDO3_SEQUENCE_SLOT is shown in Figure 7-24 and described in Table 7-21.
Return to the Summary Table.
Figure 7-24. LDO3_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| LDO3_SEQUENCE_ON_SLOT |  | LDO3_SEQUENCE_OFF_SLOT |  |  |  |
| R/W-X | R/W-X |  |  |  |  |

Table 7-21. LDO3_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | $\begin{aligned} & \text { LDO3_SEQUENCE_ON_ } \\ & \text { SLOT } \end{aligned}$ | R/W | X | $\begin{aligned} & \text { LDO3 slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\text { slot } 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \mathrm{Bh}=\text { slot } 11 \\ & \text { Ch = slot } 12 \\ & \text { Dh = slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh = slot } 15 \end{aligned}$ |
| 3-0 | LDO3_SEQUENCE_OFF_ SLOT | R/W | X | $\begin{aligned} & \text { LDO3 slot number for power-down (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\operatorname{slot} 3 \\ & 4 \mathrm{~h}=\operatorname{slot} 4 \\ & 5 \mathrm{~h}=\operatorname{slot} 5 \\ & 6 \mathrm{~h}=\operatorname{slot} 6 \\ & 7 \mathrm{~h}=\operatorname{slot} 7 \\ & 8 \mathrm{~h}=\operatorname{slot} 8 \\ & 9 \mathrm{~h}=\operatorname{slot} 9 \\ & \text { Ah = slot } 10 \\ & \text { Bh }=\text { slot } 11 \\ & \mathrm{Ch}=\text { slot } 12 \\ & \text { Dh }=\text { slot } 13 \\ & \text { Eh }=\text { slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |

### 7.6.14 LDO2_SEQUENCE_SLOT Register (Offset = Dh) [Reset = X]

LDO2_SEQUENCE_SLOT is shown in Figure 7-25 and described in Table 7-22.
Return to the Summary Table.
Figure 7-25. LDO2_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| LDO2_SEQUENCE_ON_SLOT |  | LDO2_SEQUENCE_OFF_SLOT |  |  |  |  |
| R/W-X | R/W-X |  |  |  |  |  |

Table 7-22. LDO2_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | $\begin{aligned} & \text { LDO2_SEQUENCE_ON_ } \\ & \text { SLOT } \end{aligned}$ | R/W | X | $\begin{aligned} & \text { LDO2 slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\text { slot } 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \mathrm{Bh}=\text { slot } 11 \\ & \text { Ch = slot } 12 \\ & \text { Dh = slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh = slot } 15 \end{aligned}$ |
| 3-0 | LDO2_SEQUENCE_OFF_ SLOT | R/W | X | $\begin{aligned} & \text { LDO2 slot number for power-down (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\operatorname{slot} 3 \\ & 4 \mathrm{~h}=\operatorname{slot} 4 \\ & 5 \mathrm{~h}=\operatorname{slot} 5 \\ & 6 \mathrm{~h}=\operatorname{slot} 6 \\ & 7 \mathrm{~h}=\operatorname{slot} 7 \\ & 8 \mathrm{~h}=\operatorname{slot} 8 \\ & 9 \mathrm{~h}=\operatorname{slot} 9 \\ & \text { Ah = slot } 10 \\ & \text { Bh }=\text { slot } 11 \\ & \mathrm{Ch}=\text { slot } 12 \\ & \text { Dh }=\text { slot } 13 \\ & \text { Eh }=\text { slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |

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### 7.6.15 LDO1_SEQUENCE_SLOT Register (Offset = Eh) [Reset = X]

LDO1_SEQUENCE_SLOT is shown in Figure 7-26 and described in Table 7-23.
Return to the Summary Table.
Figure 7-26. LDO1_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 4 | 3 | 2 |
| :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-23. LDO1_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | $\begin{aligned} & \text { LDO1_SEQUENCE_ON_ } \\ & \text { SLOT } \end{aligned}$ | R/W | X | $\begin{aligned} & \text { LDO1 slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\text { slot } 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \mathrm{Bh}=\text { slot } 11 \\ & \text { Ch = slot } 12 \\ & \text { Dh = slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |
| 3-0 | $\begin{aligned} & \text { LDO1_SEQUENCE_OFF_ } \\ & \text { SLOT } \end{aligned}$ | R/W | X | $\begin{aligned} & \text { LDO1 slot number for power-down (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\operatorname{slot} 3 \\ & 4 \mathrm{~h}=\operatorname{slot} 4 \\ & 5 \mathrm{~h}=\operatorname{slot} 5 \\ & 6 \mathrm{~h}=\operatorname{slot} 6 \\ & 7 \mathrm{~h}=\operatorname{slot} 7 \\ & 8 \mathrm{~h}=\operatorname{slot} 8 \\ & 9 \mathrm{~h}=\operatorname{slot} 9 \\ & \text { Ah } 9 \text { slot } 10 \\ & \text { Bh }=\text { slot } 11 \\ & \text { Ch }=\text { slot } 12 \\ & \text { Dh }=\text { slot } 13 \\ & \text { Eh }=\text { slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |

### 7.6.16 BUCK3_SEQUENCE_SLOT Register (Offset = Fh) [Reset = X]

BUCK3_SEQUENCE_SLOT is shown in Figure 7-27 and described in Table 7-24.
Return to the Summary Table.
Figure 7-27. BUCK3_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| BUCK3_SEQUENCE_ON_SLOT |  | BUCK3_SEQUENCE_OFF_SLOT |  |  |  |
| R/W-X | R/W-X |  |  |  |  |

Table 7-24. BUCK3_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | BUCK3_SEQUENCE_ON _SLOT | R/W | X | $\begin{aligned} & \text { BUCK3 slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot 0 } \\ & \text { 1h = slot } 1 \\ & 2 h \text { = slot } 2 \\ & 3 h=\text { slot } 3 \\ & 4 h=\text { slot } 4 \\ & 5 h=\text { slot } 5 \\ & 6 h=\text { slot } 6 \\ & 7 h=\text { slot } 7 \\ & 8 h=\text { slot } 8 \\ & 9 h \text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \text { Bh slot } 11 \\ & \text { Ch = slot } 12 \\ & \text { Dh = slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh = slot } 15 \end{aligned}$ |
| 3-0 | BUCK3_SEQUENCE_OF F_SLOT | R/W | X | BUCK3 slot number for power-down (Default from NVM memory) $\text { Oh = slot } 0$ <br> $1 \mathrm{~h}=$ slot 1 <br> $2 \mathrm{~h}=$ slot 2 <br> $3 \mathrm{~h}=\operatorname{slot} 3$ <br> $4 \mathrm{~h}=$ slot 4 <br> $5 \mathrm{~h}=\operatorname{slot} 5$ <br> $6 \mathrm{~h}=$ slot 6 <br> $7 \mathrm{~h}=\operatorname{slot} 7$ <br> $8 \mathrm{~h}=\operatorname{slot} 8$ <br> $9 \mathrm{~h}=\operatorname{slot} 9$ <br> $\mathrm{Ah}=$ slot 10 <br> $\mathrm{Bh}=$ slot 11 <br> $\mathrm{Ch}=\operatorname{slot} 12$ <br> Dh $=$ slot 13 <br> Eh $=$ slot 14 <br> Fh $=$ slot 15 |

### 7.6.17 BUCK2_SEQUENCE_SLOT Register (Offset $=10 \mathrm{~h}$ ) Reset $=\mathrm{X}]$

BUCK2_SEQUENCE_SLOT is shown in Figure 7-28 and described in Table 7-25.
Return to the Summary Table.
Figure 7-28. BUCK2_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BUCK2_SEQUENCE_ON_SLOT |  | BUCK2_SEQUENCE_OFF_SLOT |  |  |  |  |
| R/W-X | R/W-X |  |  |  |  |  |

Table 7-25. BUCK2_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | BUCK2_SEQUENCE_ON _SLOT | R/W | X | $\begin{aligned} & \text { BUCK2 Slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot 0 } \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { solot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\text { slot } 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \text { Bh = slot } 11 \\ & \text { Ch = slot } 12 \\ & \text { Dh = slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh = slot } 15 \end{aligned}$ |
| 3-0 | BUCK2_SEQUENCE_OF F_SLOT | R/W | X | BUCK2 slot number for power-down (Default from NVM memory) $\text { Oh = slot } 0$ <br> $1 \mathrm{~h}=$ slot 1 <br> $2 \mathrm{~h}=$ slot 2 <br> $3 \mathrm{~h}=\operatorname{slot} 3$ <br> $4 \mathrm{~h}=$ slot 4 <br> $5 \mathrm{~h}=\operatorname{slot} 5$ <br> $6 \mathrm{~h}=$ slot 6 <br> $7 \mathrm{~h}=\operatorname{slot} 7$ <br> $8 \mathrm{~h}=\operatorname{slot} 8$ <br> $9 \mathrm{~h}=\operatorname{slot} 9$ <br> $\mathrm{Ah}=$ slot 10 <br> $\mathrm{Bh}=$ slot 11 <br> $\mathrm{Ch}=\operatorname{slot} 12$ <br> Dh $=$ slot 13 <br> Eh $=$ slot 14 <br> Fh $=$ slot 15 |

### 7.6.18 BUCK1_SEQUENCE_SLOT Register (Offset = 11h) [Reset = X]

BUCK1_SEQUENCE_SLOT is shown in Figure 7-29 and described in Table 7-26.
Return to the Summary Table.
Figure 7-29. BUCK1_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BUCK1_SEQUENCE_ON_SLOT |  | BUCK1_SEQUENCE_OFF_SLOT |  |  |  |  |
| R/W-X | R/W-X |  |  |  |  |  |

Table 7-26. BUCK1_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | BUCK1_SEQUENCE_ON _SLOT | R/W | X | $\begin{aligned} & \text { BUCK1 Slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\text { slot } 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \mathrm{Bh}=\text { slot } 11 \\ & \mathrm{Ch}=\text { slot } 12 \\ & \text { Dh = slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh = slot } 15 \end{aligned}$ |
| 3-0 | BUCK1_SEQUENCE_OF F_SLOT | R/W | X | BUCK1 slot number for power-down (Default from NVM memory) <br> Oh = slot 0 <br> 1h = slot 1 <br> $2 \mathrm{~h}=$ slot 2 <br> $3 \mathrm{~h}=$ slot 3 <br> $4 \mathrm{~h}=$ slot 4 <br> $5 \mathrm{~h}=$ slot 5 <br> $6 \mathrm{~h}=$ slot 6 <br> $7 \mathrm{~h}=$ slot 7 <br> $8 \mathrm{~h}=$ slot 8 <br> $9 \mathrm{~h}=$ slot 9 <br> Ah = slot 10 <br> $\mathrm{Bh}=$ slot 11 <br> $\mathrm{Ch}=$ slot 12 <br> Dh $=$ slot 13 <br> Eh = slot 14 <br> Fh $=$ slot 15 |

### 7.6.19 nRST_SEQUENCE_SLOT Register (Offset = 12h) [Reset = X]

nRST_SEQUENCE_SLOT is shown in Figure 7-30 and described in Table 7-27.
Return to the Summary Table.
Figure 7-30. nRST_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 4 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| nRST_SEQUENCE_ON_SLOT |  | nRST_SEQUENCE_OFF_SLOT |  |  |  |
| R/W-X | R/W-X |  |  |  |  |

Table 7-27. nRST_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | nRST_SEQUENCE_ON_ SLOT | R/W | X | $\begin{aligned} & \text { nRST slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\text { slot } 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \mathrm{Bh}=\text { slot } 11 \\ & \text { Ch = slot } 12 \\ & \text { Dh = slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |
| 3-0 | $\begin{aligned} & \text { nRST_SEQUENCE_OFF_ } \\ & \text { SLOT } \end{aligned}$ | R/W | X | $\begin{aligned} & \text { nRST slot number for power-down (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\operatorname{slot} 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\operatorname{slot} 7 \\ & 8 \mathrm{~h}=\operatorname{slot} 8 \\ & 9 \mathrm{~h}=\operatorname{slot} 9 \\ & \text { Ah }=\text { slot } 10 \\ & \text { Bh }=\text { slot } 11 \\ & \text { Ch }=\text { slot } 12 \\ & \text { Dh }=\text { slot } 13 \\ & \text { Eh }=\text { slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |

### 7.6.20 GPIO_SEQUENCE_SLOT Register (Offset = 13h) [Reset = X]

GPIO_SEQUENCE_SLOT is shown in Figure 7-31 and described in Table 7-28.
Return to the Summary Table.
Figure 7-31. GPIO_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| GPIO_SEQUENCE_ON_SLOT |  | GPIO_SEQUENCE_OFF_SLOT |  |  |  |
| R/W-X | R/W-X |  |  |  |  |

Table 7-28. GPIO_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | GPIO_SEQUENCE_ON_ SLOT | R/W | X | ```GPIO slot number for power-up (Default from NVM memory) Oh = slot 0 1h = slot 1 2h = slot 2 \(3 \mathrm{~h}=\) slot 3 \(4 \mathrm{~h}=\) slot 4 \(5 \mathrm{~h}=\) slot 5 \(6 \mathrm{~h}=\) slot 6 \(7 \mathrm{~h}=\operatorname{slot} 7\) 8h = slot 8 9h = slot 9 Ah = slot 10 \(\mathrm{Bh}=\) slot 11 Ch \(=\) slot 12 Dh \(=\) slot 13 Eh = slot 14 Fh = slot 15``` |
| 3-0 | GPIO_SEQUENCE_OFF_ SLOT | R/W | X | $\begin{aligned} & \text { GPIO slot number for power-down (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\operatorname{slot} 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah }=\text { slot } 10 \\ & \text { Bh = slot } 11 \\ & \text { Ch }=\text { slot } 12 \\ & \text { Dh }=\text { slot } 13 \\ & \text { Eh }=\text { slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |

### 7.6.21 GPO2_SEQUENCE_SLOT Register (Offset = 14h) [Reset = X]

GPO2_SEQUENCE_SLOT is shown in Figure 7-32 and described in Table 7-29.
Return to the Summary Table.
Figure 7-32. GPO2_SEQUENCE_SLOT Register

| 7 | 6 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| GPO2_SEQUENCE_ON_SLOT |  | GPO2_SEQUENCE_OFF_SLOT |  |  |  |
| R/W-X | R/W-X |  |  |  |  |

Table 7-29. GPO2_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | $\begin{aligned} & \text { GPO2_SEQUENCE_ON_ } \\ & \text { SLOT } \end{aligned}$ | R/W | X | $\begin{aligned} & \text { GPO2 slot number for power-up (Default from NVM memory) } \\ & \text { Oh = slot } 0 \\ & 1 \mathrm{~h}=\text { slot } 1 \\ & 2 \mathrm{~h}=\text { slot } 2 \\ & 3 \mathrm{~h}=\text { slot } 3 \\ & 4 \mathrm{~h}=\text { slot } 4 \\ & 5 \mathrm{~h}=\text { slot } 5 \\ & 6 \mathrm{~h}=\text { slot } 6 \\ & 7 \mathrm{~h}=\text { slot } 7 \\ & 8 \mathrm{~h}=\text { slot } 8 \\ & 9 \mathrm{~h}=\text { slot } 9 \\ & \text { Ah = slot } 10 \\ & \mathrm{Bh}=\text { slot } 11 \\ & \mathrm{Ch}=\text { slot } 12 \\ & \text { Dh }=\text { slot } 13 \\ & \text { Eh = slot } 14 \\ & \text { Fh }=\text { slot } 15 \end{aligned}$ |
| 3-0 | GPO2_SEQUENCE_OFF _SLOT | R/W | X | GPO2 slot number for power-down (Default from NVM memory) <br> Oh = slot 0 <br> $1 \mathrm{~h}=$ slot 1 <br> $2 \mathrm{~h}=$ slot 2 <br> $3 \mathrm{~h}=$ slot 3 <br> 4h = slot 4 <br> $5 \mathrm{~h}=$ slot 5 <br> $6 \mathrm{~h}=$ slot 6 <br> $7 \mathrm{~h}=$ slot 7 <br> $8 \mathrm{~h}=$ slot 8 <br> $9 \mathrm{~h}=$ slot 9 <br> $\mathrm{Ah}=$ slot 10 <br> $\mathrm{Bh}=$ slot 11 <br> $\mathrm{Ch}=$ slot 12 <br> Dh = slot 13 <br> Eh = slot 14 <br> Fh = slot 15 |

### 7.6.22 GPO1_SEQUENCE_SLOT Register (Offset = 15h) [Reset = X]

GPO1_SEQUENCE_SLOT is shown in Figure 7-33 and described in Table 7-30.
Return to the Summary Table.
Figure 7-33. GPO1_SEQUENCE_SLOT Register

| 7 | 6 | 5 | 4 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| GPO1_SEQUENCE_ON_SLOT |  | GPO1_SEQUENCE_OFF_SLOT |  |  |  |  |
| R/W-X | R/W-X |  |  |  |  |  |

Table 7-30. GPO1_SEQUENCE_SLOT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-4 | $\begin{aligned} & \text { GPO1_SEQUENCE_ON_ } \\ & \text { SLOT } \end{aligned}$ | R/W | X | ```GPO1 slot number for power-up (Default from NVM memory) Oh = slot 0 \(1 \mathrm{~h}=\) slot 1 \(2 \mathrm{~h}=\) slot 2 \(3 \mathrm{~h}=\) slot 3 4h = slot 4 \(5 \mathrm{~h}=\) slot 5 \(6 \mathrm{~h}=\) slot 6 \(7 \mathrm{~h}=\) slot 7 \(8 \mathrm{~h}=\) slot 8 \(9 \mathrm{~h}=\) slot 9 \(\mathrm{Ah}=\) slot 10 \(\mathrm{Bh}=\) slot 11 \(\mathrm{Ch}=\) slot 12 Dh \(=\) slot 13 Eh = slot 14 Fh = slot 15``` |
| 3-0 | GPO1_SEQUENCE_OFF _SLOT | R/W | X | GPO1 slot number for power-down (Default from NVM memory) <br> Oh = slot 0 <br> 1h = slot 1 <br> $2 \mathrm{~h}=$ slot 2 <br> 3h = slot 3 <br> 4h = slot 4 <br> $5 \mathrm{~h}=$ slot 5 <br> $6 \mathrm{~h}=$ slot 6 <br> $7 \mathrm{~h}=$ slot 7 <br> $8 \mathrm{~h}=$ slot 8 <br> $9 \mathrm{~h}=$ slot 9 <br> $\mathrm{Ah}=$ slot 10 <br> $\mathrm{Bh}=$ slot 11 <br> $\mathrm{Ch}=$ slot 12 <br> Dh = slot 13 <br> Eh = slot 14 <br> Fh = slot 15 |

### 7.6.23 POWER_UP_SLOT_DURATION_1 Register (Offset = 16h) [Reset = X]

POWER_UP_SLOT_DURATION_1 is shown in Figure 7-34 and described in Table 7-31.
Return to the Summary Table.
Figure 7-34. POWER_UP_SLOT_DURATION_1 Register

| 7 | 6 | 5 | 4 | 3 |
| :---: | :---: | :---: | :---: | :---: |

Table 7-31. POWER_UP_SLOT_DURATION_1 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_UP_SLOT_0_D URATION | R/W | X | Duration of slot 0 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_UP_SLOT_1_D URATION | R/W | X | Duration of slot 1 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_UP_SLOT_2_D URATION | R/W | X | Duration of slot 2 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 1-0 | POWER_UP_SLOT_3_D URATION | R/W | X | Duration of slot 3 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

### 7.6.24 POWER_UP_SLOT_DURATION_2 Register (Offset = 17h) [Reset = X]

POWER_UP_SLOT_DURATION_2 is shown in Figure 7-35 and described in Table 7-32.
Return to the Summary Table.
Figure 7-35. POWER_UP_SLOT_DURATION_2 Register

| 7 | 6 | 5 | 4 | 3 | 2 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| POWER_UP_SLOT_4_DURATIO | POWER_UP_SLOT_5_DURATIO | POWER_UP_SLOT_6_DURATIO | POWER_UP_SLOT_7_DURATIO |  |  |
| N |  | N |  |  |  |
| R/W-X | R/W-X | R/W-X | R/W-X |  |  |

Table 7-32. POWER_UP_SLOT_DURATION_2 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_UP_SLOT_4_D URATION | R/W | X | Duration of slot 4 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_UP_SLOT_5_D URATION | R/W | X | Duration of slot 5 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_UP_SLOT_6_D URATION | R/W | X | Duration of slot 6 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 1-0 | POWER_UP_SLOT_7_D URATION | R/W | X | Duration of slot 7 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

### 7.6.25 POWER_UP_SLOT_DURATION_3 Register (Offset = 18h) [Reset = X]

POWER_UP_SLOT_DURATION_3 is shown in Figure 7-36 and described in Table 7-33.
Return to the Summary Table.
Figure 7-36. POWER_UP_SLOT_DURATION_3 Register

| 7 | 6 | 5 | 4 | 3 | 2 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| POWER_UP_SLOT_8_DURATIO | POWER_UP_SLOT_9_DURATIO |  |  |  |  |
| N | POWER_UP_SLOT_10_DURATI | POWER_UP_SLOT_11_DURATI |  |  |  |
| ON-X | ON |  |  |  |  |
| R/W-X | R/W-X | R/W-X | R/W-X |  |  |

Table 7-33. POWER_UP_SLOT_DURATION_3 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_UP_SLOT_8_D URATION | R/W | X | Duration of slot 8 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_UP_SLOT_9_D URATION | R/W | X | Duration of slot 9 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_UP_SLOT_10_D URATION | R/W | X | Duration of slot 10 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 1-0 | POWER_UP_SLOT_11_D URATION | R/W | X | Duration of slot 11 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

### 7.6.26 POWER_UP_SLOT_DURATION_4 Register (Offset = 19h) [Reset = X]

POWER_UP_SLOT_DURATION_4 is shown in Figure 7-37 and described in Table 7-34.
Return to the Summary Table.
Figure 7-37. POWER_UP_SLOT_DURATION_4 Register

| 7 6 | 54 | 32 | 10 |
| :---: | :---: | :---: | :---: |
| POWER_UP_SLOT_12_DURATI | POWER_UP_SLOT_13_DURATI | POWER_UP_SLOT_14_DURATI | POWER_UP_SLOT_15_DURATI |
| R/W-X | R/W-X | R/W-X | R/W-X |

Table 7-34. POWER_UP_SLOT_DURATION_4 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_UP_SLOT_12_D URATION | R/W | X | Duration of slot 12 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_UP_SLOT_13_D URATION | R/W | X | Duration of slot 13 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_UP_SLOT_14_D URATION | R/W | X | Duration of slot 14 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \\ & 3 \mathrm{~h}=10 \mathrm{~ms} \end{aligned}$ |
| 1-0 | POWER_UP_SLOT_15_D URATION | R/W | X | Duration of slot 15 during the power-up and standby-to-active sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

### 7.6.27 POWER_DOWN_SLOT_DURATION_1 Register (Offset = 1Ah) [Reset = X]

POWER_DOWN_SLOT_DURATION_1 is shown in Figure 7-38 and described in Table 7-35.
Return to the Summary Table.
Figure 7-38. POWER_DOWN_SLOT_DURATION_1 Register
$\left.\begin{array}{|cc|cc|c|c|}\hline 7 & 6 & 5 & 4 & 3 & 2 \\ \hline \begin{array}{c}\text { POWER_DOWN_SLOT_0_DUR } \\ \text { ATION }\end{array} & \text { POWER_DOWN_SLOT_1_DUR } \\ \text { ATION }\end{array}\right)$

Table 7-35. POWER_DOWN_SLOT_DURATION_1 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_DOWN_SLOT_0 _DURATION | R/W | X | Duration of slot 0 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_DOWN_SLOT_1 _DURATION | R/W | X | Duration of slot 1 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_DOWN_SLOT_2 _DURATION | R/W | X | Duration of slot 2 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 1-0 | POWER_DOWN_SLOT_3 _DURATION | R/W | X | Duration of slot 3 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

### 7.6.28 POWER_DOWN_SLOT_DURATION_2 Register (Offset = 1Bh) [Reset = X]

POWER_DOWN_SLOT_DURATION_2 is shown in Figure 7-39 and described in Table 7-36.
Return to the Summary Table.
Figure 7-39. POWER_DOWN_SLOT_DURATION_2 Register

| 7 | 6 | 5 | 4 | 3 |
| :---: | :---: | :---: | :---: | :---: |
| POWER_DOWN_SLOT_4_DUR <br> ATION | POWER_DOWN_SLOT_5_DUR <br> ATION | POWER_DOWN_SLOT_6_DUR <br> ATION | POWER_DOWN_SLOT_7_DUR <br> ATION |  |
| R/W-X | R/W-X | R/W-X | R/W-X |  |

Table 7-36. POWER_DOWN_SLOT_DURATION_2 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_DOWN_SLOT_4 _DURATION | R/W | X | Duration of slot 4 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_DOWN_SLOT_5 _DURATION | R/W | X | Duration of slot 5 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_DOWN_SLOT_6 _DURATION | R/W | X | Duration of slot 6 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 1-0 | POWER_DOWN_SLOT_7 _DURATION | R/W | X | Duration of slot 7 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

### 7.6.29 POWER_DOWN_SLOT_DURATION_3 Register (Offset = 1Ch) [Reset = X]

POWER_DOWN_SLOT_DURATION_3 is shown in Figure 7-40 and described in Table 7-37.
Return to the Summary Table.
Figure 7-40. POWER_DOWN_SLOT_DURATION_3 Register

| 7 | 6 | 5 | 4 | 3 |
| :---: | :---: | :---: | :---: | :---: |
| POWER_DOWN_SLOT_8_DUR <br> ATION | POWER_DOWN_SLOT_9_DUR <br> ATION | POWER_DOWN_SLOT_10_DU <br> RATION | POWER_DOWN_SLOT_11_DUR <br> ATION |  |
| R/W-X | R/W-X | R/W-X | R/W-X |  |

Table 7-37. POWER_DOWN_SLOT_DURATION_3 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_DOWN_SLOT_8 DURATION | R/W | X | Duration of slot 8 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_DOWN_SLOT_9 _DURATION | R/W | X | Duration of slot 9 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_DOWN_SLOT_1 0_DURATION | R/W | X | Duration of slot 10 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 1-0 | POWER_DOWN_SLOT_1 1_DURATION | R/W | X | Duration of slot 11 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

### 7.6.30 POWER_DOWN_SLOT_DURATION_4 Register (Offset = 1Dh) [Reset = X]

POWER_DOWN_SLOT_DURATION_4 is shown in Figure 7-41 and described in Table 7-38.
Return to the Summary Table.
Figure 7-41. POWER_DOWN_SLOT_DURATION_4 Register

| 7 | 6 | 5 | 4 |  |
| :---: | :---: | :---: | :---: | :---: |
| POWER_DOWN_SLOT_12_DU <br> RATION | POWER_DOWN_SLOT_13_DU <br> RATION | POWER_DOWN_SLOT_14_DU <br> RATION | POWER_DOWN_SLOT_15_DU <br> RATION |  |
| R/W-X | R/W-X | R/W-X | R/W-X |  |

Table 7-38. POWER_DOWN_SLOT_DURATION_4 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7-6 | POWER_DOWN_SLOT_1 2_DURATION | R/W | X | Duration of slot 12 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 5-4 | POWER_DOWN_SLOT_1 3_DURATION | R/W | X | Duration of slot 13 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 3-2 | POWER_DOWN_SLOT_1 4_DURATION | R/W | X | Duration of slot 14 during the power-down and active-to-standby sequences. (Default from NVM memory) $0 \mathrm{~h}=0 \mathrm{~ms}$ $1 \mathrm{~h}=1.5 \mathrm{~ms}$ $2 \mathrm{~h}=3 \mathrm{~ms}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |
| 1-0 | POWER_DOWN_SLOT_1 5_DURATION | R/W | X | Duration of slot 15 during the power-down and active-to-standby sequences. (Default from NVM memory) $\begin{aligned} & 0 \mathrm{~h}=0 \mathrm{~ms} \\ & 1 \mathrm{~h}=1.5 \mathrm{~ms} \\ & 2 \mathrm{~h}=3 \mathrm{~ms} \end{aligned}$ $3 \mathrm{~h}=10 \mathrm{~ms}$ |

TPS65220
SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 7.6.31 GENERAL_CONFIG Register (Offset $=1 \mathrm{Eh}$ ) [Reset $=\mathrm{X}]$

GENERAL_CONFIG is shown in Figure 7-42 and described in Table 7-39.
Return to the Summary Table.
Figure 7-42. GENERAL_CONFIG Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BYPASS_RAIL <br> S_DISCHARGE <br> D_CHECK | LDO4_UV_THR | LDO3_UV_THR | LDO2_UV_THR | LDO1_UV_THR | GPIO_EN | GPO2_EN | GPO1_EN |
| R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |

Table 7-39. GENERAL_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | BYPASS_RAILS_DISCHA RGED_CHECK | R/W | X | Bypass the all-rails discharged check to commence a transition to ACTIVE state, and the rails-in-slot discharged check executed in each slot during a power-down to INITIALIZE state. Does not bypass the check for RV(Pre-biased) condition prior to enabling a regulator. <br> (Default from NVM memory) <br> Oh = Discharged checks enforced <br> 1h = Discharged checks bypassed |
| 6 | LDO4_UV_THR | R/W | X | UV threshold selection bit for LDO4. Only applicable if configured as LDO. (Default from NVM memory) <br> Oh $=-5 \%$ UV detection <br> $1 \mathrm{~h}=-10 \%$ UV detection |
| 5 | LDO3_UV_THR | R/W | X | UV threshold selection bit for LDO3. Only applicable if configured as LDO. (Default from NVM memory) <br> Oh $=-5 \%$ UV detection <br> $1 \mathrm{~h}=-10 \%$ UV detection |
| 4 | LDO2_UV_THR | R/W | X | UV threshold selection bit for LDO2. Only applicable if configured as LDO. (Default from NVM memory) <br> Oh $=-5 \%$ UV detection <br> $1 \mathrm{~h}=-10 \%$ UV detection |
| 3 | LDO1_UV_THR | R/W | X | UV threshold selection bit for LDO1. Only applicable if configured as LDO. (Default from NVM memory) <br> Oh = $-5 \%$ UV detection <br> $1 \mathrm{~h}=-10 \%$ UV detection |
| 2 | GPIO_EN | R/W | X | Both an enable and state control of GPIO. This bit enables the GPIO function and also controls the state of the GPIO pin. (Default from NVM memory) <br> Oh = The GPIO function is disabled. The output state is 'low'. <br> $1 \mathrm{~h}=$ The GPIO function is enabled. The output state is 'high'. |
| 1 | GPO2_EN | R/W | X | Both an enable and state control of GPO2. This bit enables the GPO2 function and also controls the state of the GPO2 pin. (Default from NVM memory) <br> Oh = GPO2 disabled. The output state is low. <br> $1 \mathrm{~h}=\mathrm{GPO} 2$ enabled. The output state is $\mathrm{Hi}-\mathrm{Z}$. |
| 0 | GPO1_EN | R/W | X | Both an enable and state control of GPO1. This bit enables the GPO1 function and also controls the state of the GPO1 pin. (Default from NVM memory) <br> Oh = GPO1 disabled. The output state is low. <br> $1 \mathrm{~h}=\mathrm{GPO} 1$ enabled. The output state is $\mathrm{Hi}-\mathrm{Z}$. |

### 7.6.32 MFP_1_CONFIG Register (Offset = 1Fh) [Reset = X]

MFP_1_CONFIG is shown in Figure 7-43 and described in Table 7-40.
Return to the Summary Table.
Figure 7-43. MFP_1_CONFIG Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MODE_I2C_CT <br> RL | VSEL_SD_I2C_ <br> CTRL | MODE_RESET <br> _POLARITY | MODE_STBY_ <br> POLARITY | MULTI_DEVICE <br> _ENABLE | VSEL_RAIL | VSEL_SD_POL | VSEL_DDR_SD |
| R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |  |

Table 7-40. MFP_1_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | MODE_I2C_CTRL | R/W | X | MODE control using I2C. Consolidated with MODE control via MODE/RESET and/or MODE/STBY pins. Refer to table in the data sheet. (Default from NVM memory) <br> Oh = Auto PFM <br> 1h = Forced PWM |
| 6 | VSEL_SD_I2C_CTRL | R/W | X | VSEL_SD control using I2C. Applicable only if VSEL_SD/ VSEL_DDR pin is configured as "VSEL_DDR". (Default from NVM memory) $\mathrm{Oh}=1.8 \mathrm{~V}$ <br> 1h = LDOx_VOUT register setting |
| 5 | MODE_RESET_POLARIT Y | R/W | X | MODE_RESET Pin Polarity configuration. Note: Ok to change during operation, but consider immediate reaction: MODE-change or RESET-entry! (Default from NVM memory) <br> Oh = [if configured as MODE] LOW - auto-PFM / HIGH - forced PWM. [if configured as RESET] LOW - reset / HIGH - normal operation. <br> 1h = [if configured as MODE] HIGH - auto-PFM / LOW - forced PWM. [if configured as RESET] HIGH - reset / LOW - normal operation. |
| 4 | MODE_STBY_POLARITY | R/W | X | MODE_STBY Pin Polarity configuration. Note: Ok to change during operation, but consider immediate reaction: MODE-change or STATE-change! (Default from NVM memory) <br> Oh = [if configured as MODE] LOW - auto-PFM / HIGH - forced PWM. [if configured as a STBY] LOW - STBY state / HIGH - ACTIVE state. <br> 1h = [if configured as MODE] HIGH - auto-PFM / LOW - forced PWM. [if configured as a STBY] HIGH - STBY state / LOW - ACTIVE state. |
| 3 | MULTI_DEVICE_ENABLE | R/W | X | Configures the device as a single device where GPO is used as GPO function, or as a multi-device configuration where GPO is used for synchronization with other devices. NOTE: ONLY CHANGE IN INITIALIZE STATE! (Default from NVM memory) <br> Oh = Single-device configuration, GPIO pin configured as GPO <br> 1h = Multi-device configuration, GPIO pin configured as GPIO |
| 2 | VSEL_RAIL | R/W | X | LDO controlled by VSEL_SD/VSEL_DDR. NOTE: ONLY CHANGE IN INITIALIZE STATE! (Default from NVM memory) $\begin{aligned} & \text { Oh = LDO1 } \\ & \text { 1h = LDO2 } \end{aligned}$ |
| 1 | VSEL_SD_POLARITY | R/W | X | SD Card Voltage Select Note: Ok to change during operation, but consider immediate reaction: change of SD-card supply voltage! (Default from NVM memory) <br> Oh = LOW - $1.8 \mathrm{~V} /$ HIGH - LDOx_VOUT register setting <br> $1 \mathrm{~h}=$ HIGH $-1.8 \mathrm{~V} /$ LOW - LDOx_VOUT register setting |
| 0 | VSEL_DDR_SD | R/W | X | VSEL_SD/VSEL_DDR Configuration NOTE: ONLY CHANGE IN INITIALIZE STATE! (Default from NVM memory) Oh = VSEL pin configured as DDR to set the voltage on Buck3 $1 \mathrm{~h}=$ VSEL pin configured as SD to set the voltage on the VSEL_RAIL |

### 7.6.33 MFP_2_CONFIG Register (Offset $=\mathbf{2 0 h}$ ) [Reset $=\mathrm{X}]$

MFP_2_CONFIG is shown in Figure 7-44 and described in Table 7-41.
Return to the Summary Table.
Figure 7-44. MFP_2_CONFIG Register

| 7 | 6 | 54 | 3 | 2 | 10 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| PU_ON_FSD | $\begin{aligned} & \text { WARM_COLD_ } \\ & \text { RESET_CONFI } \\ & \bar{G} \end{aligned}$ | EN_PB_VSENSE_CONFIG | EN_PB_VSENS E_DEGL | MODE_RESET _CONFIG | MODE_STBY_CONFIG |
| R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |

Table 7-41. MFP_2_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | PU_ON_FSD | R/W | X | Power up upon First Supply Detected (FSD). So when VSYS is <br> applied, device does power up to ACTIVE state even if EN/PB/ <br> VSENSE pin is at OFF_REQ status. (Default from NVM memory) <br> Oh = First Supply Detection (FSD) Disabled. <br> 1h = First Supply Detection (FSD) Enabled. |
| 6 | WARM_COLD_RESET_C <br> ONFIG | R/W | X | Selection between WARM or COLD Reset, when a RESET event is <br> triggered via MODE/RESET pin (does not apply to RESET via I2C) <br> (Default from NVM memory) <br> Oh = COLD RESET <br> 1h = WARM RESET |
| $5-4$ | EN_PB_VSENSE_CONFI <br> G | R/W | X | Enable / Push-Button / VSENSE Configuration. Do not change via <br> I2C after NVM load (except as a precursor before programming <br> NVM) (Default from NVM memory) <br> Oh = Device Enable Configuration |
| 1h = Push Button Configuration |  |  |  |  |
| 2h = VSENSE Configuration |  |  |  |  |
| 3h = Device Enable Configuration |  |  |  |  |$|$

INSTRUMENTS

### 7.6.34 STBY_1_CONFIG Register (Offset = 21h) [Reset = X]

STBY_1_CONFIG is shown in Figure 7-45 and described in Table 7-42.
Return to the Summary Table.
Figure 7-45. STBY_1_CONFIG Register

| 7 | 6 | 5 | 43 |  | 2 |  | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | $\operatorname{LDO}_{-\mathrm{N}}^{\mathrm{N}}$ | $\underset{\mathrm{N}}{\text { LDO3_STBY_E }^{2}}$ | $\operatorname{LDO}_{\mathrm{N}}^{2} \mathrm{STBY} \text { _E }$ | $\underset{N}{\text { LDO1_STBY_E }}$ | $\underset{E N}{\text { BUCK3_STBY }_{-}}$ | $\underset{\text { EN }}{\text { BUCK2_STBY_ }}$ | $\begin{gathered} \text { BUCK1_STBY_ } \\ \text { EN } \end{gathered}$ |
| R-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |

Table 7-42. STBY_1_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | LDO4_STBY_EN | R/W | X | Enable LDO4 in STANDBY state. (Default from NVM memory) <br> oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 5 | LDO3_STBY_EN | R/W | X | Enable LDO3 in STANDBY state. (Default from NVM memory) <br> Oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 4 | LDO2_STBY_EN | R/W | X | Enable LDO2 in STANDBY state. (Default from NVM memory) <br> oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 3 | LDO1_STBY_EN | R/W | X | Enable LDO1 in STANDBY state. (Default from NVM memory) <br> Oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 2 | BUCK3_STBY_EN | R/W | X | Enable BUCK3 in STANDBY state. (Default from NVM memory) <br> 0h = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 1 | BUCK2_STBY_EN | R/W | X | Enable BUCK2 in STANDBY state. (Default from NVM memory) <br> Oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 0 | BUCK1_STBY_EN | R/W | X | Enable BUCK1 in STANDBY state. (Default from NVM memory) <br> Oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |

### 7.6.35 STBY_2_CONFIG Register (Offset $=\mathbf{2 2 h}$ ) [Reset $=\mathrm{X}]$

STBY_2_CONFIG is shown in Figure 7-46 and described in Table 7-43.
Return to the Summary Table.
Figure 7-46. STBY_2_CONFIG Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | GPIO_STBY_E | GPO2_STBY_E | GPO1_STBY_E |
| R-X |  | $R-X$ | $R-X$ | $R-X$ | $R-X ~$ | $R / W-X$ | $R / W-X ~$ |

Table 7-43. STBY_2_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | RESERVED | R | X | Reserved |
| 5 | RESERVED | R | X | Reserved |
| 4 | RESERVED | R | X | Reserved |
| 3 | RESERVED | R | X | Reserved |
| 2 | GPIO_STBY_EN | R/W | X | Enable GPIO in STANDBY state. (Default from NVM memory) <br> Oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 1 | GPO2_STBY_EN | R/W | X | Enable GPO2 in STANDBY state. (Default from NVM memory) <br> Oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |
| 0 | GPO1_STBY_EN | R/W | X | Enable GPO1 in STANDBY state. (Default from NVM memory) <br> Oh = Disabled in STBY Mode <br> 1h = Enabled in STBY Mode |

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### 7.6.36 OC_DEGL_CONFIG Register (Offset = 23h) [Reset = X]

OC_DEGL_CONFIG is shown in Figure 7-47 and described in Table 7-44.
Return to the Summary Table.
Figure 7-47. OC_DEGL_CONFIG Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | EN_LONG_DE GL_FOR_OC_L DO4 | $\begin{gathered} \text { EN_LONG_DE } \\ \text { GL_FOR_OC_L } \\ \text { DOO } \end{gathered}$ | $\begin{gathered} \hline \text { EN_LONG_DE } \\ \text { GL_FOR_OC_L } \\ \text { DO2 } \end{gathered}$ | $\begin{gathered} \text { EN_LONG_DE } \\ \text { GL_FOR_OC_L } \\ \text { DO1 } \end{gathered}$ | EN_LONG_DE GL_FOR_OC_ BUCK3 | EN_LONG_DE GL_FOR_OC_ BUCK2 | EN_LONG_DE GL_FOR_OC_ BUCK1 |
| R-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |

Table 7-44. OC_DEGL_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | RESERVED | R | X | Reserved |
| 6 | $\begin{aligned} & \text { EN_LONG_DEGL_FOR_ } \\ & \text { OC_LDO4 } \end{aligned}$ | R/W | X | When set, enables the long-deglitch option for OverCurrent signal of LDO4. When clear, enables the short-deglitch option for OverCurrent signal of LDO4. (Default from NVM memory) <br> Oh = Deglitch duration for OverCurrent signals of LDO4 is ~20us <br> $1 \mathrm{~h}=$ Deglitch duration for OverCurrent signals of LDO4 is $\sim 2 \mathrm{~ms}$ |
| 5 | $\begin{aligned} & \text { EN_LONG_DEGL_FOR_ } \\ & \text { OC_LDO3 } \end{aligned}$ | R/W | X | When set, enables the long-deglitch option for OverCurrent signal of LDO3. When clear, enables the short-deglitch option for OverCurrent signal of LDO3. (Default from NVM memory) <br> Oh = Deglitch duration for OverCurrent signals of LDO3 is $\sim 20$ us <br> $1 \mathrm{~h}=$ Deglitch duration for OverCurrent signals of LDO3 is $\sim 2 \mathrm{~ms}$ |
| 4 | $\begin{aligned} & \text { EN_LONG_DEGL_FOR_ } \\ & \text { OC_LDO2 } \end{aligned}$ | R/W | X | When set, enables the long-deglitch option for OverCurrent signal of LDO2. When clear, enables the short-deglitch option for OverCurrent signal of LDO2. (Default from NVM memory) <br> Oh = Deglitch duration for OverCurrent signals of LDO2 is ~20us <br> $1 \mathrm{~h}=$ Deglitch duration for OverCurrent signals of LDO2 is $\sim 2 \mathrm{~ms}$ |
| 3 | $\begin{array}{\|l} \text { EN_LONG_DEGL_FOR_ } \\ \text { OC_LDO1 } \end{array}$ | R/W | X | When set, enables the long-deglitch option for OverCurrent signal of LDO1. When clear, enables the short-deglitch option for OverCurrent signal of LDO1. (Default from NVM memory) <br> Oh = Deglitch duration for OverCurrent signals of LDO1 is ~20us <br> $1 \mathrm{~h}=$ Deglitch duration for OverCurrent signals of LDO1 is $\sim 2 \mathrm{~ms}$ |
| 2 | $\begin{aligned} & \text { EN_LONG_DEGL_FOR_ } \\ & \text { OC_BUCK3 } \end{aligned}$ | R/W | X | When set, enables the long-deglitch option for OverCurrent signals of BUCK3. When clear, enables the short-deglitch option for OverCurrent signals of BUCK3. (Default from NVM memory) Oh = Deglitch duration for OverCurrent signals for BUCK3 (High-Side Overcurrent, Low-Side Overcurrent and Low-Side Reverse/Negative OverCurrent) is $\sim 20$ us <br> 1h = Deglitch duration for OverCurrent signals for BUCK3 (High-Side Overcurrent, Low-Side Overcurrent and Low-Side Reverse/Negative OverCurrent) is $\sim 2 \mathrm{~ms}$ |
| 1 | $\begin{aligned} & \text { EN_LONG_DEGL_FOR_ } \\ & \text { OC_BUCK2 } \end{aligned}$ | R/W | X | When set, enables the long-deglitch option for OverCurrent signals of BUCK2. When clear, enables the short-deglitch option for OverCurrent signals of BUCK2. (Default from NVM memory) Oh = Deglitch duration for OverCurrent signals for BUCK2 (High-Side Overcurrent, Low-Side Overcurrent and Low-Side Reverse/Negative OverCurrent) is $\sim 20$ us 1h = Deglitch duration for OverCurrent signals for BUCK2 (High-Side Overcurrent, Low-Side Overcurrent and Low-Side Reverse/Negative OverCurrent) is $\sim 2 \mathrm{~ms}$ |

Table 7-44. OC_DEGL_CONFIG Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 0 | EN_LONG_DEGL_FOR_ <br> OC_BUCK1 | R/W | X | When set, enables the long-deglitch option for OverCurrent signals <br> of BUCK1. When clear, enables the short-deglitch option for <br> OverCurrent signals of BUCK1. (Default from NVM memory) <br> Oh = Deglitch duration for OverCurrent signals for BUCK1 (High-Side <br> Overcurrent, Low-Side Overcurrent and Low-Side Reverse/Negative <br> OverCurrent) is $\sim 20$ us <br> 1h = Deglitch duration for OverCurrent signals for BUCK1 (High-Side <br> Overcurrent, Low-Side Overcurrent and Low-Side Reverse/Negative <br> OverCurrent) is $\sim 2 m s$ |

### 7.6.37 INT_MASK_UV Register (Offset = 24h) [Reset = X]

INT_MASK_UV is shown in Figure 7-48 and described in Table 7-45.
Return to the Summary Table.
Figure 7-48. INT_MASK_UV Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MASK_RETRY <br> _COUNT | BUCK3_UV_M <br> ASK | BUCK2_UV_M <br> ASK | BUCK1_UV_M <br> ASK | LDO4_UV_MA | LDO3_UV_MA | LDO2_UV_MA | LDO1_UV_MA |
| R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |  |
| SK | R/W-X |  |  |  |  |  |  |

Table 7-45. INT_MASK_UV Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | MASK_RETRY_COUNT | R/W | X | When set, device can power up even after two retries. (Default from NVM memory) <br> Oh = Device does retry up to 2 times, then stay off <br> $1 \mathrm{~h}=$ Device does retry infinitely |
| 6 | BUCK3_UV_MASK | R/W | X | BUCK3 Undervoltage Mask. (Default from NVM memory) Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 5 | BUCK2_UV_MASK | R/W | X | BUCK2 Undervoltage Mask. (Default from NVM memory) Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 4 | BUCK1_UV_MASK | R/W | X | BUCK1 Undervoltage Mask. (Default from NVM memory) Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 3 | LDO4_UV_MASK | R/W | X | LDO4 Undervoltage Mask - Always masked in BYP or LSW modes. <br> (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 2 | LDO3_UV_MASK | R/W | X | LDO3 Undervoltage Mask - Always masked in BYP or LSW modes. <br> (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 1 | LDO2_UV_MASK | R/W | X | LDO2 Undervoltage Mask - Always masked in BYP or LSW modes. <br> (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 0 | LDO1_UV_MASK | R/W | X | LDO1 Undervoltage Mask - Always masked in BYP or LSW modes. (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |

### 7.6.38 MASK_CONFIG Register (Offset = 25h) [Reset = X]

MASK_CONFIG is shown in Figure 7-49 and described in Table 7-46.
Return to the Summary Table.
Figure 7-49. MASK_CONFIG Register

| 7 | 6 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\underset{\text { R_PB }}{\substack{\text { MASK_INT_FO } \\ \text { R_PB }}}$ | MASK_EFFECT | $\begin{gathered} \text { MASK_INT_FO } \\ \text { R_RV }^{2} \end{gathered}$ | SENSOR 0 W ARM_MĀSK | SENSOR 1 W ARM_MĀSK | SENSOR 2 W ARM_MASK | SENSOR 3 W ARM_MĀSK |
| R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X | R/W-X |

Table 7-46. MASK_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | MASK_INT_FOR_PB | R/W | X | Masking bit to control whether nINT pin is sensitive to PushButton (PB) press/release events or not. (Default from NVM memory) Oh = un-masked (nINT pulled low for any PB events) <br> $1 \mathrm{~h}=$ masked (nINT not sensitive to any PB events) |
| 6-5 | MASK_EFFECT | R/W | X | Effect of masking (global) (Default from NVM memory) Oh = no state change, no nINT reaction, no bit set for Faults 1h = no state change, no nINT reaction, bit set for Faults $2 \mathrm{~h}=$ no state change, nINT reaction, bit set for Faults (same as 11b) 3h = no state change, nINT reaction, bit set for Faults (same as 10b) |
| 4 | MASK_INT_FOR_RV | R/W | X | Masking bit to control whether nINT pin is sensitive to RV (Residual Voltage) events or not. (Default from NVM memory) Oh = un-masked (nINT pulled low for any RV events during transition to ACTIVE state or during enabling of rails) 1h = masked (nINT not sensitive to any RV events) |
| 3 | $\begin{aligned} & \text { SENSOR_O_WARM_MAS } \\ & \mathrm{K} \end{aligned}$ | R/W | X | Die Temperature Warm Fault Mask, Sensor 0. (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 2 | $\begin{aligned} & \text { SENSOR_1_WARM_MAS } \\ & \mathrm{K} \end{aligned}$ | R/W | X | Die Temperature Warm Fault Mask, Sensor 1. (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 1 | SENSOR_2_WARM_MAS | R/W | X | Die Temperature Warm Fault Mask, Sensor 2. (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |
| 0 | $\begin{aligned} & \text { SENSOR_3_WARM_MAS } \\ & \mathrm{K} \end{aligned}$ | R/W | X | Die Temperature Warm Fault Mask, Sensor 3. (Default from NVM memory) <br> Oh = un-masked (Faults reported) <br> 1h = masked (Faults not reported) |

### 7.6.39 I2C_ADDRESS_REG Register (Offset = 26h) [Reset = X]

I2C_ADDRESS_REG is shown in Figure 7-50 and described in Table 7-47.
Return to the Summary Table.
Figure 7-50. I2C_ADDRESS_REG Register


Table 7-47. I2C_ADDRESS_REG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | DIY_NVM_PROGRAM_C <br> MD_ISSUED | R/W | X | Bit that indicates whether a DIY program command was attempted. <br> Once set, remains always set. (Default from NVM memory) <br> Oh = NVM data not changed <br> 1h = NVM data attempted to be changed via DIY program command |
| $6-0$ | I2C_ADDRESS | R/W | X | I2C secondary address. Note: Ok to change during operation, but <br> consider immediate reaction: new address for read/write! (Default <br> from NVM memory) |

### 7.6.40 USER_GENERAL_NVM_STORAGE_REG Register (Offset = 27h) [Reset = X]

USER_GENERAL_NVM_STORAGE_REG is shown in Figure 7-51 and described in Table 7-48.
Return to the Summary Table.
Figure 7-51. USER_GENERAL_NVM_STORAGE_REG Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Table 7-48. USER_GENERAL_NVM_STORAGE_REG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
| $7-0$ | USER_GENERAL_NVM_ <br> STORAGE | R/W | X | 8-bit NVM-based register available to the user to use to store user- <br> data, for example NVM-ID of customer-modified NVM-version or <br> other purposes. (Default from NVM memory) |

### 7.6.41 MANUFACTURING_VER Register (Offset $=\mathbf{2 8 h}$ ) [Reset $=\mathbf{0 0 h}$ ]

MANUFACTURING_VER is shown in Figure 7-52 and described in Table 7-49.
Return to the Summary Table.
Figure 7-52. MANUFACTURING_VER Register
$\left.\begin{array}{|lllllll|}\hline 7 & 6 & 5 & 4 & 3 & 2 & 1\end{array}\right]$

Table 7-49. MANUFACTURING_VER Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
| $7-0$ | SILICON_REV | R | Oh | SILICON_REV[7:6] - Reserved SILICON_REV[5:3] - ALR <br> SILICON_REV[2:0] - Metal Silicon Revision - Hard wired (not under <br> NVM control) |

### 7.6.42 MFP_CTRL Register (Offset $=\mathbf{2 9 h}$ ) [Reset $=\mathrm{X}]$

MFP_CTRL is shown in Figure 7-53 and described in Table 7-50.
Return to the Summary Table.
Figure 7-53. MFP_CTRL Register

| 7 | 6 | 5 | 4 | 2 | 1 | 0 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | RESERVED | RESERVED | GPIO_STATUS | WARM_RESET <br> _12C_CTRL | COLD_RESET_ <br> I2C_CTRL | STBY_12C_CT <br> RL | I2C_OFF_REQ |
| R-X | R-X | R-X | R-Oh | R/WSelfCIrF-Oh | R/W-Oh | R/W-Oh | R/WSelfCIrF-Oh |

Table 7-50. MFP_CTRL Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | RESERVED | R | X | Reserved |
| 5 | RESERVED | R | X | Reserved |
| 4 | GPIO_STATUS | R | Oh | Indicates the real-time value of GPIO pin <br> Oh = The GPIO pin is currently '0' <br> 1h = The GPIO pin is currently '1' |
| 3 | WARM_RESET_I2C_CTR <br> L | R/WSelfCIrF | Oh | Triggers a WARM RESET when written as '1'. Note: This bit self- <br> clears automatically, so cannot be read as '1' after the write. <br> Oh = normal operation <br> 1h = WARM_RESET |
| 2 | COLD_RESET_I2C_CTR <br> L | R/W | Oh | Triggers a COLD RESET when set high. Cleared upon entry to <br> INITIALIZE. <br> Oh = normal operation <br> 1h = COLD_RESET |
| 1 | STBY_I2C_CTRL | R/W | Oh | STBY control using I2C. Consolidated with STBY control via MODE/ <br> STBY pin. Refer to table in spec. <br> Oh = normal operation <br> 1h = STBY mode |
| 0 | I2C_OFF_REQ | R/WSelfCIrF | Oh | When '1' is written to this bit: Trigger OFF request. When '0': No <br> effect. Does self-clear. <br> Oh = No effect <br> 1h = Trigger OFF Request |

### 7.6.43 DISCHARGE_CONFIG Register (Offset = 2Ah) [Reset = X]

DISCHARGE_CONFIG is shown in Figure 7-54 and described in Table 7-51.
Return to the Summary Table.
Figure 7-54. DISCHARGE_CONFIG Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | LDO4_DISCHA <br> RGE_EN | LDO3_DISCHA <br> RGE_EN | LDO2_DISCHA <br> RGE_EN | LDO1_DISCHA <br> RGE_EN | BUCK3_DISCH <br> ARGE_EN | BUCK2_DISCH <br> ARGE_EN | BUCK1_DISCH <br> ARGE_EN |
| R-X | R/W-1h | R/W-1h | R/W-1h | R/W-1h | R/W-1h | R/W-1h | R/W-1h |

Table 7-51. DISCHARGE_CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | RESERVED | R | X | Reserved |
| 6 | LDO4_DISCHARGE_EN | R/W | 1h | Discharge setting for LDO4 Oh = No Discharge $1 \mathrm{~h}=250 \Omega$ |
| 5 | LDO3_DISCHARGE_EN | R/W | 1h | Discharge setting for LDO3 Oh = No Discharge $1 \mathrm{~h}=250 \Omega$ |
| 4 | LDO2_DISCHARGE_EN | R/W | 1h | Discharge setting for LDO2 Oh = No Discharge $1 \mathrm{~h}=200 \Omega$ |
| 3 | LDO1_DISCHARGE_EN | R/W | 1h | Discharge setting for LDO1 Oh = No Discharge $1 \mathrm{~h}=200 \Omega$ |
| 2 | BUCK3_DISCHARGE_EN | R/W | 1h | Discharge setting for BUCK3 Oh = No Discharge $1 \mathrm{~h}=125 \Omega$ |
| 1 | BUCK2_DISCHARGE_EN | R/W | 1h | Discharge setting for BUCK2 Oh = No Discharge $1 \mathrm{~h}=125 \Omega$ |
| 0 | BUCK1_DISCHARGE_EN | R/W | 1h | Discharge setting for BUCK1 Oh = No Discharge $1 \mathrm{~h}=125 \Omega$ |

TPS65220
SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 7.6.44 INT_SOURCE Register (Offset $=\mathbf{2 B h}$ ) [Reset $=00 \mathrm{~h}$ ]

INT_SOURCE is shown in Figure 7-55 and described in Table 7-52.
Return to the Summary Table.
Figure 7-55. INT_SOURCE Register

| 7 | 65 |  | 43 |  | 21 |  | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INT_PB_IS_SE | $\begin{gathered} \text { INT_LDO_3_4_ } \\ \text { IS_SET }^{-} \end{gathered}$ | $\begin{gathered} \text { INT_LDO_1_2 } \\ \text { IS_SET } \end{gathered}$ | $\begin{gathered} \text { INT_BUCK_3_I } \\ \text { S_SET }^{-1} \end{gathered}$ | $\underset{\text { INT_BUCK_1_2 }}{\text { IS_SET }}$ | $\begin{array}{\|c\|} \hline \text { INT_SYSTEM_I } \\ \text { S_SET } \end{array}$ | INT_RV_IS_SE | INT_TIMEOUT RV_SD_IS_SE |
| R-Oh | R-Oh | R-Oh | R-Oh | R-Oh | R-Oh | R-Oh | R-Oh |

Table 7-52. INT_SOURCE Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | INT_PB_IS_SET | R | Oh | One or more sources of the INT present in register INT_PB <br> Oh = No bits set in INT_PB <br> 1h = One or more bits set in INT_PB |
| 6 | INT_LDO_3_4_IS_SET | R | Oh | One or more sources of the INT present in register INT_LDO_3_4 <br> Oh = No bits set in INT_LDO_3_4 <br> 1h = One or more bits set in INT_LDO_3_4 |
| 5 | INT_LDO_1_2_IS_SET | R | Oh | One or more sources of the INT present in register INT_LDO_1_2 <br> Oh = No bits set in INT_LDO_1_2 <br> 1h = One or more bits set in INT_LDO_1_2 |
| 4 | INT_BUCK_3_IS_SET | R | Oh | One or more sources of the INT present in register INT_BUCK_3 <br> Oh = No bits set in INT_BUCK_3 <br> 1h = One or more bits set in INT_BUCK_3 |
| 3 | INT_BUCK_1_2_IS_SET | R | Oh | One or more sources of the INT present in register INT_BUCK_1_2 <br> Oh = No bits set in INT_BUCK_1_2 <br> 1h = One or more bits set in INT_BUCK_1_2 |
| 2 | INT_SYSTEM_IS_SET | R | Oh | One or more sources of the INT present in register INT_SYSTEM <br> Oh = No bits set in INT_SYSTEM <br> 1h = One or more bits set in INT_SYSTEM |
| 1 | INT_RV_IS_SET | R | Oh | One or more sources of the INT present in register INT_RV <br> Oh = No bits set in INT_RV <br> 1h = One or more bits set in INT_RV |
| 0 | INT_TIMEOUT_RV_SD_I <br> S_SET | R | Oh | One or more sources of the INT present in register <br> INT_TIMEOUT_RV_SD <br> Oh = No bits set in INT_TIMEOUT_RV_SD <br> 1h = One or more bits set in INT_TIMEOUT_RV_SD |

### 7.6.45 INT_LDO_3_4 Register (Offset = 2Ch) [Reset = X]

INT_LDO_3_4 is shown in Figure 7-56 and described in Table 7-53.
Return to the Summary Table.
Figure 7-56. INT_LDO_3_4 Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | RESERVED | LDO4_UV | LDO4_OC | LDO4_SCG | LDO3_UV | LDO3_OC | LDO3_SCG |
| R-X | R-X | R/W1C-0h | R/W1C-Oh | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h |

Table 7-53. INT_LDO_3_4 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | RESERVED | R | X | Reserved |
| 5 | LDO4_UV | R/W1C | Oh | LDO4 Undervoltage Fault. Is automatically cleared upon a transition <br> to INITIALIZE state, if corresponding *_UV_MASK bit in register <br> INT_MASK_UV is '11 <br> Oh = No Fault detected <br> 1h = Fault detected |
| 4 | LDO4_OC | R/W1C | Oh | LDO4 Overcurrent Fault. <br> 0h = No Fault detected <br> 1h = Fault detected |
| 3 | LDO4_SCG | R/W1C | Oh | LDO4 Short Circuit to Ground Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 2 | LDO3_UV | R/W1C | Oh | LDO3 Undervoltage Fault. Is automatically cleared upon a transition <br> to INITIALIZE state, if corresponding *_UV_MASK bit in register <br> INT_MASK_UV is '1' |
| Oh = No Fault detected |  |  |  |  |
| 1h = Fault detected |  |  |  |  |$|$

### 7.6.46 INT_LDO_1_2 Register (Offset = 2Dh) [Reset = X]

INT_LDO_1_2 is shown in Figure 7-57 and described in Table 7-54.
Return to the Summary Table.
Figure 7-57. INT_LDO_1_2 Register

| 7 | 6 | 5 | 4 | 3 | 1 | 0 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | RESERVED | LDO2_UV | LDO2_OC | LDO2_SCG | LDO1_UV | LDO1_OC | LDO1_SCG |
| R-X | R-X | R/W1C-0h | R/W1C-Oh | R/W1C-Oh | R/W1C-0h | R/W1C-0h | R/W1C-0h |

Table 7-54. INT_LDO_1_2 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | RESERVED | R | X | Reserved |
| 5 | LDO2_UV | R/W1C | Oh | LDO2 Undervoltage Fault. Is automatically cleared upon a transition <br> to INITIALIZE state, if corresponding *_UV_MASK bit in register <br> INT_MASK_UV is '11 <br> Oh = No Fault detected <br> 1h = Fault detected |
| 4 | LDO2_OC | R/W1C | Oh | LDO2 Overcurrent Fault <br> 0h = No Fault detected <br> 1h = Fault detected |
| 3 | LDO2_SCG | R/W1C | Oh | LDO2 Short Circuit to Ground Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 2 | LDO1_UV | R/W1C | Oh | LDO1 Undervoltage Fault. Is automatically cleared upon a transition <br> to INITIALIZE state, if corresponding *_UV_MASK bit in register <br> INT_MASK_UV is '1' |
| Oh = No Fault detected |  |  |  |  |
| 1h = Fault detected |  |  |  |  |$|$

### 7.6.47 INT_BUCK_3 Register (Offset = 2Eh) [Reset = X]

INT_BUCK_3 is shown in Figure 7-58 and described in Table 7-55.
Return to the Summary Table.
Figure 7-58. INT_BUCK_3 Register

| 7 | 6 | 5 | 4 | 3 | 1 | 0 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | RESERVED | RESERVED | RESERVED | BUCK3_UV | BUCK3_NEG_ <br> OC | BUCK3_OC | BUCK3_SCG |
| R-X | R-X | R-X | R-X | R/W1C-0h | R/W1C-Oh | R/W1C-0h | R/W1C-0h |

Table 7-55. INT_BUCK_3 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | RESERVED | R | X | Reserved |
| 5 | RESERVED | R | X | Reserved |
| 4 | RESERVED | R | X | Reserved |
| 3 | BUCK3_UV | R/W1C | Oh | BUCK3 Undervoltage Fault. Is automatically cleared upon a <br> transition to INITIALIZE state, if corresponding *_UV_MASK bit in <br> register INT_MASK_UV is '1' <br> Oh = No Fault detected <br> 1h = Fault detected |
| 2 | BUCK3_NEG_OC | R/W1C | Oh | BUCK3 Negative Overcurrent Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 1 | BUCK3_OC | R/W1C | Oh | BUCK3 Positive Overcurrent Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 0 | BUCK3_SCG | R/W1C | Oh | BUCK3 Short Circuit to Ground Fault <br> Oh = No Fault detected <br> 1h = Fault detected |

SLVSGY1A - DECEMBER 2022 - REVISED JULY 2023

### 7.6.48 INT_BUCK_1_2 Register (Offset = 2Fh) [Reset =00h]

INT_BUCK_1_2 is shown in Figure 7-59 and described in Table 7-56.
Return to the Summary Table.
Figure 7-59. INT_BUCK_1_2 Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| BUCK2_UV | BUCK2_NEG_ <br> OC | BUCK2_OC | BUCK2_SCG | BUCK1_UV | BUCK1_NEG_ <br> OC | BUCK1_OC | BUCK1_SCG |
| R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h |

Table 7-56. INT_BUCK_1_2 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | BUCK2_UV | R/W1C | Oh | BUCK2 Undervoltage Fault. Is automatically cleared upon a <br> transition to INITIALIZE state, if corresponding *_UV_MASK bit in <br> register INTMASK_UV is '1' <br> Oh = No Fault detected <br> 1h F Fault detected |
| 6 | BUCK2_NEG_OC | R/W1C | Oh | BUCK2 Negative Overcurrent Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 5 | BUCK2_OC | R/W1C | Oh | BUCK2 Positive Overcurrent Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 4 | BUCK2_SCG | R/W1C | Oh | BUCK2 Short Circuit to Ground Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 3 | BUCK1_UV | R/W1C | Oh | BUCK1 Undervoltage Fault. Is automatically cleared upon a <br> transition to INITIALIZE state, if corresponding *_UV_MASK bit in <br> register INTMASK_UV is '1' <br> Oh = No Fault detected <br> 1h F Fault detected |
| 2 | BUCK1_NEG_OC | R/W1C | Oh | BUCK1 Negative Overcurrent Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 1 | BUCK1_OC | R/W1C | Oh | BUCK1 Positive Overcurrent Fault <br> Oh = No Fault detected <br> 1h = Fault detected |
| 0 | BUCK1_SCG | R/W1C | Oh | BUCK1 Short Circuit to Ground Fault <br> Oh = No Fault detected <br> 1h = Fault detected |

### 7.6.49 INT_SYSTEM Register (Offset = 30h) [Reset = 00h]

INT_SYSTEM is shown in Figure 7-60 and described in Table 7-57.
Return to the Summary Table.
Figure 7-60. INT_SYSTEM Register

| 7 | 6 | 5 | 4 | 2 | 1 | 0 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SENSOR_0_H <br> OT | SENSOR_1_H <br> OT | SENSOR_2_H <br> OT | SENSOR_3_H <br> OT | SENSOR_0_W <br> ARM | SENSOR_1_W <br> ARM | SENSOR_2_W <br> ARM | SENSOR_3_W <br> ARM |
| R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h |

Table 7-57. INT_SYSTEM Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | SENSOR_0_HOT | R/W1C | Oh | TSD Hot detection for sensor 0 Oh = No Fault detected <br> 1h = Fault detected |
| 6 | SENSOR_1_HOT | R/W1C | Oh | TSD Hot detection for sensor 1 Oh = No Fault detected <br> 1h = Fault detected |
| 5 | SENSOR_2_HOT | R/W1C | Oh | TSD Hot detection for sensor 2 Oh = No Fault detected 1h = Fault detected |
| 4 | SENSOR_3_HOT | R/W1C | Oh | TSD Hot detection for sensor 3 Oh = No Fault detected 1h = Fault detected |
| 3 | SENSOR_0_WARM | R/W1C | Oh | TSD Warm detection for sensor 0 . Is automatically cleared upon a transition to INITIALIZE state, if corresponding *_WARM_MASK bit in register MASK_CONFIG is ' 1 ' <br> Oh = No Fault detected <br> 1h = Fault detected |
| 2 | SENSOR_1_WARM | R/W1C | Oh | TSD Warm detection for sensor 1 . Is automatically cleared upon a transition to INITIALIZE state, if corresponding *_WARM_MASK bit in register MASK_CONFIG is ' 1 ' <br> Oh = No Fault detected <br> 1h = Fault detected |
| 1 | SENSOR_2_WARM | R/W1C | Oh | TSD Warm detection for sensor 2. Is automatically cleared upon a transition to INITIALIZE state, if corresponding *_WARM_MASK bit in register MASK_CONFIG is ' 1 ' <br> Oh = No Fault detected <br> 1h = Fault detected |
| 0 | SENSOR_3_WARM | R/W1C | Oh | TSD Warm detection for sensor 3. Is automatically cleared upon a transition to INITIALIZE state, if corresponding *_WARM_MASK bit in register MASK_CONFIG is '1' <br> Oh = No Fault detected <br> 1h = Fault detected |

TPS65220

### 7.6.50 INT_RV Register (Offset = 31 $\mathbf{h}$ ) Reset = X]

INT_RV is shown in Figure 7-61 and described in Table 7-58.
Return to the Summary Table.
Figure 7-61. INT_RV Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | LDO4_RV | LDO3_RV | LDO2_RV | LDO1_RV | BUCK3_RV | BUCK2_RV | BUCK1_RV |
| R-X | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h |

Table 7-58. INT_RV Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | LDO4_RV | R/W1C | Oh | RV event detected on LDO4 rail during rail-turn-on, or after 4-5 <br> ms during discharge checks prior to entering power sequence to <br> ACTIVE state <br> Oh = No RV detected <br> 1h = RV detected |
| 5 | LDO3_RV | R/W1C | Oh | RV event detected on LDO3 rail during rail-turn-on, or after 4-5 <br> ms during discharge checks prior to entering power sequence to <br> ACTIVE state <br> Oh = No RV detected <br> 1h = RV detected |
| 4 | LDO2_RV | R/W1C | Oh | RV event detected on LDO2 rail during rail-turn-on, or after 4-5 <br> ms during discharge checks prior to entering power sequence to <br> ACTIVE state <br> Oh = No RV detected <br> 1h = RV detected |
| 3 | LDO1_RV | R/W1C | Oh | RV event detected on LDO1 rail during rail-turn-on, or after 4-5 <br> ms during discharge checks prior to entering power sequence to <br> ACTIVE state <br> Oh = No RV detected <br> 1h = RV detected |
| 2 | BUCK3_RV | R/W1C | Oh | RV event detected on BUCK3 rail during rail-turn-on, or after 4-5 <br> ms during discharge checks prior to entering power sequence to <br> ACTIVE state <br> Oh = No RV detected <br> 1h = RV detected |
| 1 | BUCK2_RV | R/W1C | Oh | RV event detected on BUCK2 rail during rail-turn-on, or after 4-5 <br> ms during discharge checks prior to entering power sequence to <br> ACTIVE state <br> Oh = No RV detected <br> 1h = RV detected |
| 0 | BUCK1_RV | R/W1C | Oh | RV event detected on BUCK1 rail during rail-turn-on, or after 4-5 <br> ms during discharge checks prior to entering power sequence to <br> ACTIVE state <br> Oh = No RV detected <br> 1h = RV detected |

### 7.6.51 INT_TIMEOUT_RV_SD Register (Offset = 32h) [Reset = 00h]

INT_TIMEOUT_RV_SD is shown in Figure 7-62 and described in Table 7-59.
Return to the Summary Table.
Figure 7-62. INT_TIMEOUT_RV_SD Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TIMEOUT | LDO4_RV_SD | LDO3_RV_SD | LDO2_RV_SD | LDO1_RV_SD | BUCK3_RV_SD | BUCK2_RV_SD | BUCK1_RV_SD |
| R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h | R/W1C-0h |

Table 7-59. INT_TIMEOUT_RV_SD Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | TIMEOUT | R/W1C | Oh | Is set if ShutDown occurred due to a TimeOut while: 1. Transitioning to ACTIVE state, and one or more rails did not rise past the UV level at the end of the assigned slot (and UV on this rail is configured as a SD fault). Which rail(s) is/are indicated by the *_UV bits in the INT_* registers. 2. Transitioning to STANDBY state, and one or more rails did not fall below the SCG level at the end of the assigned slot and discharge is enabled for that rail (which rail(s) is/are indicated by the corresponding RV_SD bit(s) in this register). <br> Oh = No SD due to TimeOut occurred <br> 1h = SD due to TimeOut occurred |
| 6 | LDO4_RV_SD | R/W1C | Oh | RV on LDO4 rail caused a shutdown during: 1. A transition to STANDBY state, this rail did not discharge at the end of the assigned slot and discharge is enabled for this rail 2. A transition to STANDBY state, RV was observed on this rail during the transition after this rail was disabled and discharge was enabled 3. A transition to ACTIVE state, RV was observed on this rail during the transition when this rail was OFF (rails are expected to be discharged before commencing the sequence to ACTIVE) 4. This rail did not discharge and therefore caused a Timeout-SD while attempting to discharge all rails at the start of a transition from STANDBY to ACTIVE (TIMEOUT bit gets also set in this case) <br> Oh = No SD due to RV/DISCHARGE_TIMEOUT on LDO4 occurred 1h = SD due to RV/DISCHARGE_TIMEOUT on LDO4 occurred |
| 5 | LDO3_RV_SD | R/W1C | Oh | RV on LDO4 rail caused a shutdown during: 1. A transition to STANDBY state, this rail did not discharge at the end of the assigned slot and discharge is enabled for this rail 2. A transition to STANDBY state, RV was observed on this rail during the transition after this rail was disabled and discharge was enabled 3. A transition to ACTIVE state, RV was observed on this rail during the transition when this rail was OFF (rails are expected to be discharged before commencing the sequence to ACTIVE) 4. This rail did not discharge and therefore caused a Timeout-SD while attempting to discharge all rails at the start of a transition from STANDBY to ACTIVE (TIMEOUT bit gets also set in this case) <br> Oh = No SD due to RV/DISCHARGE_TIMEOUT on LDO3 occurred 1h = SD due to RV/DISCHARGE_TIMEOUT on LDO3 occurred |
| 4 | LDO2_RV_SD | R/W1C | Oh | RV on LDO4 rail caused a shutdown during: 1. A transition to STANDBY state, this rail did not discharge at the end of the assigned slot and discharge is enabled for this rail 2. A transition to STANDBY state, RV was observed on this rail during the transition after this rail was disabled and discharge was enabled 3. A transition to ACTIVE state, RV was observed on this rail during the transition when this rail was OFF (rails are expected to be discharged before commencing the sequence to ACTIVE) 4. This rail did not discharge and therefore caused a Timeout-SD while attempting to discharge all rails at the start of a transition from STANDBY to ACTIVE (TIMEOUT bit gets also set in this case) <br> Oh = No SD due to RV/DISCHARGE_TIMEOUT on LDO2 occurred 1h = SD due to RV/DISCHARGE_TIMEOUT on LDO2 occurred |

TPS65220
Table 7-59. INT_TIMEOUT_RV_SD Register Field Descriptions (continued)

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 3 | LDO1_RV_SD | R/W1C | Oh | RV on LDO4 rail caused a shutdown during: 1. A transition to STANDBY state, this rail did not discharge at the end of the assigned slot and discharge is enabled for this rail 2. A transition to STANDBY state, RV was observed on this rail during the transition after this rail was disabled and discharge was enabled 3. A transition to ACTIVE state, RV was observed on this rail during the transition when this rail was OFF (rails are expected to be discharged before commencing the sequence to ACTIVE) 4. This rail did not discharge and therefore caused a Timeout-SD while attempting to discharge all rails at the start of a transition from STANDBY to ACTIVE (TIMEOUT bit gets also set in this case) <br> Oh = No SD due to RV/DISCHARGE_TIMEOUT on LDO1 occurred 1h = SD due to RV/DISCHARGE_TIMEOUT on LDO1 occurred |
| 2 | BUCK3_RV_SD | R/W1C | Oh | RV on LDO4 rail caused a shutdown during: 1. A transition to STANDBY state, this rail did not discharge at the end of the assigned slot and discharge is enabled for this rail 2. A transition to STANDBY state, RV was observed on this rail during the transition after this rail was disabled and discharge was enabled 3. A transition to ACTIVE state, RV was observed on this rail during the transition when this rail was OFF (rails are expected to be discharged before commencing the sequence to ACTIVE) 4. This rail did not discharge and therefore caused a Timeout-SD while attempting to discharge all rails at the start of a transition from STANDBY to ACTIVE (TIMEOUT bit gets also set in this case) <br> Oh = No SD due to RV/DISCHARGE_TIMEOUT on BUCK3 occurred 1h = SD due to RV/DISCHARGE_TIMEOUT on BUCK3 occurred |
| 1 | BUCK2_RV_SD | R/W1C | Oh | RV on LDO4 rail caused a shutdown during: 1. A transition to STANDBY state, this rail did not discharge at the end of the assigned slot and discharge is enabled for this rail 2. A transition to STANDBY state, RV was observed on this rail during the transition after this rail was disabled and discharge was enabled 3. A transition to ACTIVE state, RV was observed on this rail during the transition when this rail was OFF (rails are expected to be discharged before commencing the sequence to ACTIVE) 4. This rail did not discharge and therefore caused a Timeout-SD while attempting to discharge all rails at the start of a transition from STANDBY to ACTIVE (TIMEOUT bit gets also set in this case) <br> Oh = No SD due to RV/DISCHARGE_TIMEOUT on BUCK2 occurred 1h = SD due to RV/DISCHARGE_TIMEOUT on BUCK2 occurred |
| 0 | BUCK1_RV_SD | R/W1C | Oh | RV on LDO4 rail caused a shutdown during: 1. A transition to STANDBY state, this rail did not discharge at the end of the assigned slot and discharge is enabled for this rail 2. A transition to STANDBY state, RV was observed on this rail during the transition after this rail was disabled and discharge was enabled 3. A transition to ACTIVE state, RV was observed on this rail during the transition when this rail was OFF (rails are expected to be discharged before commencing the sequence to ACTIVE) 4. This rail did not discharge and therefore caused a Timeout-SD while attempting to discharge all rails at the start of a transition from STANDBY to ACTIVE (TIMEOUT bit gets also set in this case) <br> Oh = No SD due to RV/DISCHARGE_TIMEOUT on BUCK1 occurred 1h = SD due to RV/DISCHARGE_TIMEOUT on BUCK1 occurred |

### 7.6.52 INT_PB Register (Offset = 33h) [Reset = X]

INT_PB is shown in Figure 7-63 and described in Table 7-60.
Return to the Summary Table.
Figure 7-63. INT_PB Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| RESERVED | RESERVED | RESERVED | RESERVED | RESERVED | PB_REAL_TIM E_STATŪS | PB_RISING_E DGE_DETECT ED | $\begin{gathered} \hline \text { PB_FALLING_E } \\ \text { DGE_DETECT } \\ \text { ED } \end{gathered}$ |
| R-X | R-X | R-X | R-X | R-X | R-1h | R/W1C-Oh | R/W1C-0h |

Table 7-60. INT_PB Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | RESERVED | R | X | Reserved |
| 6 | RESERVED | R | X | Reserved |
| 5 | RESERVED | R | X | Reserved |
| 4 | RESERVED | R | X | Reserved |
| 3 | RESERVED | R | X | Reserved |
| 2 | PB_REAL_TIME_STATUS | R | 1 h | Deglitched (64-128ms) real-time status of PB pin. Valid only when <br> EN/PB/VSENSE pin is configured as PB. <br> Oh = Current deglitched status of PB: PRESSED <br> 1h = Current deglitched status of PB: RELEASED |
| 1 | PB_RISING_EDGE_DET <br> ECTED | R/W1C | Oh | PB was released for > deglitch period (64-128ms) since the previous <br> time this bit was cleared. This bit when set, does assert nINT pin (if <br> config bit MASK_INT_FOR_PB='0'). <br> Oh = No PB-rel-ase detected <br> 1h = PB-release detected |
| 0 | PB_FALLING_EDGE_DE <br> TECTED | R/W1C | Oh | PB was pressed for > deglitch period (64-128ms) since the previous <br> time this bit was cleared. This bit when set, does assert nINT pin (if <br> config bit MASK_INT_FOR_PB='0'). <br> Oh = No PB-press detected <br> 1h = PB-press detected |

### 7.6.53 USER_NVM_CMD_REG Register (Offset = 34h) [Reset =00h]

USER_NVM_CMD_REG is shown in Figure 7-64 and described in Table 7-61.
Return to the Summary Table.
Figure 7-64. USER_NVM_CMD_REG Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| NVM_VERIFY_- <br> RESULT | CUST_NVM_V <br> ERIFY_DONE | CUST_PROG_- <br> DONE | I2C_OSC_ON |  | USER_NVM_CMD |  |  |
| R-Oh | R/W1C-Oh | R/W1C-Oh | R-Oh |  | R-Oh |  |  |

Table 7-61. USER_NVM_CMD_REG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | NVM_VERIFY_RESULT | R | Oh | After an CUST_NVM_VERIFY_CMD is executed, this bit gives the <br> result of the operation. (1 = fail, 0 o pass). If '1', can only be cleared if <br> a subsequent CUST_NVM_VERIFY_CMD passes. <br> Oh = PASS <br> 1h = FAIL |
| 6 | CUST_NVM_VERIFY_DO <br> NE | R/W1C | Oh | Is set to '1' after a CUST_NVM_VERIFY_CMD is executed. Remains <br> '1' until W1C by user. <br> Oh = Not yet done / not in progress <br> 1h = Done |
| 5 | CUST_PROG_DONE | R/W1C | Oh | Is set to '1' after a CUST_PROG_CMD is executed. Remains '1' until <br> W1C by user. <br> Oh = Not yet done / not in progress <br> 1h = Done |
| 4 | I2C_OSC_ON | R | Oh | This register field is set to '1' if an EN_OSC_DIY is received. <br> Oh = OSC not controlled via I2C <br> 1h = OSC unconditionally ON due to I2C command EN_OSC_DIY |
| $3-0$ | USER_NVM_CMD | R | Oh | Commands to enter DIY programming mode and program user NVM <br> space. Always reads as 0. <br> 6h = DIS_OSC_DIY <br> 7h = CUST_NVM_VERIFY_CMD <br> 9h = EN_OSC_DIY <br> Ah = CUST_PROG_CMD |

### 7.6.54 POWER_UP_STATUS_REG Register (Offset = 35h) [Reset = 00h]

POWER_UP_STATUS_REG is shown in Figure 7-65 and described in Table 7-62.
Return to the Summary Table.
Figure 7-65. POWER_UP_STATUS_REG Register

| 7 | 6 | 5 | 4 | 3 | 21 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| POWER_UP_F ROM_FSD | POWER_UP_F ROM_EN_PB VSENSE | COLD_RESET_ ISSUED | STATE |  | RETRY_COUNT | POWER_UP_F ROM_OFF |
| R/W1C-0h | R/W1C-0h | R/W1C-0h | R-Oh |  | R-Oh | R/W1C-0h |

Table 7-62. POWER_UP_STATUS_REG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :---: | :---: | :---: | :---: |
| 7 | POWER_UP_FROM_FSD | R/W1C | Oh | Is set if ON_REQ was triggered due to FSD Oh = No power-up via FSD detected <br> 1h = Power-up via FSD detected |
| 6 | POWER_UP_FROM_EN_ PB_VSENSE | R/W1C | Oh | Is set if ON_REQ was triggered due to EN/PB/VSENSE pin Oh = No power-up via pin detected <br> 1h = Power-up via pin detected |
| 5 | COLD_RESET_ISSUED | R/W1C | Oh | Is set if we received a COLD_RESET over pin or over I2C Oh = No COLD RESET received <br> 1h = COLD RESET received either through pin or I2C |
| 4-3 | STATE | R | Oh | Indicates the current device state Oh = Transition state <br> $1 \mathrm{~h}=$ INITIALIZE <br> $2 \mathrm{~h}=$ STANDBY <br> 3h = ACTIVE |
| 2-1 | RETRY_COUNT | R | Oh | Reads the current retry count in the state machine. If RETRY_COUNT = 3 and is not masked, device does not power up. |
| 0 | POWER_UP_FROM_OFF | R/W1C | Oh | Indicates if we powered up from OFF state (POR was asserted) Oh = OFF state not entered since the previous clearing of this bit $1 \mathrm{~h}=$ OFF state was entered since the previous clearing of this bit |

### 7.6.55 SPARE_2 Register (Offset $=\mathbf{3 6 h}$ ) [Reset $=00 \mathrm{~h}]$

SPARE_2 is shown in Figure 7-66 and described in Table 7-63.
Return to the Summary Table.
Figure 7-66. SPARE_2 Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SPARE_2_1 | SPARE_2_2 | SPARE_2_3 | SPARE_2_4 | SPARE_2_5 | SPARE_2_6 | SPARE_2_7 | SPARE_2_8 |
| R/W-0h | R/W-0h | R/W-0h | R/W-0h | R/W-0h | R/W-0h | R/W-0h | R/W-0h |

Table 7-63. SPARE_2 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :---: | :--- | :--- | :--- | :--- |
| 7 | SPARE_2_1 | R/W | Oh | Spare bit in user non-NVM space |
| 6 | SPARE_2_2 | R/W | Oh | Spare bit in user non-NVM space |
| 5 | SPARE_2_3 | R/W | Oh | Spare bit in user non-NVM space |
| 4 | SPARE_2_4 | R/W | Oh | Spare bit in user non-NVM space |
| 3 | SPARE_2_5 | R/W | Oh | Spare bit in user non-NVM space |
| 2 | SPARE_2_6 | R/W | Oh | Spare bit in user non-NVM space |
| 1 | SPARE_2_7 | R/W | Oh | Spare bit in user non-NVM space |
| 0 | SPARE_2_8 | R/W | Oh | Spare bit in user non-NVM space |

### 7.6.56 SPARE_3 Register (Offset $=\mathbf{3 7} \mathrm{h}$ ) [Reset $=00 \mathrm{~h}]$

SPARE_3 is shown in Figure 7-67 and described in Table 7-64.
Return to the Summary Table.
Figure 7-67. SPARE_3 Register

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SPARE_3_1 |  |  |  |  |  |  |  |
| R/W-Oh |  |  |  |  |  |  |  |

Table 7-64. SPARE_3 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
| $7-0$ | SPARE_3_1 | R/W | Oh | Spare bit in user non-NVM space |

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### 7.6.57 FACTORY_CONFIG_2 Register (Offset = 41h [Reset = X]

FACTORY_CONFIG_2 is shown in Figure 7-68 and described in Table 7-65.
Return to the Summary Table.
Figure 7-68. FACTORY_CONFIG_2 Register

| 7 | 5 | 4 | 3 | 1 | 0 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| NVM_REVISION |  |  |  |  |  |
| R/W-X |  |  |  |  |  |

Table 7-65. FACTORY_CONFIG_2 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
| :--- | :--- | :--- | :--- | :--- |
| $7-5$ | NVM_REVISION | R/W | X | Specifies the version of the NVM configuration Note: This register <br> can be programmed only by the manufacturer. <br> Oh = V0 <br> 1h = V1 ... |

## 8 Application and Implementation


#### Abstract

Note Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. Tl's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.


### 8.1 Application Information

The following sections provide more detail on the proper utilization of the PMIC. Each orderable part number has unique default non-volatile memory (NVM) settings and the relevant Technical Reference Manual (TRM) for that orderable is available in the product folder, under Technical Documentation. Refer to these TRMs for specific application information. More generic topics and some examples are outlined here.

To help with new designs, a variety of tools and documents are available in the product folder. Some examples are:

- Evaluation module and user guide.
- GUI to communicate with the PMIC
- Schematic and layout checklist
- User's guide describing how to power specific processors and SoCs with the PMIC.
- Technical Reference Manual (TRM) describing the default register settings on each orderable.


### 8.2 Typical Application

The TPS65220 PMIC contains seven regulators; 3 Buck converters and 4 Low Drop-out Regulators (LDOs). In addition to the power resources, it also integrates 3 configurable multi-function pins, 1 GPIO, 2 GPOs and I2C communication making this power management IC an ideal cost and size optimized solution to power multiple processors and SoCs. There are several considerations to take into account when designing the TPS65220 to power a processor and peripherals. The number of regulators needed, the required sequencing, the load current requirements, and the voltage characteristics are all critical in determining the number of supply rails as well as the external components used with it. The following section provides a generic case. For specific cases, refer to the relevant user's guide and TRM based on the orderable part number.

### 8.2.1 Typical Application Example

In this example, a single TPS65220 PMIC is used to power a generic processor. This power distribution network (PDN) shows a 3.3 V input supply but 5 V can be used as well to supply the Bucks and LDO (if not configured as bypass). To reduce power dissipation, the output from one of the PMIC Buck regulators can be used to supply the LDOs if it meets the required headroom and sequence needs. For example, Buck2 ( 1.8 V ) is used to supply LDO2 ( 0.85 V ). LDO1 is configured as bypass and assigned to supply the SD card interface. The bypass mode allows voltage change between VSET_LDO1 and 1.8 V to meet the SD spec for UHS speed which requires 3.3 V to initialize the card before the voltage can be lowered to 1.8 V for faster rise/fall time and lower electromagnetic interference. The VSEL_SD multifunction pin can be configured to trigger the voltage change during operation. Since Buck1 is the regulator with the highest current capabilities, it was assigned to supply the CORE rail of the processor. Each of the Buck regulators have the option to be configured for high bandwidth to support higher load transients and higher total capacitance (local + point of load). Since the PMIC is being supplied by a 3.3 V rail, an external load switch is used to supply the 3.3 V IO domain on the processor. One of the PMIC GPOs (GPO2) is configured to be part of the power-up/power-down sequence and enables the external power-switch.

## Note

If an external discrete is used to supply the 3.3 V IO, it must be chosen with active discharge so the voltage can be discharge after the PMIC GPO2 disables it.

TPS65220
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Figure 8-1. Example Power Map

### 8.2.2 Design Requirements

The design requirements for the typical application described on this section are outlined below:

- VDD CORE rail requires 0.75 V rail with high loadtransient response.
- VDDR CORE rail requires 0.85 V .
- Low noise 1.8 V required to supply the analog.
- 3.3 V and 1.8 V required to supply processor IO domains and peripherals.
- uSD card interface requires a rail with 3.3 V at startup with dynamic voltage capability to switch from 3.3 V to 1.8 V and support ultra-high speed (UHS)
- LPDDR4 requires a 1.1 V rail.
- HDMI transmitter requires 1.2 V rail.


### 8.2.3 Detailed Design Procedure

This section describes the design procedure for each of the power modules integrated in the TPS65220 PMIC. Please note, most of the external component values that are mentioned in this section are based on the typical spec. For minimum and maximum values, refer to the corresponding parameter in the Specifications section.

### 8.2.3.1 Buck1, Buck2, Buck3 Design Procedure

## Input Capacitance - Buck1, Buck2, Buck3

Each of the Buck converters require an input capacitor on the corresponding PVIN_Bx pin. The capacitor value must be selected taking into account the voltage and temperature de-rating. Due to the nature of the switching converter, a low ESR ceramic capacitor is required for best input voltage filtering. The typical recommended capacitance is $4.7 \mathrm{uF}, 10 \mathrm{~V}$ capacitor. Higher input capacitance can be used if the PCB size allows larger footprint.

## Output Capacitance - Buck1, Buck2, Buck3

Every Buck output requires a local output capacitor to form the capacitive part of the LC output filter. Ceramic capacitor with X7 temperature coefficient are recommended. Non-automotive applications can use X6 or lower based on the operating temperature. The Buck converters have multiple switching modes and bandwidth configuration that impact the output capacitor selection. The switching mode configuration (BUCK_FF_ENABLE) is a global register field that applies to the three Buck converters and must not be changed at any point. The bandwidth selection is an independent register field for each Buck converter. Refer to the Technical Reference Manual (TRM) for the specific orderable part number to identify the NVM configuration and the corresponding output capacitance requirements. Table 8-1 shows the required minimum and maximum capacitance (after derating) for each switching mode and bandwidth configuration. DC bias voltage characteristics of ceramic capacitors, tolerance, aging and temperature effects must be considered. ESR must be $10 \mathrm{~m} \Omega$ or lower.

Table 8-1. Buck output capacitance

| Switching Mode Selection | Bandwidth Selection | Spec parameter | Capacitance |  |
| :---: | :---: | :---: | :---: | :---: |
| Register Field: BUCK_FF_ENABLE | Register fields: BUCK1_BW_SEL, BUCK2_BW_SEL, BUCK3_BW_SEL |  | Min | Max <br> (Includes local + point of load) |
| Quasi-fixed frequency (auto-PFM or forced-PWM) | Low Bandwidth | COUT | 10 uF | 75 uF |
|  | High Bandwidth | COUT_HIGH_BW | 30 uF | 220 uF |
| Fixed Frequency(supported on TPS65220and TPS65219-Q1) | Low Bandwidth | COUT_FF | 12 uF | 36 uF |
|  | High Bandwidth | COUT_HIGH_BW_FF | 48 uF | 144 uF |

## Inductor Selection - Buck1, Buck2, Buck3

Internal parameters for the buck converters are optimized for 0.47 uF inductor. DCR must be $50 \mathrm{~m} \Omega$ or lower. Ensure that the selected inductor is rated to support saturation current of at least 7.4A for Buck1 and 5.4A for Buck2/Buck3.

### 8.2.3.2 LDO1, LDO2 Design Procedure

## Input Capacitance - LDO1, LDO2

LDO inputs require an input decoupling capacitor to minimize input ripple voltage. Using a typical of $2.2-\mu \mathrm{F}$ capacitance for each LDO is recommended. Depending on the input voltage of the LDO, a 6.3 V or higher rated
capacitor can be used.

## Output Capacitance - LDO1, LDO2

LDO outputs require an output capacitor to hold up the output voltage during a load step or changes to the input voltage. Using a $2.2-\mu \mathrm{F}$ local capacitance for each LDO output with ESR of 10 mOhms or less is recommended. Local capacitance must not exceed 4 uF (after derating). This requirement excludes any capacitance seen at the load and only refers to the capacitance seen close to the device. The total capacitance (local + point of load) that each LDO can support depends on the NVM configuration. Table $8-2$ shows the maximum total output capacitance allowed based on the rail configuration. Refer to the Technical Reference Manual (TRM) for the specific orderable part number to identify the LDO configuration based on the register settings and the applicable max total capacitance.

Table 8-2. LDO1, LDO2 output capacitance

| Register setting |  | LDO config | Max total capacitance (2.2uF local + <br> point of load) |
| :---: | :---: | :---: | :---: |
| LDOx_LSW_CONFIG | LDOx_BYP_CONFIG |  | LDO |
| 0 | 0 | Bypass | 50 uF |
| 0 | 1 | Load-switch | 50 uF |
| 1 | $X$ | 50 uF |  |

### 8.2.3.3 LDO3, LDO4 Design Procedure

## Input Capacitance - LDO3, LDO4

The input supply pin for LDO3 and LDO4 require an input decoupling capacitor to minimize input ripple voltage. These two LDOs share the same input supply pin. Using a minimum of $4.7-\mu \mathrm{F}$ input capacitance is recommended. Depending on the input voltage of the LDO, a 6.3 V or higher rated capacitor can be used. The same input capacitance requirements applies when the LDO is configured as LDO or load-switch.

## Output Capacitance - LDO3, LDO4

LDO outputs require an output capacitor to hold up the output voltage during a load step or changes to the input voltage. Using a $2.2-\mu \mathrm{F}$ local capacitance for each LDO output with ESR of 10 mOhms or less is recommended. Local capacitance must not exceed 4 uF (after derating). This requirement excludes any capacitance seen at the load and only refers to the capacitance seen close to the device. The total capacitance (local + point of load) that each LDO can support depends on the NVM configuration. Table 8-3 shows the maximum total output capacitance allowed. Refer to the Technical Reference Manual (TRM) for the specific orderable part number to identify the LDO configuration based on the register settings and the applicable maximum total capacitance.

Table 8-3. LDO3, LDO4 output capacitance

| Register setting | LDO ramp config | Max total capacitance <br> (2.2uF local + point of load) |
| :---: | :---: | :---: |
| LDOx_SLOW_PU_RAMP |  | 15uF |
| 0 | fast ramp | 30 uF |
| 1 | slow ramp |  |

### 8.2.3.4 VSYS, VDD1P8

The VSYS pin provides power to the internal VDD1P8 LDO and other internal functions. This pin requires a typical of 2.2 uF ceramic capacitor. The input capacitor can be increased without any limit for better input-voltage filtering. On a typical application, this pin is connected to the same pre-regulator that supplies the PVIN_Bx pins.

VDD1P8 in an internal reference LDO and must not have any load. This pin requires a 2.2 uF ceramic capacitor.

### 8.2.3.5 Digital Signals Design Procedure

This section describes the external connections required for the digital pins. 3.3 V or 1.8 V supply is commonly used as the voltage level for the digital signals that require an external pull-up. However, higher voltage can be used (up to the maximum spec). The pull-up supply for the digital pins on the PMIC must be the same as the IO domain for the digital signal that is connected to on the processor. $100 \mathrm{k} \Omega$ is the recommended pull-up resistor for EN/PB/VSENSE. Pull-up resistor for I2C pins can be calculated based on system requirements. All other digital pins can use $10 \mathrm{k} \Omega$.
If GPIO, GPO1 or GPO2 is assigned to the first slot of the power-up sequence to enable an external discrete, they can be pulled up to VSYS.
The EN/PB/VSENSE pin can be driven externally to enable or disable the PMIC. However, if the application does not have an external signal dedicated to drive this pin, it can be pulled up to VSYS.

## Note

Driving the EN/PB/VSENSE pin with an external signal is needed to wake-up the PMIC after an I2C OFF request is sent by I2C (I2C_OFF_REQ). If an OFF request is sent by I2C and the EN/PB/ VSENSE is not driven by an external signal, a power cycle on VSYS must be performed to transfer the PMIC from Initialize state to Active.

Table 8-4. Digital Signals requirements

| Digital Pin | External Connection |
| :--- | :--- |
| nINT | Open-drain output. Requires external pull-up. |
| nRSTOUT | Wpen-drain output. Requires external pull-up. <br> When configured as EN, this signal can be driven by external logic to enable or disable the PMIC. <br> is optional. <br> When configured as VSENSE, this signal requires an external resistor divider to monitor the pre- <br> regulator. |
| SDA | I2C clock signal. Requires external pull-up. |
| SCL | I2C data signal. Requires external pull-up. |
| GPIO | When configured as GPIO (for multi-PMIC), this pin shares the external pull-up resistor with the <br> second TPS65220 PMIC. <br> When configured as GPO (for single PMIC), requires external pull-up. |
| GPO1 | Open-drain general purpose output. Requires external pull-up. |
| GPO2 | Open-drain general purpose output. Requires external pull-up. |
| VSEL_SD / VSEL_DDR | Input digital pin. The initial state (pull-up or pull-down) must be set before the assigned PMIC rail <br> ramps up. For example, if this pin is used to set the voltage on LDO1, the state must be set before <br> LDO1 powers up. |
| MODE / STBY | Input digital pin. The initial state (pull-up or pull-down) must be set before the power-up sequence is |
| complete. |  |
| MOSET | Input digital pin. The initial state (pull-up or pull-down) must be set before the power-up sequence is <br> complete. |

### 8.2.4 Application Curves



Figure 8-2. Buck1 ramp


Bandwidth
Figure 8-4. Buck3 ramp


Figure 8-6. LDO3, LDO4 Fast Ramp


Bandwidth
Figure 8-3. Buck2 ramp


Figure 8-5. LDO1, LDO2 ramp


Figure 8-7. LDO3, LDO4 Slow Ramp


Figure 8-8. Bucks Discharge


Figure 8-10. Configurable power-up sequence Example


Figure 8-9. LDOs Discharge


Figure 8-11. Configurable power-down sequence Example

### 8.3 Power Supply Recommendations

The device is designed to operate with an input voltage supply range between 2.5 V and 5.5 V . This input supply can be generated from a single cell Li-lon battery, two primary cells or a regulated pre-regulator. The voltage headroom required for each of the PMIC regulators must be taken into account when defining selecting the supply voltage. For example, if the Bucks require 700 mV head room and the output voltage is configured as 3.3 V , then the input supply must be at least 4 V to allow sufficient headroom. The resistance of the input supply rail must be low enough that the input current transient does not cause too high drop in the device supply voltage that can cause false UVLO fault triggering. If the input supply is located more than a few inches from the device, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of $47 \mu \mathrm{~F}$ is a typical choice. When using a pre-regulator to supply the PMIC, it is recommended to select the pre-regulator without active discharge to hold the voltage at the input of the PMIC for as long as possible during a uncontrolled power-down.

## CAUTION

Sequencing and Voltage requirements: The voltage on PVIN_Bx, and PVIN_LDOx must not exceed VSYS. The Pull-up supply for the digital signals must not exceed VSYS at any point.

### 8.4 Layout

### 8.4.1 Layout Guidelines

For all switching power supplies, the layout is an important step in the design. If the layout is not carefully done, the regulators can have stability and EMI issues. Therefore, use wide and short traces for the main current path and for the power ground tracks. The input capacitors, output capacitors, and inductors must be placed as close as possible to the device. The output capacitors must have a low impedance to ground. Use multiple VIAS (at least three) directly at the ground landing pad of the capacitor. Here are some layout guidelines:

- PVIN_Bx: Place the input capacitor as close to the IC as allowed by the layout DRC rules. Any extra parasitic inductance between the input cap and the PVIN_Bx pin can create a voltage spike. It is recommended to have wide a short traces or polygon to help minimize trace inductance. Do not route any sensitive signals close to the input cap and the device pin as this node has high frequency switching currents. Add $3-4$ vias per amp of current on the GND pads for each DCDC. If the space is limited and does not allow to place the input capacitors on the same layer as the PMIC, then place the input capacitors on the opposite layer with VIAS, close to the IC, and add a small input capacitor ( 0.1 uF ) on the same layer as the PMIC. This small capacitor must be placed close to the PVIN_Bx pin.
- LX_Bx: Place the inductor close to the PMIC without compromising the PVIN input caps and use short \& wide traces or polygons to connect the pin to the inductor. Do not route any sensitive signals close to this node. The inductor must be placed in the same layer as the IC to prevent having to use VIAS in the SW node. Since the SW-node voltage swings from the input voltage to ground with very fast rise and fall times, it is the main generator of EMI. If needed, to reduce EMI, a RC snubber can be added to the SW node.
- FB_Bx: Route each of the FB_Bx pins as a trace to the output capacitor. Do not extend the output voltage polygon to the FB _Bx pin as this pin requires to be routed as a trace. The trace resistance from the output capacitor to the $\mathrm{FB} \_\mathrm{Bx}$ pin must be less than $1 \Omega$. The TPS65220 does not support remote sensing so the FB_Bx pins must be connected to the local capacitor of the PMIC. Avoid routing the FB_Bx close to any noisy signals such as the switch node or under the inductor to avoid coupling. If space is constraint, FB_Bx pin can be routed through an inner layer. See example layout.
- Bucks Cout: The local output capacitors must be placed as close to the inductor as possible to minimize electromagnetic emissions.
- PVIN_LDOx: Place the input capacitor as close as posible to the PVIN_LDOx pin.
- VLDOx: Place the output capacitor close to the VLDOx pin. For the LDO regulators, the feedback connection is internal. Therefore, it is important to keep the PCB resistance between LDO output and target load in the range of the acceptable voltage, IR, drop for LDOs.
- VSYS: Connect VSYS directly to a quiet system voltage node. Place the decoupling capacitor as close as possible to the VSYS pin.
- VDD1P8: Place the 2.2 uF cap as close as possible to the VDD1P8 pin. This capacitor needs to be placed in the same layer as the IC. Two to Three VIAS can be used to connect the GND side of the capacitor to the GND plane of the PCB.
- Power Pad: The thermal pad must be connected to the PCB ground plane with a minimum of nine VIAS.
- AGND: Do not connect AGND to the power pad (or thermal pad). The AGDN pin must be connected to the PCB ground planes through a VIA. Keep the trace from the AGDN pin to the VIA short.


### 8.4.2 Layout Example



Figure 8-12. Example PMIC Layout

## 9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 9.1 Documentation Support

### 9.1.1 Related Documentation

### 9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Subscribe to updates to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.3 Support Resources

TI E2E ${ }^{\text {TM }}$ support forums are an engineer's go-to source for fast, verified answers and design help - straight from the experts. Search existing answers or ask your own question to get the quick design help you need.
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### 9.4 Trademarks

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### 9.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.
ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

INSTRUMENTS

## PACKAGING INFORMATION

| Orderable Device | Status <br> (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <br> (2) | Lead finish/ Ball material <br> (6) | MSL Peak Temp <br> (3) | Op Temp ( ${ }^{\circ} \mathrm{C}$ ) | Device Marking <br> (4/5) | Samples |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TPS6522053RHBR | ACTIVE | VQFN | RHB | 32 | 3000 | RoHS \& Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | $\begin{aligned} & 65220 \\ & \text { NVM } 53 \end{aligned}$ | Samples |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
${ }^{(2)}$ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. Tl may reference these types of products as "Pb-Free"
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption
Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the $<=1000 \mathrm{ppm}$ threshold requirement.
${ }^{(3)}$ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
${ }^{(4)}$ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device
${ }^{(5)}$ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
${ }^{(6)}$ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


TAPE DIMENSIONS


| A0 | Dimension designed to accommodate the component width |
| :---: | :--- |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> Diameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> W1 $(\mathbf{m m})$ | A0 <br> $(\mathbf{m m})$ | B0 <br> $(\mathbf{m m})$ | K0 <br> $(\mathbf{m m})$ | P1 <br> $(\mathbf{m m})$ | W <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TPS6522053RHBR | VQFN | RHB | 32 | 3000 | 330.0 | 12.4 | 5.3 | 5.3 | 1.1 | 8.0 | 12.0 | Q2 |


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TPS6522053RHBR | VQFN | RHB | 32 | 3000 | 367.0 | 367.0 | 35.0 |



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.


## LAND PATTERN EXAMPLE

SCALE:15X


NON SOLDER MASK DEFINED
(PREFERRED)


SOLDER MASK
DEFINED

SOLDER MASK DETAILS

NOTES: (continued)
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271)
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

## EXAMPLE STENCIL DESIGN



NOTES: (continued)
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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